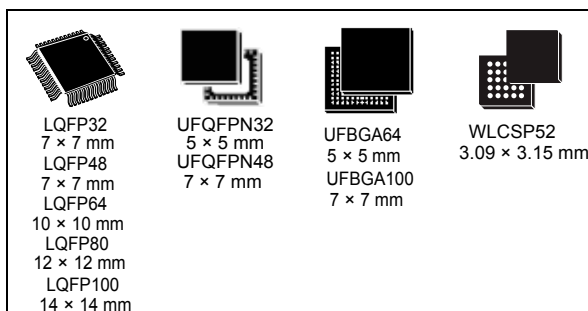


Arm[®] Cortex[®]-M0+ 32-bit MCU, up to 512KB Flash, 144KB RAM, 6x USART, timers, ADC, DAC, comm. I/Fs, 1.7-3.6V

Datasheet - production data

Features

- Core: Arm[®] 32-bit Cortex[®]-M0+ CPU, frequency up to 64 MHz
- -40°C to 85°C/105°C/125°C operating temperature
- Memories
 - Up to 512 Kbytes of Flash memory with protection and securable area, two banks, read-while-write support
 - 144 Kbytes of SRAM (128 Kbytes with HW parity check)
- CRC calculation unit
- Reset and power management
 - Voltage range: 1.7 V to 3.6 V
 - Separate I/O supply pin (1.6 V to 3.6 V)
 - Power-on/Power-down reset (POR/PDR)
 - Programmable Brownout reset (BOR)
 - Programmable voltage detector (PVD)
 - Low-power modes: Sleep, Stop, Standby, Shutdown
 - V_{BAT} supply for RTC and backup registers
- Clock management
 - 4 to 48 MHz crystal oscillator
 - 32 kHz crystal oscillator with calibration
 - Internal 16 MHz RC with PLL option (±1 %)
 - Internal 32 kHz RC oscillator (±5 %)
- Up to 94 fast I/Os
 - All mappable on external interrupt vectors
 - Multiple 5 V-tolerant I/Os
- 12-channel DMA controller with flexible mapping
- 12-bit, 0.4 μs ADC (up to 16 ext. channels)
 - Up to 16-bit with hardware oversampling
 - Conversion range: 0 to 3.6V
- Two 12-bit DACs, low-power sample-and-hold
- Three fast low-power analog comparators, with programmable input and output, rail-to-rail
- 15 timers (two 128 MHz capable): 16-bit for advanced motor control, one 32-bit and six 16-bit general-purpose, two basic 16-bit, two low-power 16-bit, two watchdogs, SysTick timer
- Calendar RTC with alarm and periodic wakeup from Stop/Standby/Shutdown



- Communication interfaces
 - Three I²C-bus interfaces supporting Fast-mode Plus (1 Mbit/s) with extra current sink, two supporting SMBus/PMBus and wakeup from Stop mode
 - Six USARTs with master/slave synchronous SPI; three supporting ISO7816 interface, LIN, IrDA capability, auto baud rate detection and wakeup feature
 - Two low-power UARTs
 - Three SPIs (32 Mbit/s) with 4- to 16-bit programmable bitframe, two multiplexed with I²S interface
 - HDMI CEC interface, wakeup on header
- USB 2.0 FS device (crystal-less) and host controller
- USB Type-C™ Power Delivery controller
- Two FDCAN controllers
- Development support: serial wire debug (SWD)
- 96-bit unique ID
- All packages ECOPACK 2 compliant

Table 1. Device summary

Reference	Part number
STM32G0B1xB	STM32G0B1CB, STM32G0B1KB, STM32G0B1MB, STM32G0B1RB, STM32G0B1VB
STM32G0B1xC	STM32G0B1CC, STM32G0B1KC, STM32G0B1MC, STM32G0B1RC, STM32G0B1VC
STM32G0B1xE	STM32G0B1CE, STM32G0B1KE, STM32G0B1ME, STM32G0B1NE, STM32G0B1RE, STM32G0B1VE

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1 Introduction

This document provides information on STM32G0B1xB/xC/xE microcontrollers, such as description, functional overview, pin assignment and definition, electrical characteristics, packaging, and ordering codes.

Information on memory mapping and control registers is object of reference manual.

Information on Arm^{®(a)} Cortex[®]-M0+ core is available from the www.arm.com website.



arm

a. Arm is a registered trademark of Arm Limited (or its subsidiaries) in the US and/or elsewhere.

2 Description

The STM32G0B1xB/xC/xE mainstream microcontrollers are based on high-performance Arm® Cortex®-M0+ 32-bit RISC core operating at up to 64 MHz frequency. Offering a high level of integration, they are suitable for a wide range of applications in consumer, industrial and appliance domains and ready for the Internet of Things (IoT) solutions.

The devices incorporate a memory protection unit (MPU), high-speed embedded memories (144 Kbytes of SRAM and up to 512 Kbytes of Flash program memory with read protection, write protection, proprietary code protection, and securable area), DMA, an extensive range of system functions, enhanced I/Os, and peripherals. The devices offer standard communication interfaces (three I²Cs, three SPIs / two I²S, one HDMI CEC, one full-speed USB, two FD CANs, and six USARTs), one 12-bit ADC (2.5 MSPs) with up to 19 channels, one 12-bit DAC with two channels, three fast comparators, an internal voltage reference buffer, a low-power RTC, an advanced control PWM timer running at up to double the CPU frequency, six general-purpose 16-bit timers with one running at up to double the CPU frequency, a 32-bit general-purpose timer, two basic timers, two low-power 16-bit timers, two watchdog timers, and a SysTick timer. The devices provide a fully integrated USB Type-C Power Delivery controller.

The devices operate within ambient temperatures from -40 to 125°C and with supply voltages from 1.7 V to 3.6 V. Optimized dynamic consumption combined with a comprehensive set of power-saving modes, low-power timers and low-power UART, allows the design of low-power applications.

VBAT direct battery input allows keeping RTC and backup registers powered.

The devices come in packages with 32 to 100 pins. Some packages with low pin count are available in two pinouts (standard and alternative indicated by “N” suffix). Products marked by N suffix are offering V_{DDIO2} supply and additional UCPD port versus the standard pinout, therefore those are better choice for UCPD/USB applications.

Table 2. Features and peripheral counts

Peripheral	STM32G0B1_									
	_KB/ _KC/ _KE	_KBxxN/ _KCxxN/ _KExxN	_CB/ _CC/ _CE	_CBxxN/ _CCxxN/ _CExxN	_NE	_RB/ _RC/ _RE	_RBxxN/ _RCxxN/ _RExxN	_MB/ _MC/ _ME	_VB/ _VC/ _VE	
Flash memory (Kbyte)	128/256/ 512	128/256 /512	128/256 /512	128/256 /512	512	128/256 /512	128/256 /512	128/256 /512	128/256 /512	
SRAM (Kbyte)	128 (parity-protected) or 144 (not parity-protected)									
Timers	Advanced control	1 (16-bit) high frequency								
	General-purpose	6 (16-bit) + 1 (16-bit) high frequency + 1 (32-bit)								
	Basic	2 (16-bit)								
	Low-power	2 (16-bit)								
	SysTick	1								
	Watchdog	2								

Table 2. Features and peripheral counts (continued)

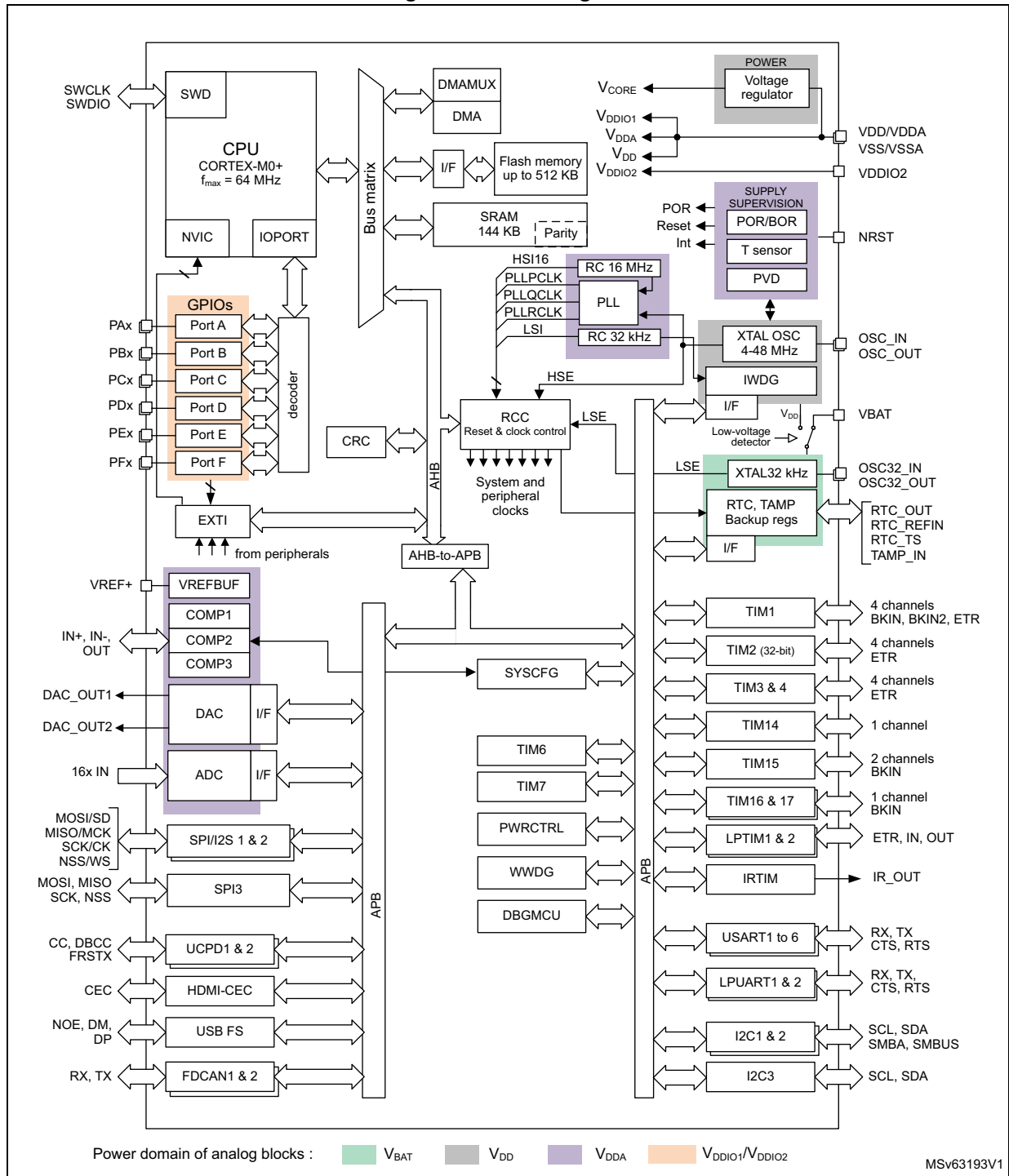
Peripheral	STM32G0B1_									
	_KB/ _KC/ _KE	_KBxxN/ _KCxxN/ _KExxN	_CB/ _CC/ _CE	_CBxxN/ _CCxxN/ _CExxN	_NE	_RB/ _RC/ _RE	_RBxxN/ _RCxxN/ _RExxN	_MB/ _MC/ _ME	_VB/ _VC/ _VE	
Comm. interfaces	SPI [I ² S] ⁽¹⁾	3 [2]								
	I ² C	3								
	USART	6								
	LPUART	2								
	USB	1								
	UCPD	1 ⁽²⁾	2	1	2	1	2			
	FDCAN	2								
	CEC	1								
RTC	Yes									
Tamper pins	3									
VDDIO2 pin / VSS pin	No/No	Yes/No	No/No	Yes/Yes	Yes/Yes	No/No	Yes/Yes	Yes/Yes	Yes/Yes	
Random number generator	No									
AES	No									
GPIOs	30	29	44	42	46	60	58	74	94	
Wakeup pins	4	3	4			5		7	8	
ADC channels (ext. + int.)	11 + 2	10 + 2	14 + 3	12 + 3	14 + 3	16 + 3	14 + 3	16 + 3	16 + 3	
DAC channels	2									
Internal voltage reference buffer	No		Yes							
Analog comparators	3									
Max. CPU frequency	64 MHz									
Operating voltage	1.7 to 3.6 V									
Operating temperature ⁽³⁾	Ambient: -40 to 85 °C / -40 to 105 °C / -40 to 125 °C Junction: -40 to 105 °C / -40 to 125 °C / -40 to 130 °C									
Number of pins	32		48		52	64		80	100	

1. The numbers in brackets denote the count of SPI interfaces configurable as I²S interface.

2. One port with only one CC line available (supporting limited number of use cases).

3. Depends on order code. Refer to [Section 7: Ordering information](#) for details.

Figure 1. Block diagram



3 Functional overview

3.1 Arm[®] Cortex[®]-M0+ core with MPU

The Cortex-M0+ is an entry-level 32-bit Arm Cortex processor designed for a broad range of embedded applications. It offers significant benefits to developers, including:

- a simple architecture, easy to learn and program
- ultra-low power, energy-efficient operation
- excellent code density
- deterministic, high-performance interrupt handling
- upward compatibility with Cortex-M processor family
- platform security robustness, with integrated Memory Protection Unit (MPU).

The Cortex-M0+ processor is built on a highly area- and power-optimized 32-bit core, with a 2-stage pipeline Von Neumann architecture. The processor delivers exceptional energy efficiency through a small but powerful instruction set and extensively optimized design, providing high-end processing hardware including a single-cycle multiplier.

The Cortex-M0+ processor provides the exceptional performance expected of a modern 32-bit architecture, with a higher code density than other 8-bit and 16-bit microcontrollers.

Owing to embedded Arm core, the STM32G0B1xB/xC/xE devices are compatible with Arm tools and software.

The Cortex-M0+ is tightly coupled with a nested vectored interrupt controller (NVIC) described in [Section 3.13.1](#).

3.2 Memory protection unit

The memory protection unit (MPU) is used to manage the CPU accesses to memory to prevent one task to accidentally corrupt the memory or resources used by any other active task.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

3.3 Embedded Flash memory

STM32G0B1xB/xC/xE devices feature up to 512 Kbytes of embedded Flash memory available for storing code and data.

Flexible protections can be configured thanks to option bytes:

- Readout protection (RDP) to protect the whole memory. Three levels are available:
 - Level 0: no readout protection
 - Level 1: memory readout protection: the Flash memory cannot be read from or written to if either debug features are connected, boot in RAM or bootloader is selected
 - Level 2: chip readout protection: debug features (Cortex-M0+ serial wire), boot in RAM and bootloader selection are disabled. This selection is irreversible.

Table 3. Access status versus readout protection level and execution modes

Area	Protection level	User execution			Debug, boot from RAM or boot from system memory (loader)		
		Read	Write	Erase	Read	Write	Erase
User memory	1	Yes	Yes	Yes	No	No	No
	2	Yes	Yes	Yes	N/A	N/A	N/A
System memory	1	Yes	No	No	Yes	No	No
	2	Yes	No	No	N/A	N/A	N/A
Option bytes	1	Yes	Yes	Yes	Yes	Yes	Yes
	2	Yes	No	No	N/A	N/A	N/A
Backup registers	1	Yes	Yes	N/A ⁽¹⁾	No	No	N/A ⁽¹⁾
	2	Yes	Yes	N/A	N/A	N/A	N/A

1. Erased upon RDP change from Level 1 to Level 0.

- Write protection (WRP): the protected area is protected against erasing and programming. Two areas per bank can be selected, with 2-Kbyte granularity.
- Proprietary code readout protection (PCROP): a part of the Flash memory can be protected against read and write from third parties. The protected area is execute-only: it can only be reached by the STM32 CPU as instruction code, while all other accesses (DMA, debug and CPU data read, write and erase) are strictly prohibited. An additional option bit (PCROP_RDP) determines whether the PCROP area is erased or not when the RDP protection is changed from Level 1 to Level 0.

The whole non-volatile memory embeds the error correction code (ECC) feature supporting:

- single error detection and correction
- double error detection
- readout of the ECC fail address from the ECC register

3.3.1 Securable area

A part of the Flash memory can be hidden from the application once the code it contains is executed. As soon as the write-once SEC_PROT bit is set, the securable memory cannot be accessed until the system resets. The securable area generally contains the secure boot code to execute only once at boot. This helps to isolate secret code from untrusted application code.

3.4 Embedded SRAM

STM32G0B1xB/xC/xE devices have 128 Kbytes of embedded SRAM with parity. Hardware parity check allows memory data errors to be detected, which contributes to increasing functional safety of applications.

When the parity protection is not required because the application is not safety-critical, the parity memory bits can be used as additional SRAM, to increase its total size to 144 Kbytes.

The memory can be read/write-accessed at CPU clock speed, with 0 wait states.

3.5 Boot modes

At startup, the boot pin and boot selector option bit are used to select one of the three boot options:

- boot from User Flash memory
- boot from System memory
- boot from embedded SRAM

The boot pin is shared with a standard GPIO and can be enabled through the boot selector option bit. The boot loader is located in System memory. It manages the Flash memory reprogramming through one of the following interfaces:

- USART on pins PA9/PA10, PC10/PC11, or PA2/PA3
- I²C-bus on pins PB6/PB7 or PB10/PB11
- SPI on pins PA4/PA5/PA6/PA7 or PB12/PB13/PB14/PB15
- USB on pins PA11/PA12
- FDCAN on pins PD0/PD1

3.6 Cyclic redundancy check calculation unit (CRC)

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code using a configurable generator polynomial value and size.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link time and stored at a given memory location.

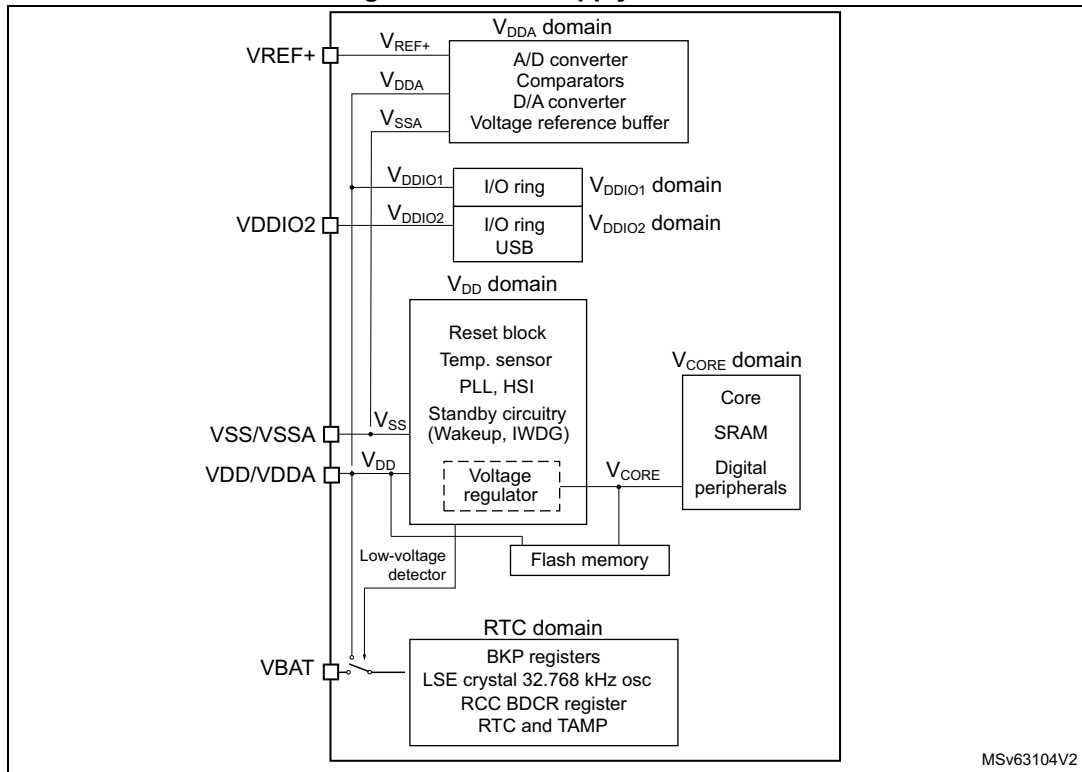
3.7 Power supply management

3.7.1 Power supply schemes

The STM32G0B1xB/xC/xE devices require a 1.7 V to 3.6 V operating supply voltage (V_{DD}). Several different power supplies are provided to specific peripherals:

- $V_{DD} = 1.7$ (1.6) to 3.6 V
 V_{DD} is the external power supply for the internal regulator and the system analog such as reset, power management and internal clocks. It is provided externally through VDD/VDDA pin.
 The minimum voltage of 1.7 V corresponds to power-on reset release threshold $V_{POR(max)}$. Once this threshold is crossed and power-on reset is released, the functionality is guaranteed down to power-down reset threshold $V_{PDR(min)}$.
- $V_{DDA} = 1.62$ V (ADC and COMP) / 1.8 V (DAC) / 2.4 V (VREFBUF) to 3.6 V
 V_{DDA} is the analog power supply for the A/D converter, D/A converter, voltage reference buffer and comparators. V_{DDA} voltage level is identical to V_{DD} voltage as it is provided externally through VDD/VDDA pin.
- $V_{DDIO1} = V_{DD}$
 V_{DDIO1} is the power supply for the I/Os. V_{DDIO1} voltage level is identical to V_{DD} voltage as it is provided externally through VDD/VDDA pin.
- $V_{DDIO2} = 1.6$ to 3.6 V
 V_{DDIO2} is the power supply from VDDIO2 pin for selected I/Os and V_{DDUSB} . On packages without VDDIO2 pin, V_{DDUSB} and V_{DDIO2} are internally connected with V_{DD} . Although V_{DDIO2} is independent of V_{DD} or V_{DDA} , it must not be applied without valid V_{DD} .
- $V_{BAT} = 1.55$ V to 3.6 V. V_{BAT} is the power supply (through a power switch) for RTC, TAMP, low-speed external 32.768 kHz oscillator and backup registers when V_{DD} is not present. V_{BAT} is provided externally through VBAT pin. When this pin is not available on the package, VBAT bonding pad is internally bonded to the VDD/VDDA pin.
- V_{REF+} is the analog peripheral input reference voltage, or the output of the internal voltage reference buffer (when enabled). When $V_{DDA} < 2$ V, V_{REF+} must be equal to V_{DDA} . When $V_{DDA} \geq 2$ V, V_{REF+} must be between 2 V and V_{DDA} . It can be grounded when the analog peripherals using V_{REF+} are not active.
 The internal voltage reference buffer supports two output voltages, which is configured with VRS bit of the VREFBUF_CSR register:
 - V_{REF+} around 2.048 V (requiring V_{DDA} equal to or higher than 2.4 V)
 - V_{REF+} around 2.5 V (requiring V_{DDA} equal to or higher than 2.8 V) V_{REF+} is delivered through VREF+ pin. On packages without VREF+ pin, V_{REF+} is internally connected with V_{DD} , and the internal voltage reference buffer must be kept disabled (refer to datasheets for package pinout description).
- V_{CORE}
 An embedded linear voltage regulator is used to supply the V_{CORE} internal digital power. V_{CORE} is the power supply for digital peripherals, SRAM and Flash memory. The Flash memory is also supplied with V_{DD} .

Figure 2. Power supply overview



3.7.2 Power supply supervisor

The device has an integrated power-on/power-down (POR/PDR) reset active in all power modes except Shutdown and ensuring proper operation upon power-on and power-down. It maintains the device in reset when the supply voltage is below $V_{POR/PDR}$ threshold, without the need for an external reset circuit. Brownout reset (BOR) function allows extra flexibility. It can be enabled and configured through option bytes, by selecting one of four thresholds for rising V_{DD} and other four for falling V_{DD} .

The device also features an embedded programmable voltage detector (PVD) that monitors the V_{DD} power supply and compares it to V_{PVD} threshold. It allows generating an interrupt when V_{DD} level crosses the V_{PVD} threshold, selectively while falling, while rising, or while falling and rising. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

3.7.3 Voltage regulator

Two embedded linear voltage regulators, main regulator (MR) and low-power regulator (LPR), supply most of digital circuitry in the device.

The MR is used in Run and Sleep modes. The LPR is used in Low-power run, Low-power sleep and Stop modes.

In Standby and Shutdown modes, both regulators are powered down and their outputs set in high-impedance state, such as to bring their current consumption close to zero. However, SRAM data retention is possible in Standby mode, in which case the LPR remains active and it only supplies the SRAM.

3.7.4 Low-power modes

By default, the microcontroller is in Run mode after system or power reset. It is up to the user to select one of the low-power modes described below:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.
- **Low-power run mode**

This mode is achieved with V_{CORE} supplied by the low-power regulator to minimize the regulator's operating current. The code can be executed from SRAM or from Flash, and the CPU frequency is limited to 2 MHz. The peripherals with independent clock can be clocked by HSI16.
- **Low-power sleep mode**

This mode is entered from the low-power run mode. Only the CPU clock is stopped. When wakeup is triggered by an event or an interrupt, the system reverts to the Low-power run mode.
- **Stop 0 and Stop 1 modes**

In Stop 0 and Stop 1 modes, the device achieves the lowest power consumption while retaining the SRAM and register contents. All clocks in the V_{CORE} domain are stopped. The PLL, as well as the HSI16 RC oscillator and the HSE crystal oscillator are disabled. The LSE or LSI keep running. The RTC can remain active (Stop mode with RTC, Stop mode without RTC).

Some peripherals with wakeup capability can enable the HSI16 RC during Stop mode, so as to get clock for processing the wakeup event. The main regulator remains active in Stop 0 mode while it is turned off in Stop 1 mode.
- **Standby mode**

The Standby mode is used to achieve the lowest power consumption, with POR/PDR always active in this mode. The main regulator is switched off to power down V_{CORE} domain. The low-power regulator is either switched off or kept active. In the latter case, it only supplies SRAM to ensure data retention. The PLL, as well as the HSI16 RC oscillator and the HSE crystal oscillator are also powered down. The RTC can remain active (Standby mode with RTC, Standby mode without RTC).

For each I/O, the software can determine whether a pull-up, a pull-down or no resistor shall be applied to that I/O during Standby mode.

Upon entering Standby mode, register contents are lost except for registers in the RTC domain and standby circuitry. The SRAM contents can be retained through register setting.

The device exits Standby mode upon external reset event (NRST pin), IWDG reset event, wakeup event (WKUP pin, configurable rising or falling edge) or RTC event (alarm, periodic wakeup, timestamp, tamper), or when a failure is detected on LSE (CSS on LSE).
- **Shutdown mode**

The Shutdown mode allows to achieve the lowest power consumption. The internal regulator is switched off to power down the V_{CORE} domain. The PLL, as well as the

HSI16 and LSI RC-oscillators and HSE crystal oscillator are also powered down. The RTC can remain active (Shutdown mode with RTC, Shutdown mode without RTC).

The BOR is not available in Shutdown mode. No power voltage monitoring is possible in this mode. Therefore, switching to RTC domain is not supported.

SRAM and register contents are lost except for registers in the RTC domain.

The device exits Shutdown mode upon external reset event (NRST pin), IWDG reset event, wakeup event (WKUP pin, configurable rising or falling edge) or RTC event (alarm, periodic wakeup, timestamp, tamper).

3.7.5 Reset mode

During and upon exiting reset, the schmitt triggers of I/Os are disabled so as to reduce power consumption. In addition, when the reset source is internal, the built-in pull-up resistor on NRST pin is deactivated.

3.7.6 VBAT operation

The V_{BAT} power domain, consuming very little energy, includes RTC, and LSE oscillator and backup registers.

In VBAT mode, the RTC domain is supplied from VBAT pin. The power source can be, for example, an external battery or an external supercapacitor. Two anti-tamper detection pins are available.

The RTC domain can also be supplied from VDD/VDDA pin.

By means of a built-in switch, an internal voltage supervisor allows automatic switching of RTC domain powering between V_{DD} and voltage from VBAT pin to ensure that the supply voltage of the RTC domain (V_{BAT}) remains within valid operating conditions. If both voltages are valid, the RTC domain is supplied from VDD/VDDA pin.

An internal circuit for charging the battery on VBAT pin can be activated if the V_{DD} voltage is within a valid range.

Note: External interrupts and RTC alarm/events cannot cause the microcontroller to exit the VBAT mode, as in that mode the V_{DD} is not within a valid range.

3.8 Interconnect of peripherals

Several peripherals have direct connections between them. This allows autonomous communication between peripherals, saving CPU resources thus power supply consumption. In addition, these hardware connections allow fast and predictable latency.

Depending on peripherals, these interconnections can operate in Run, Sleep and Stop modes.

Table 4. Interconnect of peripherals

Interconnect source	Interconnect destination	Interconnect action	Run Low-power run	Sleep Low-power sleep	Stop
TIMx	TIMx	Timer synchronization or chaining	Y	Y	-
	ADCx DACx	Conversion triggers	Y	Y	-
	DMA	Memory-to-memory transfer trigger	Y	Y	-
	COMPx	Comparator output blanking	Y	Y	-
COMPx	TIM1,2,3,4	Timer input channel, trigger, break from analog signals comparison	Y	Y	-
	LPTIMERx	Low-power timer triggered by analog signals comparison	Y	Y	Y
ADCx	TIM1	Timer triggered by analog watchdog	Y	Y	-
RTC	TIM16	Timer input channel from RTC events	Y	Y	-
	LPTIMERx	Low-power timer triggered by RTC alarms or tampers	Y	Y	Y
All clock sources (internal and external)	TIM14,16,17	Clock source used as input channel for RC measurement and trimming	Y	Y	-
CSS RAM (parity error) Flash memory (ECC error) COMPx PVD	TIM1,15,16,17	Timer break	Y	Y	-
CPU (hard fault)	TIM1,15,16,17	Timer break	Y	-	-
GPIO	TIMx	External trigger	Y	Y	-
	LPTIMERx	External trigger	Y	Y	Y
	ADC DACx	Conversion external trigger	Y	Y	-

3.9 Clocks and startup

The clock controller distributes the clocks coming from different oscillators to the core and the peripherals. It also manages clock gating for low-power modes and ensures clock robustness. It features:

- **Clock prescaler:** to get the best trade-off between speed and current consumption, the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler
- **Safe clock switching:** clock sources can be changed safely on the fly in run mode through a configuration register.
- **Clock management:** to reduce power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- **System clock source:** three different sources can deliver SYSCLK system clock:
 - 4-48 MHz high-speed oscillator with external crystal or ceramic resonator (HSE). It can supply clock to system PLL. The HSE can also be configured in bypass mode for an external clock.
 - 16 MHz high-speed internal RC oscillator (HSI16), trimmable by software. It can supply clock to system PLL.
 - System PLL with maximum output frequency of 64 MHz. It can be fed with HSE or HSI16 clocks.
- **Auxiliary clock source:** two ultra-low-power clock sources for the real-time clock (RTC):
 - 32.768 kHz low-speed oscillator with external crystal (LSE), supporting four drive capability modes. The LSE can also be configured in bypass mode for using an external clock.
 - 32 kHz low-speed internal RC oscillator (LSI) with $\pm 5\%$ accuracy, also used to clock an independent watchdog.
- **USB clock source:**
 - HSI 48 MHz in association with CRS can provide a dedicated clock to USB FS allowing the peripheral to operate as device without requiring an external resonator
- **Peripheral clock sources:** several peripherals (I2S, USARTs, I2Cs, LPTIMs, ADC, USB FS) have their own clock independent of the system clock.
- **Clock security system (CSS):** in the event of HSE clock failure, the system clock is automatically switched to HSI16 and, if enabled, a software interrupt is generated. LSE clock failure can also be detected and generate an interrupt. The CCS feature can be enabled by software.
- **Clock output:**
 - **MCO (microcontroller clock output)** provides one of the internal clocks for external use by the application
 - **LSCO (low speed clock output)** provides LSI or LSE in all low-power modes (except in VBAT operation).

Several prescalers allow the application to configure AHB and APB domain clock frequencies, 64 MHz at maximum.

3.10 General-purpose inputs/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function (AF). Most of the GPIO pins are shared with special digital or analog functions.

Through a specific sequence, this special function configuration of I/Os can be locked, such as to avoid spurious writing to I/O control registers.

3.11 Direct memory access controller (DMA)

The direct memory access (DMA) controller is a bus master and system peripheral with single-AHB architecture.

With 12 channels, it performs data transfers between memory-mapped peripherals and/or memories, to offload the CPU.

Each channel is dedicated to managing memory access requests from one or more peripherals. The unit includes an arbiter for handling the priority between DMA requests.

Main features of the DMA controller:

- Single-AHB master
- Peripheral-to-memory, memory-to-peripheral, memory-to-memory and peripheral-to-peripheral data transfers
- Access, as source and destination, to on-chip memory-mapped devices such as Flash memory, SRAM, and AHB and APB peripherals
- All DMA channels independently configurable:
 - Each channel is associated either with a DMA request signal coming from a peripheral, or with a software trigger in memory-to-memory transfers. This configuration is done by software.
 - Priority between the requests is programmable by software (four levels per channel: very high, high, medium, low) and by hardware in case of equality (such as request to channel 1 has priority over request to channel 2).
 - Transfer size of source and destination are independent (byte, half-word, word), emulating packing and unpacking. Source and destination addresses must be aligned on the data size.
 - Support of transfers from/to peripherals to/from memory with circular buffer management
 - Programmable number of data to be transferred: 0 to $2^{16} - 1$
- Generation of an interrupt request per channel. Each interrupt request originates from any of the three DMA events: transfer complete, half transfer, or transfer error.

3.12 DMA request multiplexer (DMAMUX)

The DMAMUX request multiplexer enables routing a DMA request line between the peripherals and the DMA controller. Each channel selects a unique DMA request line, unconditionally or synchronously with events from its DMAMUX synchronization inputs. DMAMUX may also be used as a DMA request generator from programmable events on its input trigger signals.

3.13 Interrupts and events

The device flexibly manages events causing interrupts of linear program execution, called exceptions. The Cortex-M0+ processor core, a nested vectored interrupt controller (NVIC) and an extended interrupt/event controller (EXTI) are the assets contributing to handling the exceptions. Exceptions include core-internal events such as, for example, a division by zero and, core-external events such as logical level changes on physical lines. Exceptions result in interrupting the program flow, executing an interrupt service routine (ISR) then resuming the original program flow.

The processor context (contents of program pointer and status registers) is stacked upon program interrupt and unstacked upon program resume, by hardware. This avoids context stacking and unstacking in the interrupt service routines (ISRs) by software, thus saving time, code and power. The ability to abandon and restart load-multiple and store-multiple operations significantly increases the device's responsiveness in processing exceptions.

3.13.1 Nested vectored interrupt controller (NVIC)

The configurable nested vectored interrupt controller is tightly coupled with the core. It handles physical line events associated with a non-maskable interrupt (NMI) and maskable interrupts, and Cortex-M0+ exceptions. It provides flexible priority management.

The tight coupling of the processor core with NVIC significantly reduces the latency between interrupt events and start of corresponding interrupt service routines (ISRs). The ISR vectors are listed in a vector table, stored in the NVIC at a base address. The vector address of an ISR to execute is hardware-built from the vector table base address and the ISR order number used as offset.

If a higher-priority interrupt event happens while a lower-priority interrupt event occurring just before is waiting for being served, the later-arriving higher-priority interrupt event is served first. Another optimization is called tail-chaining. Upon a return from a higher-priority ISR then start of a pending lower-priority ISR, the unnecessary processor context unstacking and stacking is skipped. This reduces latency and contributes to power efficiency.

Features of the NVIC:

- Low-latency interrupt processing
- 4 priority levels
- Handling of a non-maskable interrupt (NMI)
- Handling of 32 maskable interrupt lines
- Handling of 10 Cortex-M0+ exceptions
- Later-arriving higher-priority interrupt processed first
- Tail-chaining
- Interrupt vector retrieval by hardware

3.13.2 Extended interrupt/event controller (EXTI)

The extended interrupt/event controller adds flexibility in handling physical line events and allows identifying wake-up events at processor wakeup from Stop mode.

The EXTI controller has a number of channels, of which some with rising, falling or rising, and falling edge detector capability. Any GPIO and a few peripheral signals can be connected to these channels.

The channels can be independently masked.

The EXTI controller can capture pulses shorter than the internal clock period.

A register in the EXTI controller latches every event even in Stop mode, which allows the software to identify the origin of the processor's wake-up from Stop mode or, to identify the GPIO and the edge event having caused an interrupt.

3.14 Analog-to-digital converter (ADC)

A native 12-bit analog-to-digital converter is embedded into STM32G0B1xB/xC/xE devices. It can be extended to 16-bit resolution through hardware oversampling. The ADC has up to 16 external channels and 3 internal channels (temperature sensor, voltage reference, V_{BAT} monitoring). It performs conversions in single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC frequency is independent from the CPU frequency, allowing maximum sampling rate of ~2 MSps even with a low CPU speed. An auto-shutdown function guarantees that the ADC is powered off except during the active conversion phase.

The ADC can be served by the DMA controller. It can operate in the whole V_{DD} supply range.

The ADC features a hardware oversampler up to 256 samples, improving the resolution to 16 bits (refer to AN2668).

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all scanned channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers (TIMx) can be internally connected to the ADC start triggers, to allow the application to synchronize A/D conversions with timers.

3.14.1 Temperature sensor

The temperature sensor (TS) generates a voltage V_{TS} that varies linearly with temperature.

The temperature sensor is internally connected to an ADC input to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it has to be calibrated to obtain good overall accuracy of the temperature measurement. As the offset of the temperature sensor may vary from part to part due to process variation, the uncalibrated internal temperature sensor is suitable only for relative temperature measurements.

To improve the accuracy of the temperature sensor, each part is individually factory-calibrated by ST. The resulting calibration data are stored in the part's engineering bytes, accessible in read-only mode.

Table 5. Temperature sensor calibration values

Calibration value name	Description	Memory address
TS_CAL1	TS ADC raw data acquired at a temperature of 30 °C (± 5 °C), $V_{DDA} = V_{REF+} = 3.0$ V (± 10 mV)	0x1FFF 75A8 - 0x1FFF 75A9
TS_CAL2	TS ADC raw data acquired at a temperature of 130 °C (± 5 °C), $V_{DDA} = V_{REF+} = 3.0$ V (± 10 mV)	0x1FFF 75CA - 0x1FFF 75CB

3.14.2 Internal voltage reference (V_{REFINT})

The internal voltage reference (V_{REFINT}) provides a stable (bandgap) voltage output for the ADC and comparators. V_{REFINT} is internally connected to an ADC input. The V_{REFINT} voltage is individually precisely measured for each part by ST during production test and stored in the part's engineering bytes. It is accessible in read-only mode.

Table 6. Internal voltage reference calibration values

Calibration value name	Description	Memory address
V_{REFINT}	Raw data acquired at a temperature of 30 °C (± 5 °C), $V_{DDA} = V_{REF+} = 3.0$ V (± 10 mV)	0x1FFF 75AA - 0x1FFF 75AB

3.14.3 V_{BAT} battery voltage monitoring

This embedded hardware feature allows the application to measure the V_{BAT} battery voltage using an internal ADC input. As the V_{BAT} voltage may be higher than V_{DDA} and thus outside the ADC input range, the VBAT pin is internally connected to a bridge divider by three. As a consequence, the converted digital value is one third the V_{BAT} voltage.

3.15 Digital-to-analog converter (DAC)

The 2-channel 12-bit buffered DAC converts a digital value into an analog voltage available on the channel output. The architecture of either channel is based on integrated resistor string and an inverting amplifier. The digital circuitry is common for both channels.

Features of the DAC:

- Two DAC output channels
- 8-bit or 12-bit output mode
- Buffer offset calibration (factory and user trimming)
- Left or right data alignment in 12-bit mode
- Synchronized update capability
- Noise-wave generation
- Triangular-wave generation
- Independent or simultaneous conversion for DAC channels
- DMA capability for either DAC channel
- Triggering with timer events, synchronized with DMA
- Triggering with external events
- Sample-and-hold low-power mode, with internal or external capacitor

3.16 Voltage reference buffer (VREFBUF)

When enabled, an embedded buffer provides the internal reference voltage to analog blocks (for example ADC) and to VREF+ pin for external components.

The internal voltage reference buffer supports two voltages:

- 2.048 V
- 2.5 V

An external voltage reference can be provided through the VREF+ pin when the internal voltage reference buffer is disabled.

On some packages, the VREF+ pad of the silicon die is double-bonded with supply pad to common VDD/VDDA pin and so the internal voltage reference buffer cannot be used.

3.17 Comparators (COMP)

Three embedded rail-to-rail analog comparators have programmable reference voltage (internal or external), hysteresis, speed (low for low-power) and output polarity.

The reference voltage can be one of the following:

- external, from an I/O
- internal, from DAC
- internal reference voltage (V_{REFINT}) or its submultiple (1/4, 1/2, 3/4)

The comparators can wake up the device from Stop mode, generate interrupts, breaks or triggers for the timers and can be also combined into a window comparator.

3.18 Timers and watchdogs

The device includes an advanced-control timer, seven general-purpose timers, two basic timers, two low-power timers, two watchdog timers and a SysTick timer. [Table 7](#) compares features of the advanced-control, general-purpose and basic timers.

Table 7. Timer feature comparison

Timer type	Timer	Counter resolution	Counter type	Maximum operating frequency	Prescaler factor	DMA request generation	Capture/compare channels	Complementary outputs
Advanced-control	TIM1	16-bit	Up, down, up/down	128 MHz	Integer from 1 to 2 ¹⁶	Yes	4	3
General-purpose	TIM2	32-bit	Up, down, up/down	64 MHz	Integer from 1 to 2 ¹⁶	Yes	4	-
	TIM3	16-bit	Up, down, up/down	64 MHz	Integer from 1 to 2 ¹⁶	Yes	4	-
	TIM4	16-bit	Up, down, up/down	64 MHz	Integer from 1 to 2 ¹⁶	Yes	4	-
	TIM14	16-bit	Up	64 MHz	Integer from 1 to 2 ¹⁶	No	1	-
	TIM15	16-bit	Up	128 MHz	Integer from 1 to 2 ¹⁶	Yes	2	1
	TIM16 TIM17	16-bit	Up	64 MHz	Integer from 1 to 2 ¹⁶	Yes	1	1
Basic	TIM6 TIM7	16-bit	Up	64 MHz	Integer from 1 to 2 ¹⁶	Yes	-	-
Low-power	LPTIM1 LPTIM2	16-bit	Up	64 MHz	2 ⁿ where n=0 to 7	No	N/A	-

3.18.1 Advanced-control timer (TIM1)

The advanced-control timer can be seen as a three-phase PWM unit multiplexed on 6 channels. It has complementary PWM outputs with programmable inserted dead-times. It can also be seen as a complete general-purpose timer. The four independent channels can be used for:

- input capture
- output compare
- PWM output (edge or center-aligned modes) with full modulation capability (0-100%)
- one-pulse mode output

In debug mode, the advanced-control timer counter can be frozen and the PWM outputs disabled, so as to turn off any power switches driven by these outputs.

Many features are shared with those of the general-purpose TIMx timers (described in [Section 3.18.2](#)) using the same architecture, so the advanced-control timers can work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

3.18.2 General-purpose timers (TIM2, 3, 4, 14, 15, 16, 17)

There are seven synchronizable general-purpose timers embedded in the device (refer to [Table 7](#) for comparison). Each general-purpose timer can be used to generate PWM outputs or act as a simple timebase.

- TIM2, TIM3, and TIM4

These are full-featured general-purpose timers:

- TIM2 with 32-bit auto-reload up/downcounter and 16-bit prescaler
- TIM3 and TIM4 with 16-bit auto-reload up/downcounter and 16-bit prescaler

They have four independent channels for input capture/output compare, PWM or one-pulse mode output. They can operate in combination with other general-purpose timers via the Timer Link feature for synchronization or event chaining. They can generate independent DMA request and support quadrature encoders. Their counter can be frozen in debug mode.

- TIM14

This timer is based on a 16-bit auto-reload upcounter and a 16-bit prescaler. It has one channel for input capture/output compare, PWM output or one-pulse mode output. Its counter can be frozen in debug mode.

- TIM15, TIM16, TIM17

These are general-purpose timers featuring:

- 16-bit auto-reload upcounter and 16-bit prescaler
- 2 channels and 1 complementary channel for TIM15
- 1 channel and 1 complementary channel for TIM16 and TIM17

All channels can be used for input capture/output compare, PWM or one-pulse mode output. The timers can operate together via the Timer Link feature for synchronization or event chaining. They can generate independent DMA request. Their counters can be frozen in debug mode.

3.18.3 Basic timers (TIM6 and TIM7)

These timers are mainly used for triggering DAC conversions. They can also be used as generic 16-bit timebases.

3.18.4 Low-power timers (LPTIM1 and LPTIM2)

These timers have an independent clock. When fed with LSE, LSI or external clock, they keep running in Stop mode and they can wake up the system from it.

Features of LPTIM1 and LPTIM2:

- 16-bit up counter with 16-bit autoreload register
- 16-bit compare register
- Configurable output (pulse, PWM)
- Continuous/one-shot mode
- Selectable software/hardware input trigger
- Selectable clock source:
 - Internal: LSE, LSI, HSI16 or APB clocks
 - External: over LPTIM input (working even with no internal clock source running, used by pulse counter application)
- Programmable digital glitch filter
- Encoder mode

3.18.5 Independent watchdog (IWDG)

The independent watchdog is based on an 8-bit prescaler and 12-bit downcounter with user-defined refresh window. It is clocked from an independent 32 kHz internal RC (LSI). Independent of the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes. Its counter can be frozen in debug mode.

3.18.6 System window watchdog (WWDG)

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked by the system clock. It has an early-warning interrupt capability. Its counter can be frozen in debug mode.

3.18.7 SysTick timer

This timer is dedicated to real-time operating systems, but it can also be used as a standard down counter.

Features of SysTick timer:

- 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source

3.19 Real-time clock (RTC), tamper (TAMP) and backup registers

The device embeds an RTC and five 32-bit backup registers, located in the RTC domain of the silicon die.

The ways of powering the RTC domain are described in [Section 3.7.6](#).

The RTC is an independent BCD timer/counter.

Features of the RTC:

- Calendar with subsecond, seconds, minutes, hours (12 or 24 format), week day, date, month, year, in BCD (binary-coded decimal) format
- Automatic correction for 28, 29 (leap year), 30, and 31 days of the month
- Programmable alarm
- On-the-fly correction from 1 to 32767 RTC clock pulses, usable for synchronization with a master clock
- Reference clock detection - a more precise second-source clock (50 or 60 Hz) can be used to improve the calendar precision
- Digital calibration circuit with 0.95 ppm resolution, to compensate for quartz crystal inaccuracy
- Two anti-tamper detection pins with programmable filter
- Timestamp feature to save a calendar snapshot, triggered by an event on the timestamp pin or a tamper event, or by switching to VBAT mode
- 17-bit auto-reload wakeup timer (WUT) for periodic events, with programmable resolution and period
- Multiple clock sources and references:
 - A 32.768 kHz external crystal (LSE)
 - An external resonator or oscillator (LSE)
 - The internal low-power RC oscillator (LSI, with typical frequency of 32 kHz)
 - The high-speed external clock (HSE) divided by 32

When clocked by LSE, the RTC operates in VBAT mode and in all low-power modes. When clocked by LSI, the RTC does not operate in VBAT mode, but it does in low-power modes except for the Shutdown mode.

All RTC events (Alarm, WakeUp Timer, Timestamp or Tamper) can generate an interrupt and wake the device up from the low-power modes.

The backup registers allow keeping 20 bytes of user application data in the event of V_{DD} failure, if a valid backup supply voltage is provided on VBAT pin. They are not affected by the system reset, power reset, and upon the device's wakeup from Standby or Shutdown modes.

3.20 Inter-integrated circuit interface (I2C)

The device embeds three I2C peripherals. Refer to [Table 8](#) for the features.

The I²C-bus interface handles communication between the microcontroller and the serial I²C-bus. It controls all I²C-bus-specific sequencing, protocol, arbitration and timing.

Features of the I2C peripheral:

- I²C-bus specification and user manual rev. 5 compatibility:
 - Slave and master modes, multimaster capability
 - Standard-mode (Sm), with a bitrate up to 100 kbit/s
 - Fast-mode (Fm), with a bitrate up to 400 kbit/s
 - Fast-mode Plus (Fm+), with a bitrate up to 1 Mbit/s and extra output drive I/Os
 - 7-bit and 10-bit addressing mode, multiple 7-bit slave addresses
 - Programmable setup and hold times
 - Clock stretching
- SMBus specification rev 3.0 compatibility:
 - Hardware PEC (packet error checking) generation and verification with ACK control
 - Command and data acknowledge control
 - Address resolution protocol (ARP) support
 - Host and Device support
 - SMBus alert
 - Timeouts and idle condition detection
- PMBus rev 1.3 standard compatibility
- Independent clock: a choice of independent clock sources allowing the I2C communication speed to be independent of the PCLK reprogramming
- Wakeup from Stop mode on address match
- Programmable analog and digital noise filters
- 1-byte buffer with DMA capability

Table 8. I²C implementation

I ² C features ⁽¹⁾	I2C1 I2C2	I2C3
Standard mode (up to 100 kbit/s)	X	X
Fast mode (up to 400 kbit/s)	X	X
Fast Mode Plus (up to 1 Mbit/s) with extra output drive I/Os	X	X
Programmable analog and digital noise filters	X	X
SMBus/PMBus hardware support	X	-
Independent clock	X	-
Wakeup from Stop mode on address match	X	-

1. X: supported

3.21 Universal synchronous/asynchronous receiver transmitter (USART)

The device embeds universal synchronous/asynchronous receivers/transmitters that communicate at speeds of up to 8 Mbit/s.

They provide hardware management of the CTS, RTS and RS485 DE signals, multiprocessor communication mode, master synchronous communication and single-wire half-duplex communication mode. Some can also support SmartCard communication (ISO 7816), IrDA SIR ENDEC, LIN Master/Slave capability and auto baud rate feature, and have a clock domain independent of the CPU clock, which allows them to wake up the MCU from Stop mode. The wakeup events from Stop mode are programmable and can be:

- start bit detection
- any received data frame
- a specific programmed data frame

All USART interfaces can be served by the DMA controller.

Table 9. USART implementation

USART modes/features ⁽¹⁾	USART1 USART2 USART3	USART4 USART5 USART6
Hardware flow control for modem	X	X
Continuous communication using DMA	X	X
Multiprocessor communication	X	X
Synchronous mode	X	X
Smartcard mode	X	-
Single-wire half-duplex communication	X	X
IrDA SIR ENDEC block	X	-
LIN mode	X	-
Dual clock domain and wakeup from Stop mode	X	-
Receiver timeout interrupt	X	-
Modbus communication	X	-
Auto baud rate detection	X	-
Driver Enable	X	X

1. X: supported

3.22 Low-power universal asynchronous receiver transmitter (LPUART)

The device embeds two LPUARTs. The peripheral supports asynchronous serial communication with minimum power consumption. It supports half duplex single wire communication and modem operations (CTS/RTS). It allows multiprocessor communication.

The LPUART has a clock domain independent of the CPU clock, and can wakeup the system from Stop mode. The Stop mode wakeup events are programmable and can be:

- start bit detection
- any received data frame
- a specific programmed data frame

Only a 32.768 kHz clock (LSE) is needed to allow LPUART communication up to 9600 baud. Therefore, even in Stop mode, the LPUART can wait for an incoming frame while having an extremely low energy consumption. Higher speed clock can be used to reach higher baudrates.

The LPUART interface can be served by the DMA controller.

3.23 Serial peripheral interface (SPI)

The device contains three SPIs running at up to 32 Mbits/s in master and slave modes. It supports half-duplex, full-duplex and simplex communications. A 3-bit prescaler gives eight master mode frequencies. The frame size is configurable from 4 bits to 16 bits. The SPI peripherals support NSS pulse mode, TI mode and hardware CRC calculation.

The SPI peripherals can be served by the DMA controller.

The I²S interface mode of the SPI peripheral (if supported, see the following table) supports four different audio standards can operate as master or slave, in half-duplex communication mode. It can be configured to transfer 16 and 24 or 32 bits with 16-bit or 32-bit data resolution and synchronized by a specific signal. Audio sampling frequency from 8 kHz up to 192 kHz can be set by an 8-bit programmable linear prescaler. When operating in master mode, it can output a clock for an external audio component at 256 times the sampling frequency.

Table 10. SPI/I2S implementation

SPI features ⁽¹⁾	SPI1 SPI2	SPI3
Hardware CRC calculation	X	X
Rx/Tx FIFO	X	X
NSS pulse mode	X	X
I ² S mode	X	-
TI mode	X	X

1. X = supported.

3.24 Universal serial bus device (USB) and host (USBH)

The devices embed a USB controller with full-speed USB device and host functionality compliant with the USB specification version 2.0. The internal USB PHY supports USB FS signaling, embedded DP pull-up and also battery charging detection according to Battery Charging Specification Revision 1.2. The USB interface implements a full-speed (12 Mbit/s) function interface with added support for USB 2.0 Link Power Management. It has software-configurable endpoint setting with packet memory up to 1 KB and suspend/resume support. It requires a precise 48 MHz clock that is generated from the internal main PLL (the clock source must use a HSE crystal oscillator) or by the internal 48 MHz oscillator in automatic trimming mode. The synchronization for this oscillator can be taken from the USB data stream itself (SOF signalization) which allows crystal less operation.

3.25 USB Type-C™ Power Delivery controller

The device embeds two controllers (UCPD1 and UCPD2) compliant with USB Type-C Rev. 1.2 and USB Power Delivery Rev. 3.0 specifications.

The controllers use specific I/Os supporting the USB Type-C and USB Power Delivery requirements, featuring:

- USB Type-C pull-up (R_p , all values) and pull-down (R_d) resistors
- “Dead battery” support
- USB Power Delivery message transmission and reception
- FRS (fast role swap) support

The digital controller handles notably:

- USB Type-C level detection with de-bounce, generating interrupts
- FRS detection, generating an interrupt
- byte-level interface for USB Power Delivery payload, generating interrupts (DMA compatible)
- USB Power Delivery timing dividers (including a clock pre-scaler)
- CRC generation/checking
- 4b5b encode/decode
- ordered sets (with a programmable ordered set mask at receive)
- frequency recovery in receiver during preamble

The interface offers low-power operation compatible with Stop mode, maintaining the capacity to detect incoming USB Power Delivery messages and FRS signaling.

3.26 Controller area network (FDCAN)

The controller area network (CAN) subsystem consists of two CAN modules and a message RAM.

The CAN modules are compliant with ISO 11898-1 (CAN protocol specification version 2.0 part A, B) and CAN FD protocol specification version 1.0.

The 1-Kbyte message RAM per CAN module implements filters, receive FIFOs, receive buffers, transmit event FIFOs, and transmit buffers.

3.27 Development support

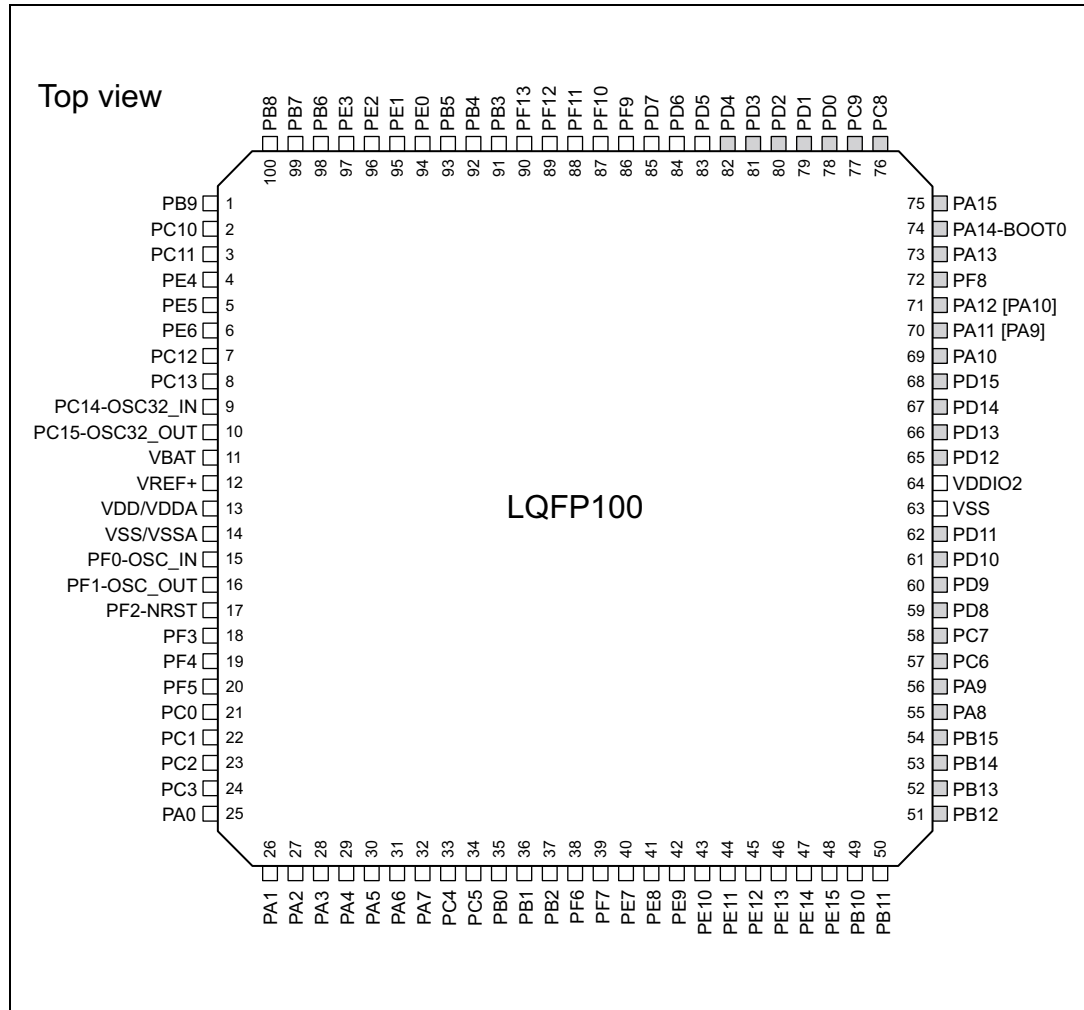
3.27.1 Serial wire debug port (SW-DP)

An Arm SW-DP interface is provided to allow a serial wire debugging tool to be connected to the MCU.

4 Pinouts, pin description and alternate functions

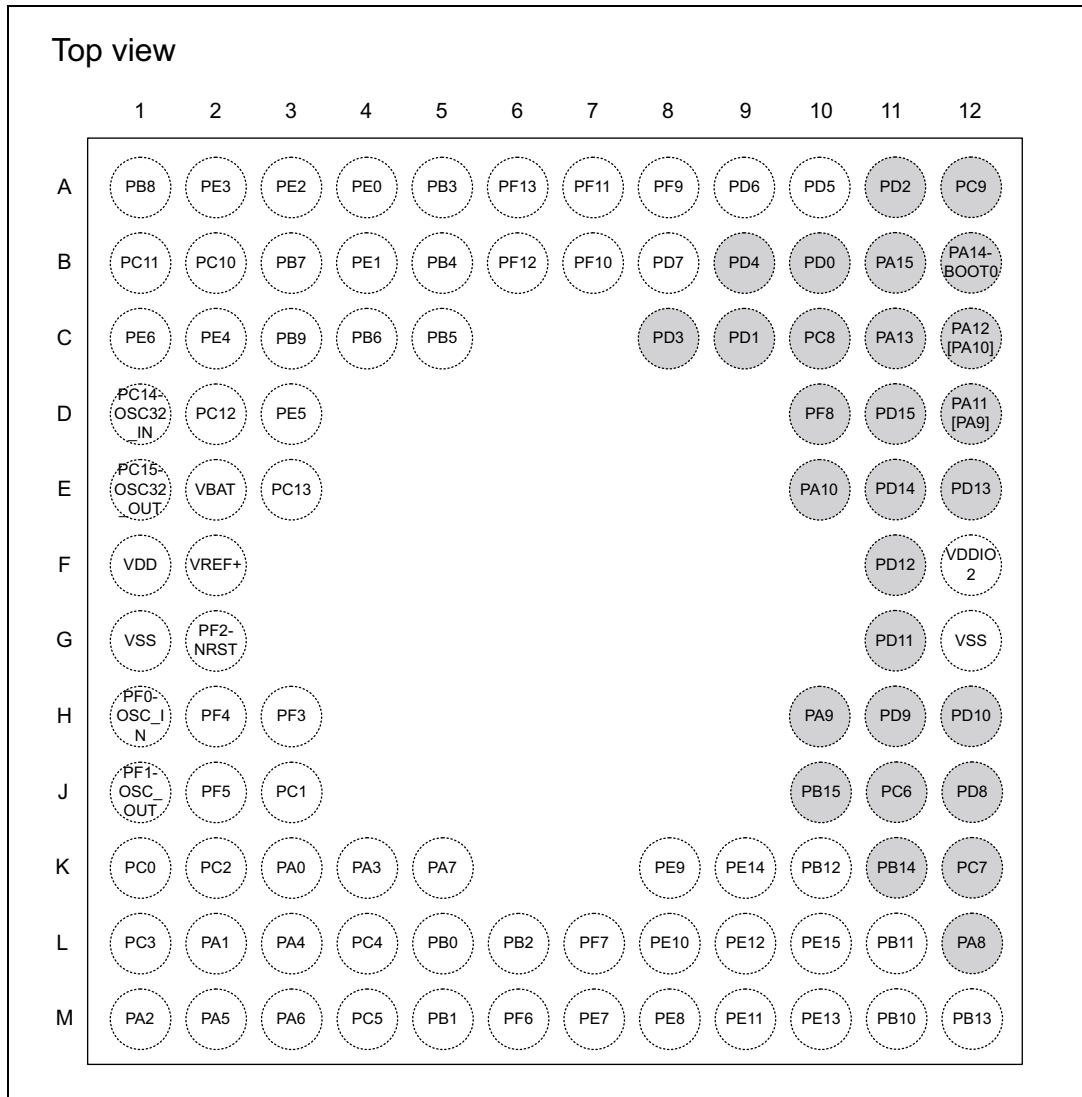
The devices housed in 32-pin, 48-pin, and 64-pin packages come in two variants - "GP" and "N" (the latter with ordering code having N behind the temperature range digit). Refer to [Table 2: Features and peripheral counts](#) for differences.

Figure 3. STM32G0B1VxT LQFP100 pinout



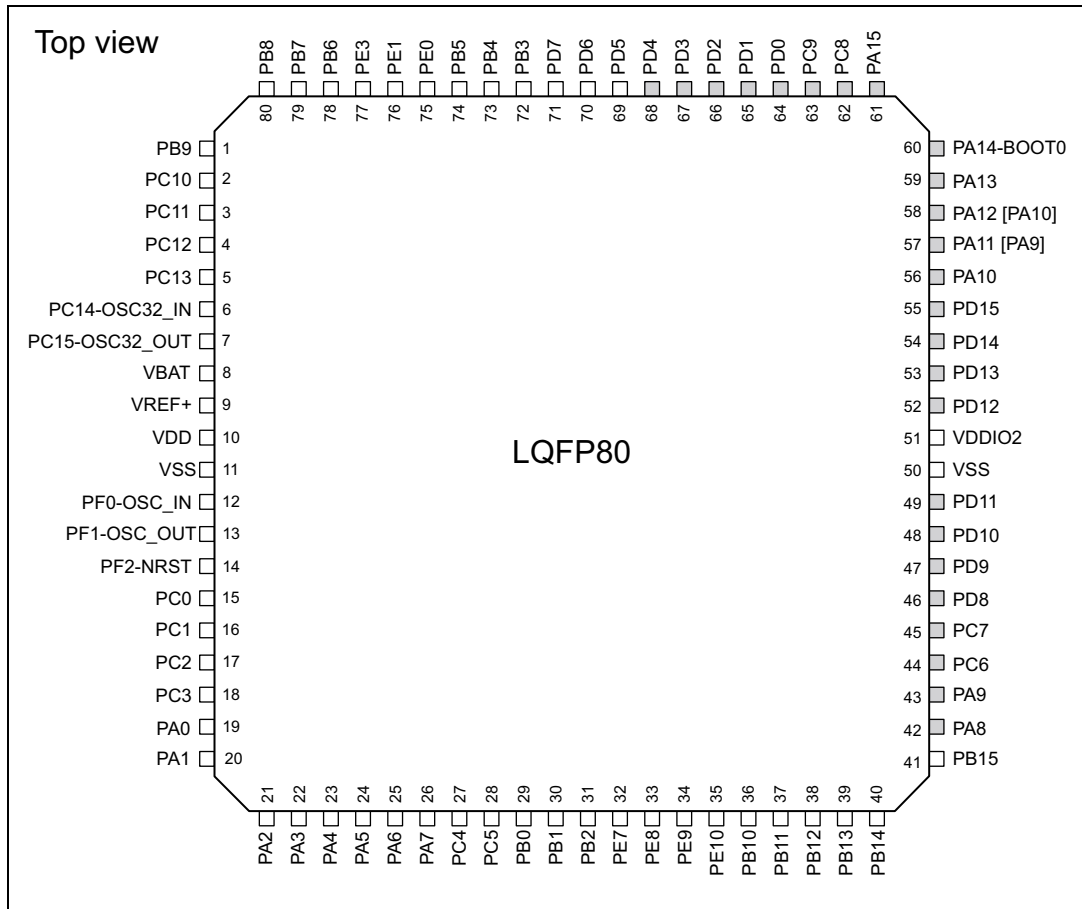
1. The I/O pins supplied by V_{DIO2} are shown in gray.

Figure 4. STM32G0B1Vxl UFBGA100 pinout



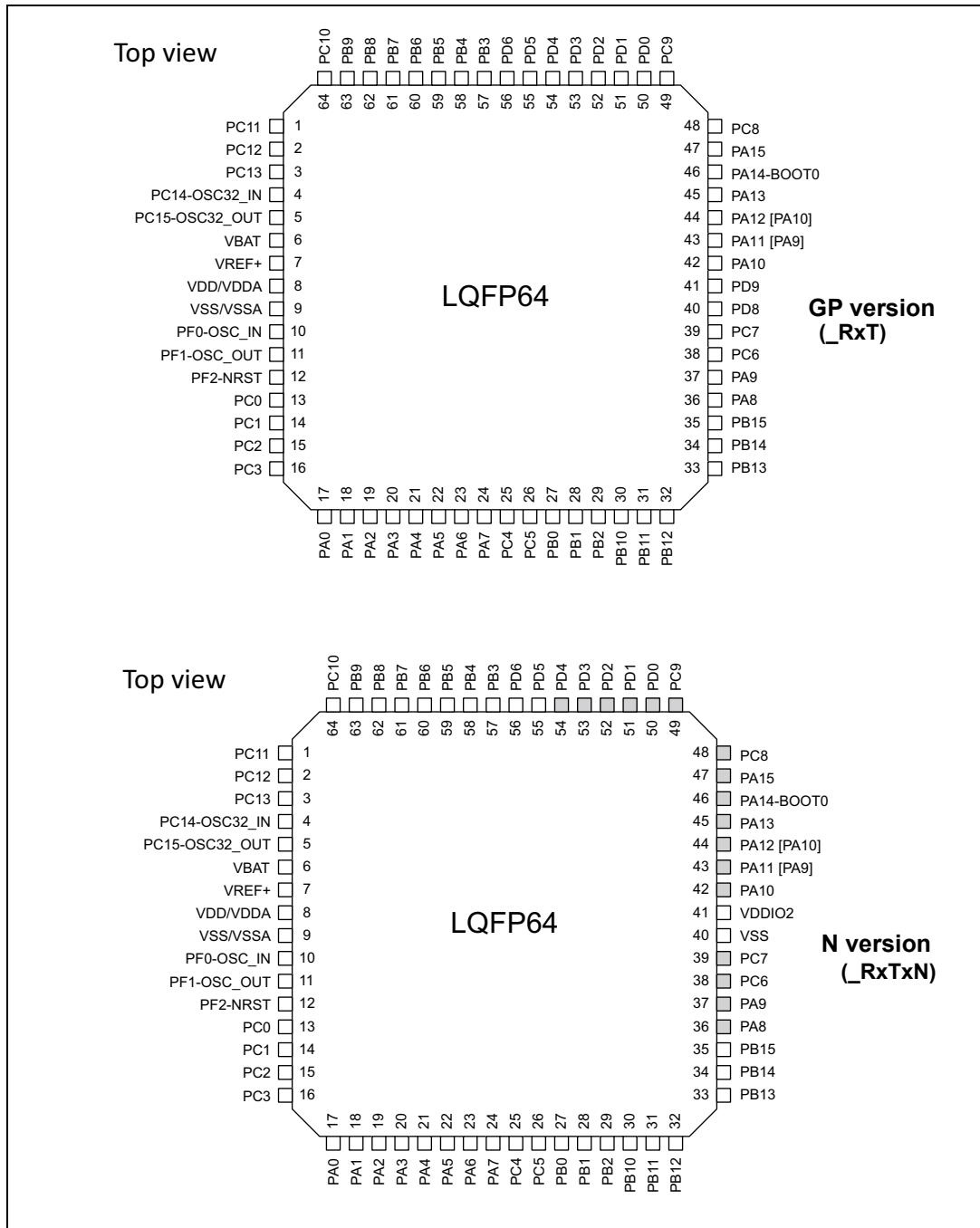
1. The I/O pads supplied by V_{DDIO2} are shown in gray.

Figure 5. STM32G0B1MxT LQFP80 pinout



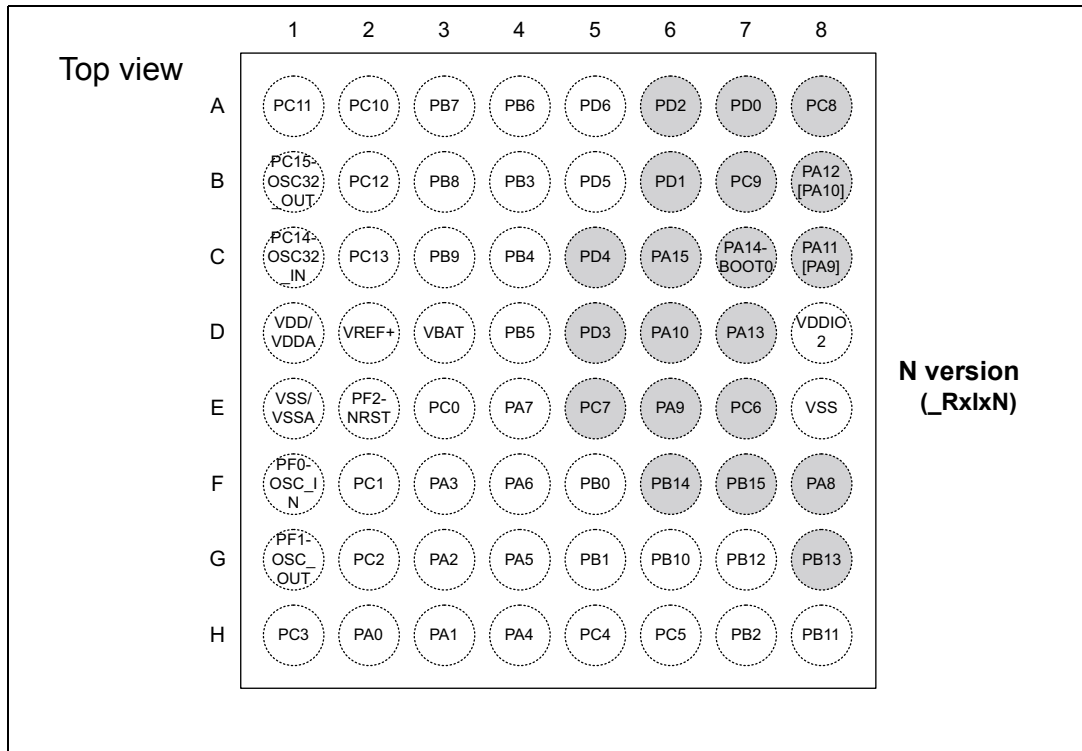
1. The I/O pins supplied by V_{DDIO2} are shown in gray.

Figure 6. STM32G0B1RxT LQFP64 pinout



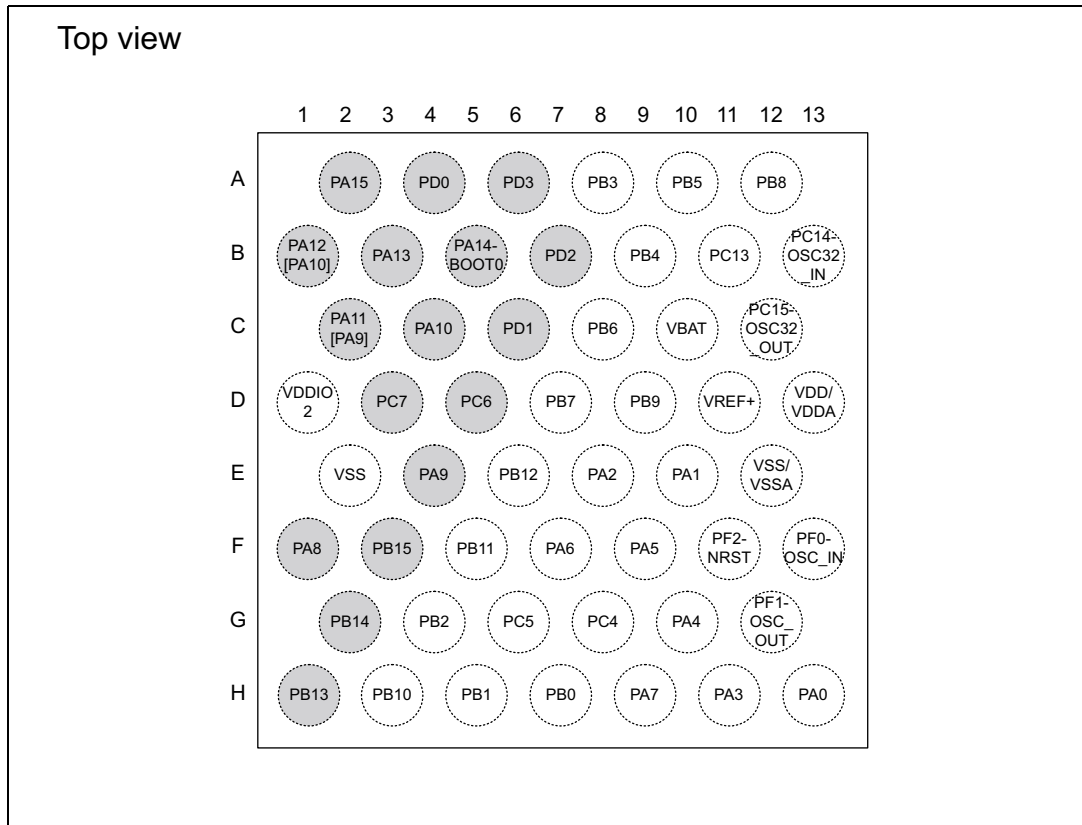
1. The I/O pins supplied by V_{DDIO2} are shown in gray.

Figure 7. STM32G0B1RxI UFBGA64 pinout



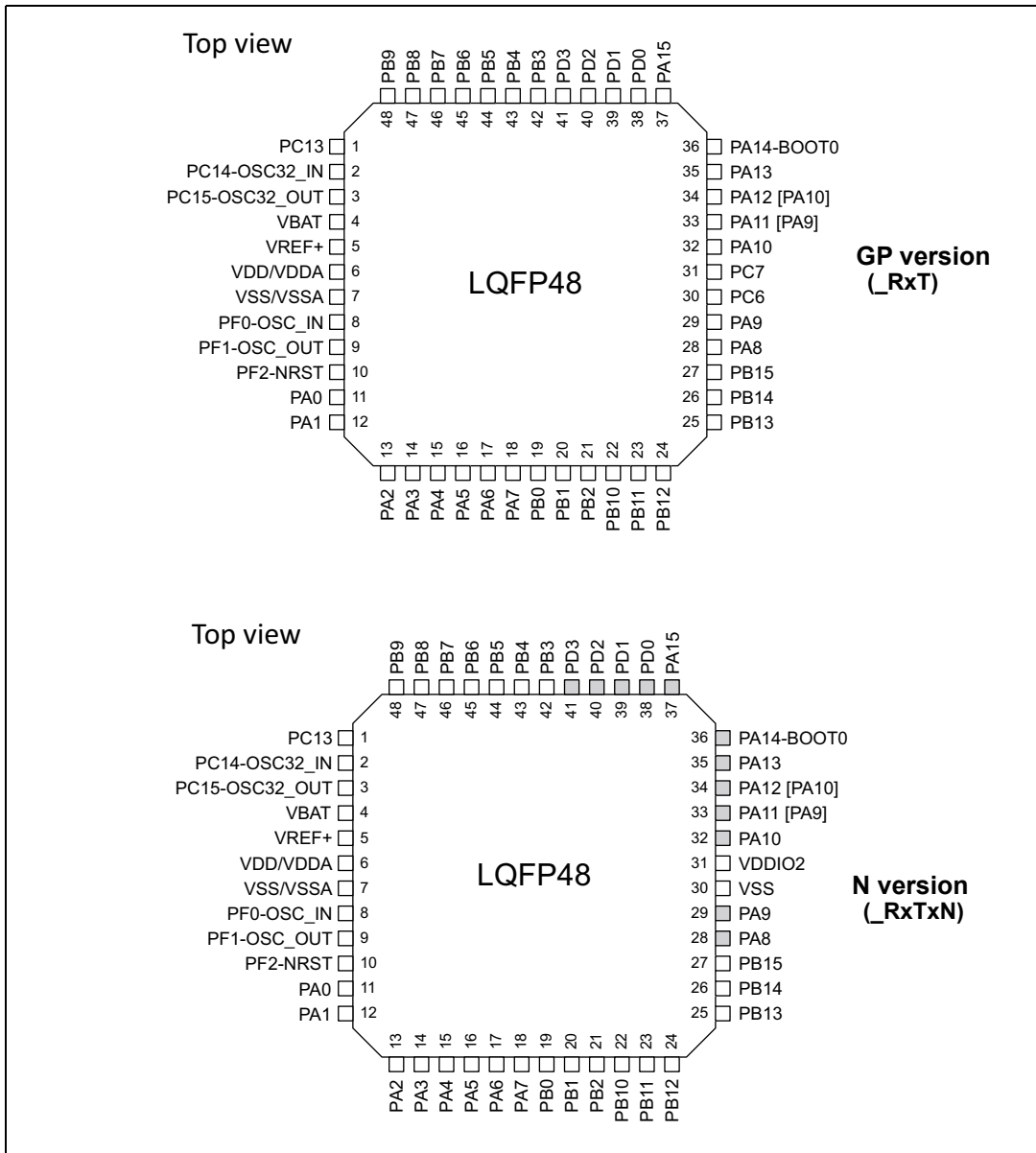
1. The I/O pads supplied by V_{DDIO2} are shown in gray.

Figure 8. STM32G0B1NxY WLCSP52 pinout



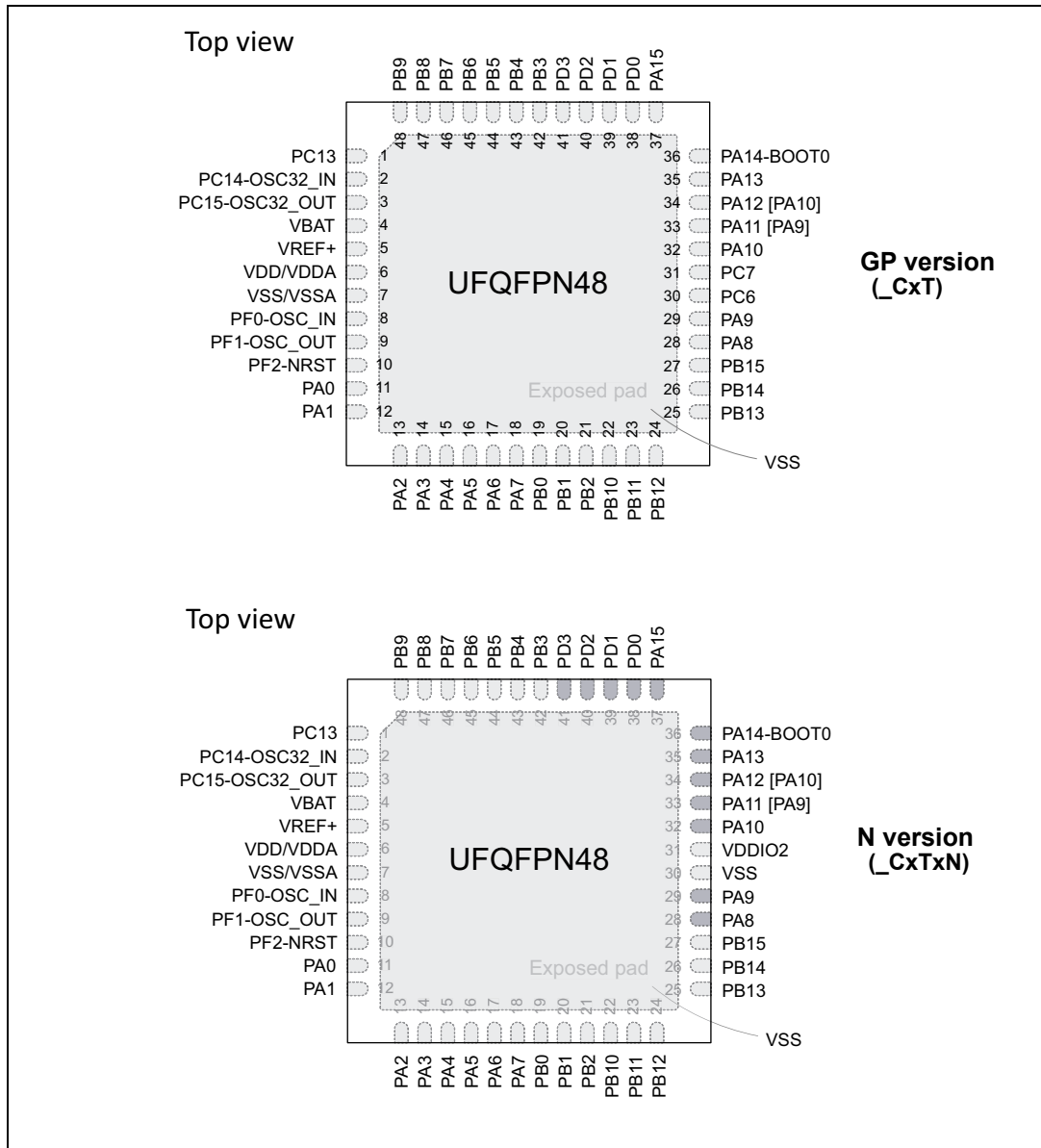
1. The I/O pads supplied by V_{DDIO2} are shown in gray.

Figure 9. STM32G0B1CxT LQFP48 pinout



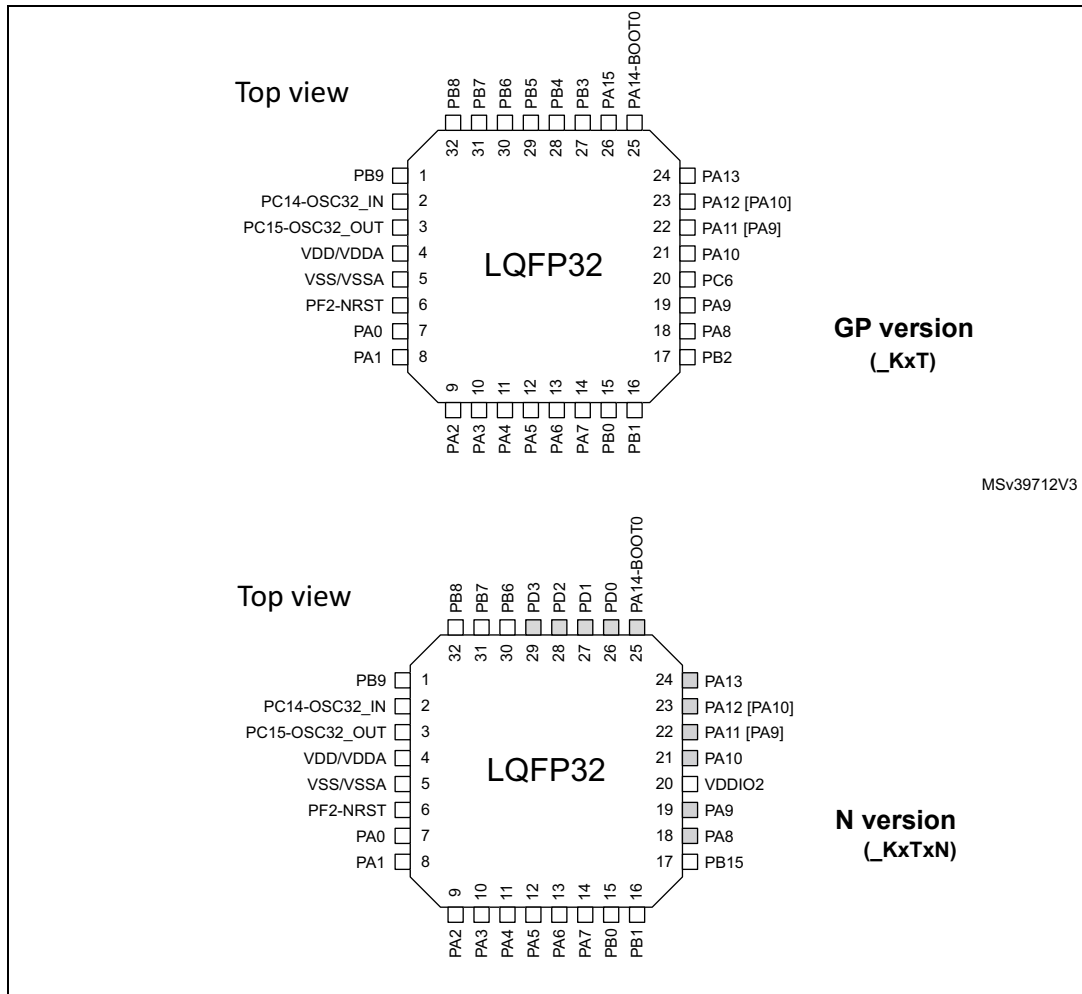
1. The I/O pins supplied by V_{DDIO2} are shown in gray.

Figure 10. STM32G0B1CxU UFQFPN48 pinout



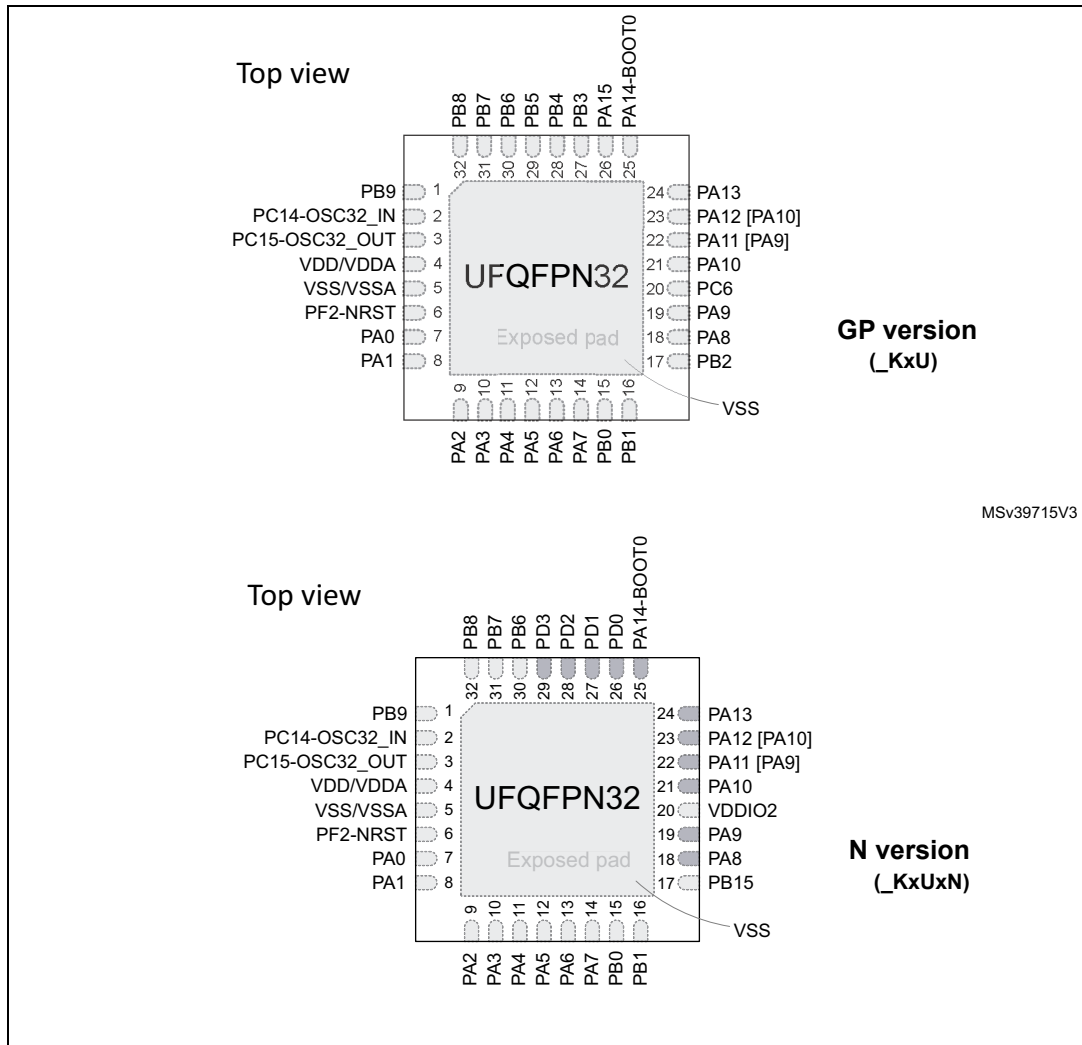
1. The I/O leads supplied by V_{DDIO2} are shown in dark gray.

Figure 11. STM32G0B1KxT LQFP32 pinout



1. The I/O pins supplied by V_{DDIO2} are shown in dark gray.

Figure 12. STM32G0B1KxU UFQFPN32 pinout



MSv39715V3

1. The I/O leads supplied by V_{DDIO2} are shown in dark gray.

Table 11. Terms and symbols used in [Table 12](#)

Column	Symbol	Definition
Pin name	Terminal name corresponds to its by-default function at reset, unless otherwise specified in parenthesis under the pin name.	
Pin type	S	Supply pin
	I	Input only pin
	I/O	Input / output pin
I/O structure	FT	5 V tolerant I/O
	TT	3.6 V tolerant I/O
	RST	Bidirectional reset pin with embedded weak pull-up resistor
	Options for TT or FT I/Os	
	_f	I/O, Fm+ capable
	_a	I/O, with analog switch function
	_c	I/O, USB Type-C PD capable
	_e	I/O, with switchable diode to V _{DD}
	_d	I/O, USB Type-C PD Dead Battery function
Note	Upon reset, all I/Os are set as analog inputs, unless otherwise specified.	
Pin functions	Alternate functions	Functions selected through GPIOx_AFR registers
	Additional functions	Functions directly selected/enabled through peripheral registers



Table 14. Port A alternate function mapping (AF8 to AF15)

Port	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
PA0	-	-	-	-	-	-	-	-
PA1	-	-	-	-	-	-	-	-
PA2	-	-	-	-	-	-	-	-
PA3	-	-	-	-	-	-	-	-
PA4	-	SPI3_NSS	-	-	-	-	-	-
PA5	-	-	-	-	-	-	-	-
PA6	I2C2_SDA	I2C3_SDA	-	-	-	-	-	-
PA7	I2C2_SCL	I2C3_SCL	-	-	-	-	-	-
PA8	I2C2_SMBA	-	-	-	-	-	-	-
PA9	I2C2_SCL	-	-	-	-	-	-	-
PA10	I2C2_SDA	-	-	-	-	-	-	-
PA11	-	-	-	-	-	-	-	-
PA12	-	-	-	-	-	-	-	-
PA13	-	-	LPUART2_RX	-	-	-	-	-
PA14	-	-	LPUART2_TX	-	-	-	-	-
PA15	I2C2_SMBA	SPI3_NSS	-	-	-	-	-	-



Table 15. Port B alternate function mapping (AF0 to AF7)

Port	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PB0	SPI1_NSS/ I2S1_WS	TIM3_CH3	TIM1_CH2N	FDCAN2_RX	USART3_RX	LPTIM1_OUT	UCPD1_FRSTX	COMP1_OUT
PB1	TIM14_CH1	TIM3_CH4	TIM1_CH3N	FDCAN2_TX	USART3_RTS _DE_CK	LPTIM2_IN1	LPUART1_RTS _DE	COMP3_OUT
PB2	-	SPI2_MISO/ I2S2_MCK	-	MCO2	USART3_TX	LPTIM1_OUT	-	EVENTOUT
PB3	SPI1_SCK/ I2S1_CK	TIM1_CH2	TIM2_CH2	USART5_TX	USART1_RTS _DE_CK	-	I2C3_SCL	EVENTOUT
PB4	SPI1_MISO/ I2S1_MCK	TIM3_CH1	-	USART5_RX	USART1_CTS	TIM17_BKIN	I2C3_SDA	EVENTOUT
PB5	SPI1_MOSI/ I2S1_SD	TIM3_CH2	TIM16_BKIN	FDCAN2_RX	-	LPTIM1_IN1	I2C1_SMBA	COMP2_OUT
PB6	USART1_TX	TIM1_CH3	TIM16_CH1N	FDCAN2_TX	SPI2_MISO/ I2S2_MCK	LPTIM1_ETR	I2C1_SCL	EVENTOUT
PB7	USART1_RX	SPI2_MOSI/ I2S2_SD	TIM17_CH1N	-	USART4_CTS	LPTIM1_IN2	I2C1_SDA	EVENTOUT
PB8	CEC	SPI2_SCK/ I2S2_CK	TIM16_CH1	FDCAN1_RX	USART3_TX	TIM15_BKIN	I2C1_SCL	EVENTOUT
PB9	IR_OUT	UCPD2_FRSTX	TIM17_CH1	FDCAN1_TX	USART3_RX	SPI2_NSS/ I2S2_WS	I2C1_SDA	EVENTOUT
PB10	CEC	LPUART1_RX	TIM2_CH3	-	USART3_TX	SPI2_SCK/ I2S2_CK	I2C2_SCL	COMP1_OUT
PB11	SPI2_MOSI/ I2S2_SD	LPUART1_TX	TIM2_CH4	-	USART3_RX	-	I2C2_SDA	COMP2_OUT
PB12	SPI2_NSS/ I2S2_WS	LPUART1_RTS _DE	TIM1_BKIN	FDCAN2_RX	-	TIM15_BKIN	UCPD2_FRSTX	EVENTOUT
PB13	SPI2_SCK/ I2S2_CK	LPUART1_CTS	TIM1_CH1N	FDCAN2_TX	USART3_CTS	TIM15_CH1N	I2C2_SCL	EVENTOUT

**Table 15. Port B alternate function mapping (AF0 to AF7) (continued)**

Port	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PB14	SPI2_MISO/ I2S2_MCK	UCPD1_FRSTX	TIM1_CH2N	-	USART3_RTS _DE_CK	TIM15_CH1	I2C2_SDA	EVENTOUT
PB15	SPI2_MOSI/ I2S2_SD	-	TIM1_CH3N	-	TIM15_CH1N	TIM15_CH2	-	EVENTOUT

Table 16. Port B alternate function mapping (AF8 to AF15)

Port	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
PB0	USART5_TX	-	LPUART2_CTS	-	-	-	-	-
PB1	USART5_RX	-	LPUART2_RTS _DE	-	-	-	-	-
PB2	-	-	-	-	-	-	-	-
PB3	I2C2_SCL	SPI3_SCK	-	-	-	-	-	-
PB4	I2C2_SDA	SPI3_MISO	-	-	-	-	-	-
PB5	USART5_RTS _DE_CK	SPI3_MOSI	-	-	-	-	-	-
PB6	USART5_CTS	TIM4_CH1	LPUART2_TX	-	-	-	-	-
PB7	-	TIM4_CH2	LPUART2_RX	-	-	-	-	-
PB8	USART6_TX	TIM4_CH3	-	-	-	-	-	-
PB9	USART6_RX	TIM4_CH4	-	-	-	-	-	-
PB10	-	-	-	-	-	-	-	-
PB11	-	-	-	-	-	-	-	-
PB12	I2C2_SMBA	-	-	-	-	-	-	-
PB13	-	-	-	-	-	-	-	-
PB14	USART6_RTS _DE_CK	-	-	-	-	-	-	-
PB15	USART6_CTS	-	-	-	-	-	-	-



Table 17. Port C alternate function mapping

Port	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PC0	LPTIM1_IN1	LPUART1_RX	LPTIM2_IN1	LPUART2_TX	USART6_TX	-	I2C3_SCL	COMP3_OUT
PC1	LPTIM1_OUT	LPUART1_TX	TIM15_CH1	LPUART2_RX	USART6_RX	-	I2C3_SDA	-
PC2	LPTIM1_IN2	SPI2_MISO/ I2S2_MCK	TIM15_CH2	FDCAN2_RX	-	-	-	COMP3_OUT
PC3	LPTIM1_ETR	SPI2_MOSI/ I2S2_SD	LPTIM2_ETR	FDCAN2_TX	-	-	-	-
PC4	USART3_TX	USART1_TX	TIM2_CH1_ETR	FDCAN1_RX	-	-	-	-
PC5	USART3_RX	USART1_RX	TIM2_CH2	FDCAN1_TX	-	-	-	-
PC6	UCPD1_FRSTX	TIM3_CH1	TIM2_CH3	LPUART2_TX	-	-	-	-
PC7	UCPD2_FRSTX	TIM3_CH2	TIM2_CH4	LPUART2_RX	-	-	-	-
PC8	UCPD2_FRSTX	TIM3_CH3	TIM1_CH1	LPUART2_CTS	-	-	-	-
PC9	I2S_CKIN	TIM3_CH4	TIM1_CH2	LPUART2_RTS_ DE	-	-	USB_NOE	-
PC10	USART3_TX	USART4_TX	TIM1_CH3	-	SPI3_SCK	-	-	-
PC11	USART3_RX	USART4_RX	TIM1_CH4	-	SPI3_MISO	-	-	-
PC12	LPTIM1_IN1	UCPD1_FRSTX	TIM14_CH1	USART5_TX	SPI3_MOSI	-	-	-
PC13	-	-	TIM1_BKIN	-	-	-	-	-
PC14	-	-	TIM1_BKIN2	-	-	-	-	-
PC15	OSC32_EN	OSC_EN	TIM15_BKIN	-	-	-	-	-



Table 18. Port D alternate function mapping

Port	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PD0	EVENTOUT	SPI2_NSS/ I2S2_WS	TIM16_CH1	FDCAN1_RX	-	-	-	-
PD1	EVENTOUT	SPI2_SCK/ I2S2_CK	TIM17_CH1	FDCAN1_TX	-	-	-	-
PD2	USART3_RTS _DE_CK	TIM3_ETR	TIM1_CH1N	USART5_RX	-	-	-	-
PD3	USART2_CTS	SPI2_MISO/ I2S2_MCK	TIM1_CH2N	USART5_TX	-	-	-	-
PD4	USART2_RTS _DE_CK	SPI2_MOSI/ I2S2_SD	TIM1_CH3N	USART5_RTS _DE_CK	-	-	-	-
PD5	USART2_TX	SPI1_MISO/ I2S1_MCK	TIM1_BKIN	USART5_CTS	-	-	-	-
PD6	USART2_RX	SPI1_MOSI/ I2S1_SD	LPTIM2_OUT	-	-	-	-	-
PD7	-	-	-	MCO2	-	-	-	-
PD8	USART3_TX	SPI1_SCK/ I2S1_CK	LPTIM1_OUT	-	-	-	-	-
PD9	USART3_RX	SPI1_NSS/ I2S1_WS	TIM1_BKIN2	-	-	-	-	-
PD10	MCO	-	-	-	-	-	-	-
PD11	USART3_CTS	LPTIM2_ETR	-	-	-	-	-	-
PD12	USART3_RTS _DE_CK	LPTIM2_IN1	TIM4_CH1	FDCAN1_RX	-	-	-	-
PD13	-	LPTIM2_OUT	TIM4_CH2	FDCAN1_TX	-	-	-	-
PD14	-	LPUART2_CTS	TIM4_CH3	FDCAN2_RX	-	-	-	-
PD15	CRS1_SYNC	LPUART2_RTS _DE	TIM4_CH4	FDCAN2_TX	-	-	-	-



Table 19. Port E alternate function mapping

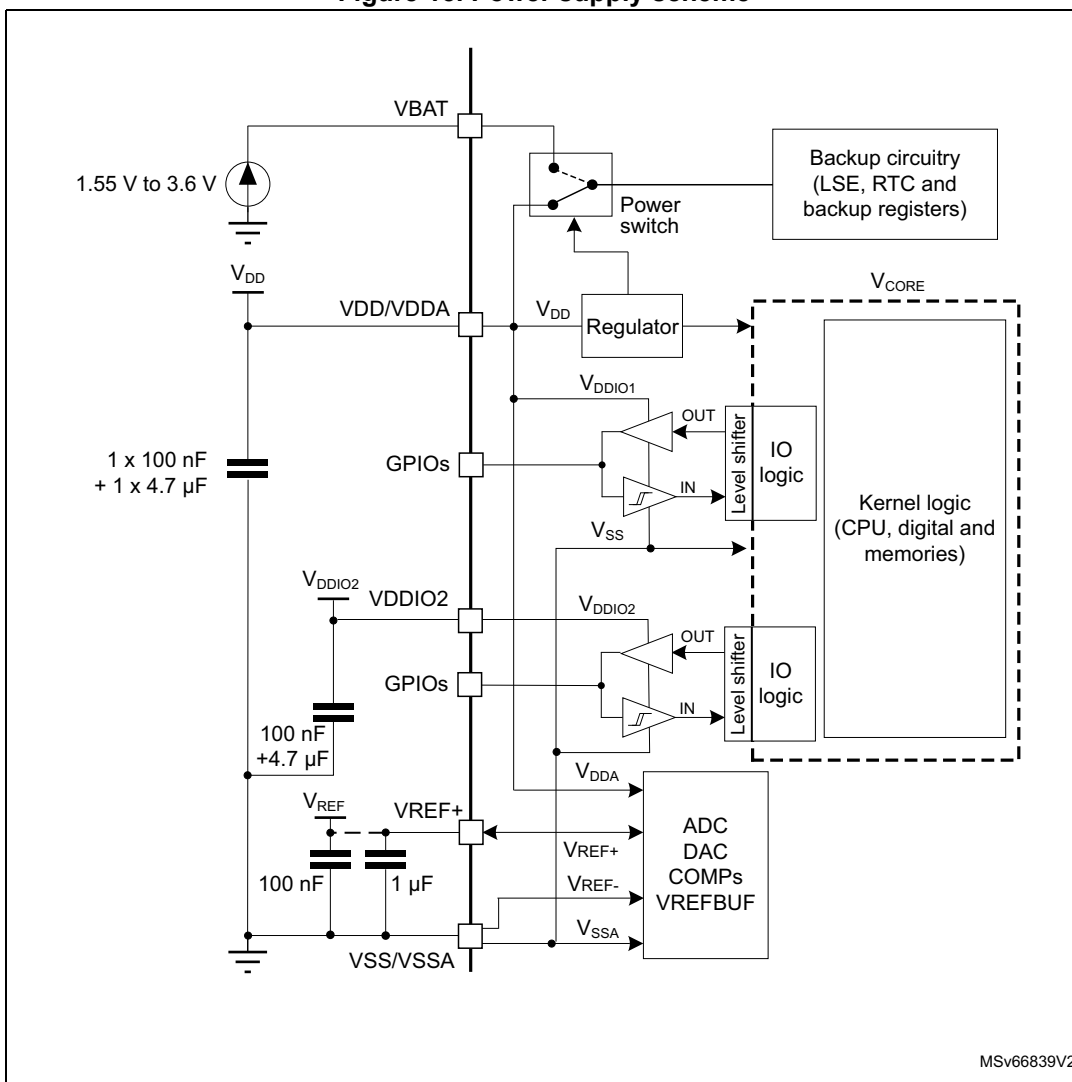
Port	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PE0	TIM16_CH1	EVENTOUT	TIM4_ETR	-	-	-	-	-
PE1	TIM17_CH1	EVENTOUT	-	-	-	-	-	-
PE2	-	TIM3_ETR	-	-	-	-	-	-
PE3	-	TIM3_CH1	-	-	-	-	-	-
PE4	-	TIM3_CH2	-	-	-	-	-	-
PE5	-	TIM3_CH3	-	-	-	-	-	-
PE6	-	TIM3_CH4	-	-	-	-	-	-
PE7	-	TIM1_ETR	-	USART5_RTS_D E_CK	-	-	-	-
PE8	USART4_TX	TIM1_CH1N	-	-	-	-	-	-
PE9	USART4_RX	TIM1_CH1	-	-	-	-	-	-
PE10	-	TIM1_CH2N	-	USART5_TX	-	-	-	-
PE11	-	TIM1_CH2	-	USART5_RX	-	-	-	-
PE12	SPI1_NSS/ I2S1_WS	TIM1_CH3N	-	-	-	-	-	-
PE13	SPI1_SCK/ I2S1_CK	TIM1_CH3	-	-	-	-	-	-
PE14	SPI1_MISO/I2S1 _MCK	TIM1_CH4	TIM1_BK2	-	-	-	-	-
PE15	SPI1_MOSI/I2S1 _SD	TIM1_BK	-	-	-	-	-	-

Table 20. Port F alternate function mapping

Port	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
PF0	CRS1_SYNC	EVENTOUT	TIM14_CH1	-	-	-	-	-
PF1	OSC_EN	EVENTOUT	TIM15_CH1N	-	-	-	-	-
PF2	MCO	LPUART2_TX	-	LPUART2_RTS_DE	-	-	-	-
PF3	-	LPUART2_RX	-	USART6_RTS_DE_CK	-	-	-	-
PF4	-	LPUART1_TX	-	-	-	-	-	-
PF5	-	LPUART1_RX	-	-	-	-	-	-
PF6	-	LPUART1_RTS_DE	-	-	-	-	-	-
PF7	-	LPUART1_CTS	-	USART5_CTS	-	-	-	-
PF8	-	-	-	-	-	-	-	-
PF9	-	-	-	USART6_TX	-	-	-	-
PF10	-	-	-	USART6_RX	-	-	-	-
PF11	-	-	-	USART6_RTS_DE_CK	-	-	-	-
PF12	TIM15_CH1	-	-	USART6_CTS	-	-	-	-
PF13	TIM15_CH2	-	-	-	-	-	-	-

5.1.6 Power supply scheme

Figure 15. Power supply scheme



MSv66839V2

Caution: Power supply pin pair (VDD/VDDA/VDDIO2 and VSS/VSSA) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure the good functionality of the device.

5.3.4 Embedded voltage reference

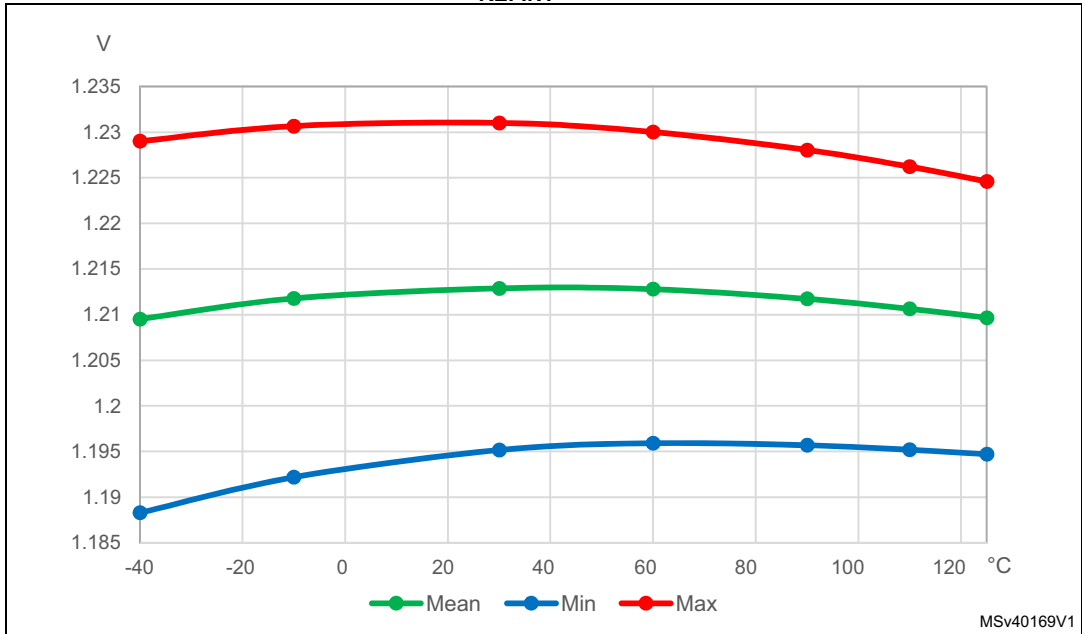
The parameters given in Table 27 are derived from tests performed under the ambient temperature and supply voltage conditions summarized in Table 24: General operating conditions.

Table 27. Embedded internal voltage reference

Table with 7 columns: Symbol, Parameter, Conditions, Min, Typ, Max, Unit. It lists various electrical characteristics of the internal voltage reference such as V_REFINT, sampling time (tS_vrefint), start time (tstart_vrefint), consumption (IDD(VREFINTBUF)), voltage spread (ΔV_REFINT), temperature coefficient (TCoeff_vrefint), long term stability (ACoeff), voltage coefficient (VDDCcoeff), and reference voltage dividers (V_REFINT_DIV1, 2, 3).

- 1. The shortest sampling time can be determined in the application by multiple iterations.
2. Guaranteed by design.

Figure 17. V_REFINT vs. temperature



5.3.5 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in [Figure 16: Current consumption measurement scheme](#).

Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in analog input mode
- All peripherals are disabled except when explicitly mentioned
- The Flash memory access time is adjusted with the minimum wait states number, depending on the f_{HCLK} frequency (refer to the table “Number of wait states according to CPU clock (HCLK) frequency” available in the RM0444 reference manual).
- When the peripherals are enabled $f_{PCLK} = f_{HCLK}$
- For Flash memory and shared peripherals $f_{PCLK} = f_{HCLK} = f_{HCLKS}$

Unless otherwise stated, values given in [Table 28](#) through [Table 36](#) are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 24: General operating conditions](#).

5.3.13 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below V_{SS} or above V_{DDIOx} (for standard, 3.3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out-of-range parameter: ADC error above a certain limit (higher than 5 LSB TUE), induced leakage current on adjacent pins out of conventional limits ($-5 \mu A/+0 \mu A$ range) or other functional failure (for example reset occurrence or oscillator frequency deviation).

Negative induced leakage current is caused by negative injection and positive induced leakage current is caused by positive injection.

Table 54. I/O current injection susceptibility⁽¹⁾

Symbol	Description		Functional susceptibility		Unit
			Negative injection	Positive injection	
I_{INJ}	Injected current on pin	All except PA4, PA5, PA6, PB0, PB3, and PC0	-5	N/A	mA
		PA4, PA5	-5	0	mA
		PA6, PB0, PB3, and PC0	0	N/A	mA

1. Based on characterization results, not tested in production.

Table 75. SPI characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f _{SCK} 1/t _{c(SCK)}	SPI clock frequency	Master mode 1.65 < V _{DD} < 3.6 V Range 1	-	-	32	MHz
		Master transmitter 1.65 < V _{DD} < 3.6 V Range 1			32	
		Slave receiver 1.65 < V _{DD} < 3.6 V Range 1			32	
		Slave transmitter/full duplex 2.7 < V _{DD} < 3.6 V Range 1			32	
		Slave transmitter/full duplex 1.65 < V _{DD} < 3.6 V Range 1			23	
		1.65 < V _{DD} < 3.6 V Range 2			8	
t _{su(NSS)}	NSS setup time	Slave mode, SPI prescaler = 2	4 × T _{PCLK}	-	-	ns
t _{h(NSS)}	NSS hold time	Slave mode, SPI prescaler = 2	2 × T _{PCLK}	-	-	ns
t _{w(SCKH)}	SCK high time	Master mode	T _{PCLK} - 1.5	T _{PCLK}	T _{PCLK} + 1.5	ns
t _{w(SCKL)}	SCK low time	Master mode	T _{PCLK} - 1.5	T _{PCLK}	T _{PCLK} + 1.5	ns
t _{su(MI)}	Master data input setup time	-	1	-	-	ns
t _{su(SI)}	Slave data input setup time	-	1	-	-	ns
t _{h(MI)}	Master data input hold time	-	5	-	-	ns
t _{h(SI)}	Slave data input hold time	-	1	-	-	ns
t _{a(SO)}	Data output access time	Slave mode	9	-	34	ns
t _{dis(SO)}	Data output disable time	Slave mode	9	-	16	ns
t _{v(SO)}	Slave data output valid time	2.7 < V _{DD} < 3.6 V Range 1	-	9	14	ns
		1.65 < V _{DD} < 3.6 V Range 1	-	9	21	
		1.65 < V _{DD} < 3.6 V Voltage Range 2	-	11	24	
t _{v(MO)}	Master data output valid time	-	-	3	5	ns

Table 75. SPI characteristics⁽¹⁾ (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{h(SO)}$	Slave data output hold time	-	5	-	-	ns
$t_{h(MO)}$	Master data output hold time	-	1	-	-	ns

1. Based on characterization results, not tested in production.

Figure 31. SPI timing diagram - slave mode and CPHA = 0

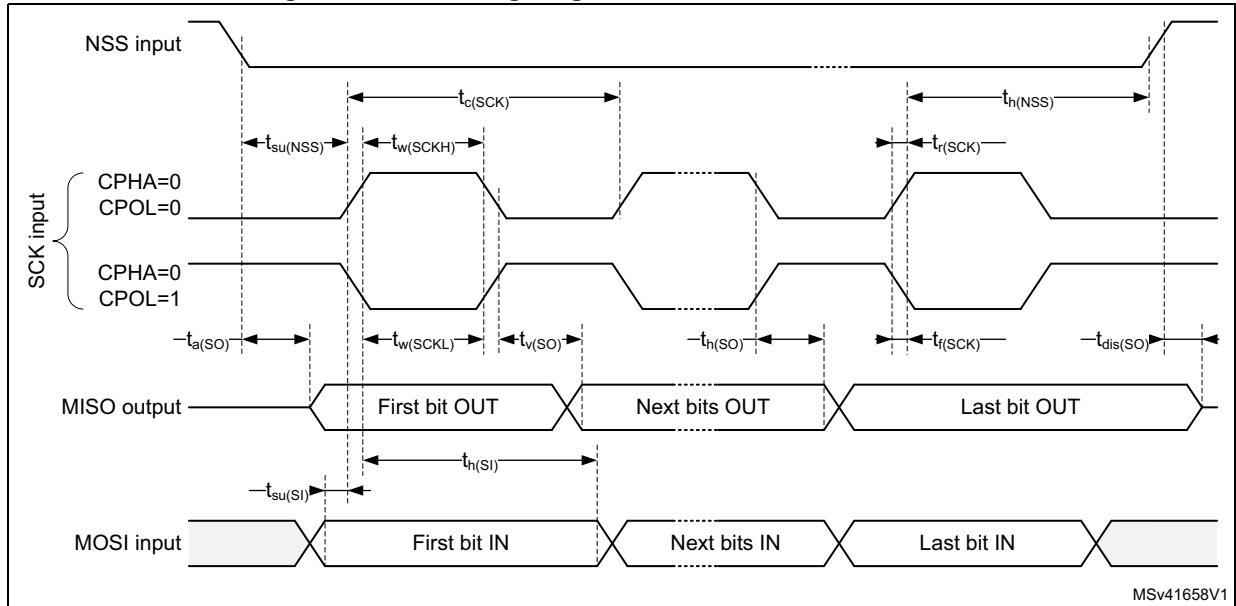
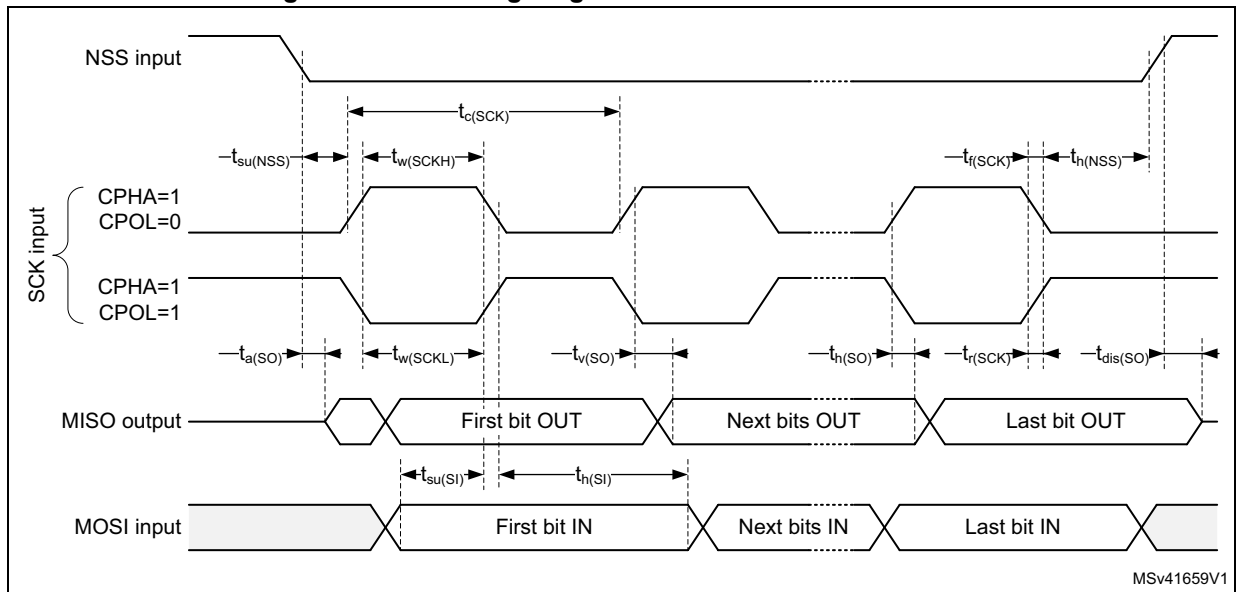
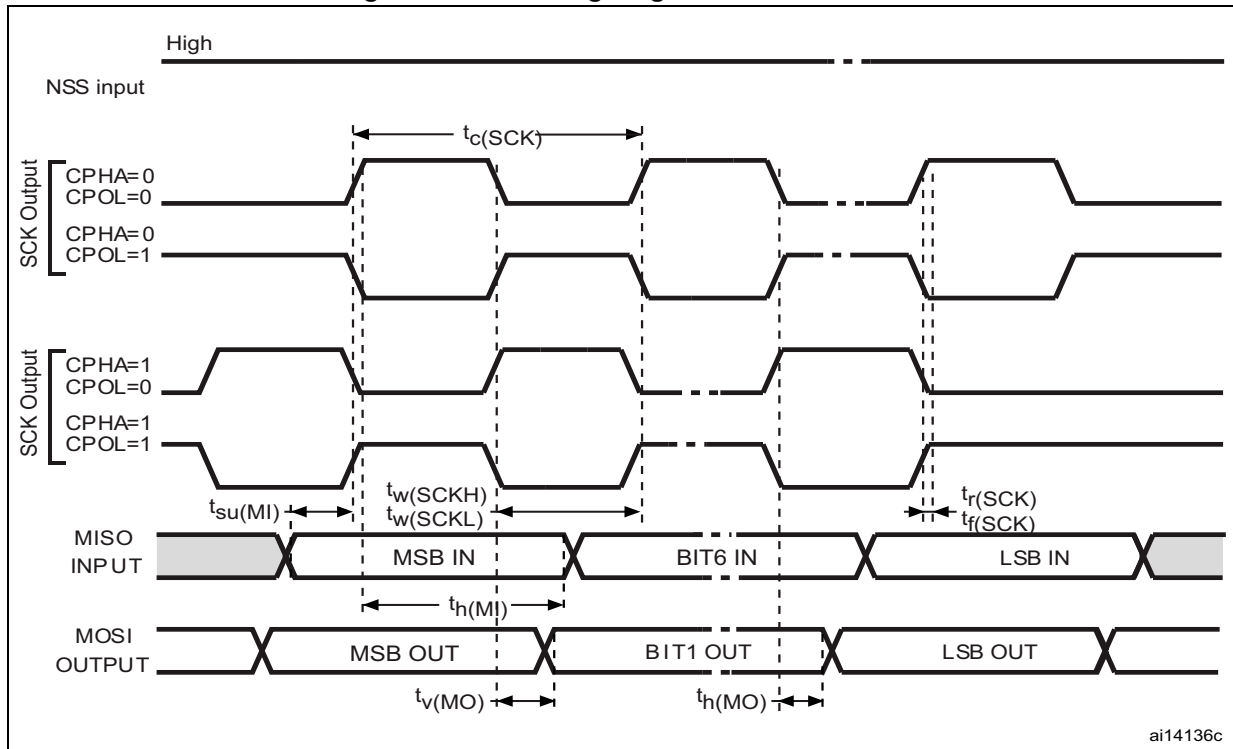


Figure 32. SPI timing diagram - slave mode and CPHA = 1



1. Measurement points are done at CMOS levels: 0.3 V_{DD} and 0.7 V_{DD}.

Figure 33. SPI timing diagram - master mode



1. Measurement points are set at CMOS levels: 0.3 V_{DD} and 0.7 V_{DD} .

Table 76. I²S characteristics⁽¹⁾

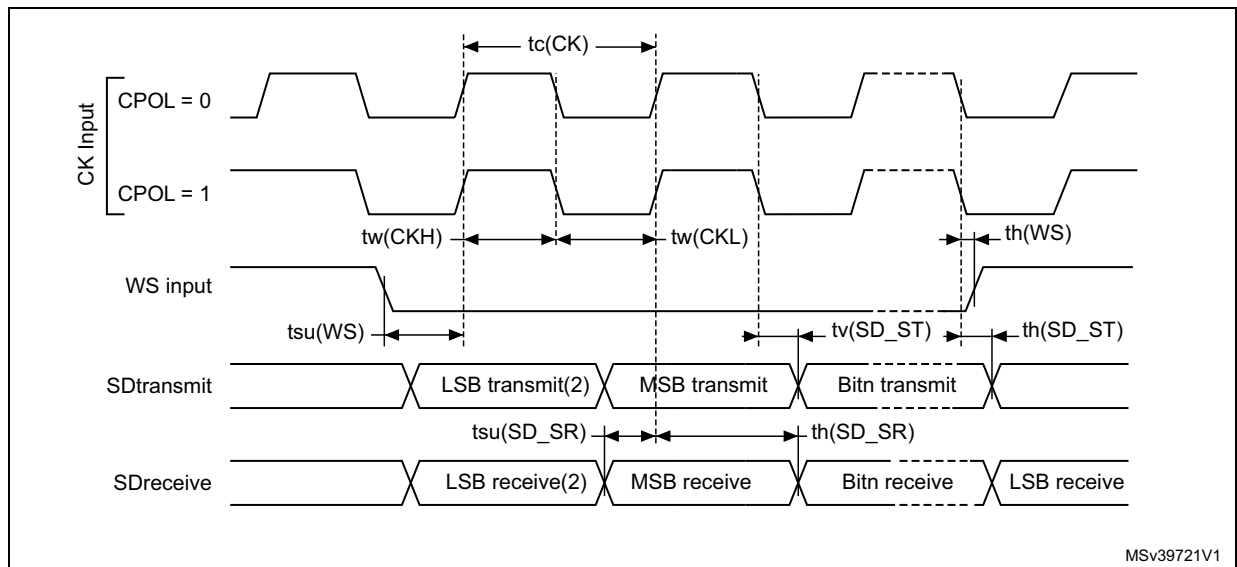
Symbol	Parameter	Conditions	Min	Max	Unit
f_{MCK}	I2S main clock output	$f_{MCK} = 256 \times F_s$; (F_s = audio sampling frequency) $F_{s_{min}} = 8$ kHz; $F_{s_{max}} = 192$ kHz;	2.048	49.152	MHz
f_{CK}	I2S clock frequency	Master data	-	$64 \times F_s$	MHz
		Slave data	-	$64 \times F_s$	
D_{CK}	I2S clock frequency duty cycle	Slave receiver	30	70	%

Table 76. I²S characteristics⁽¹⁾ (continued)

Symbol	Parameter	Conditions	Min	Max	Unit
$t_{v(WS)}$	WS valid time	Master mode	-	8	ns
$t_{h(WS)}$	WS hold time	Master mode	2	-	
$t_{su(WS)}$	WS setup time	Slave mode	4	-	
$t_{h(WS)}$	WS hold time	Slave mode	2	-	
$t_{su(SD_MR)}$	Data input setup time	Master receiver	4	-	
$t_{su(SD_SR)}$		Slave receiver	5	-	
$t_{h(SD_MR)}$	Data input hold time	Master receiver	4.5	-	
$t_{h(SD_SR)}$		Slave receiver	2	-	
$t_{v(SD_ST)}$	Data output valid time - slave transmitter	after enable edge; $2.7 < V_{DD} < 3.6V$	-	16	
		after enable edge; $1.65 < V_{DD} < 3.6V$	-	23	
$t_{v(SD_MT)}$	Data output valid time - master transmitter	after enable edge	-	5.5	
$t_{h(SD_ST)}$	Data output hold time - slave transmitter	after enable edge	8	-	
$t_{h(SD_MT)}$	Data output hold time - master transmitter	after enable edge	1	-	

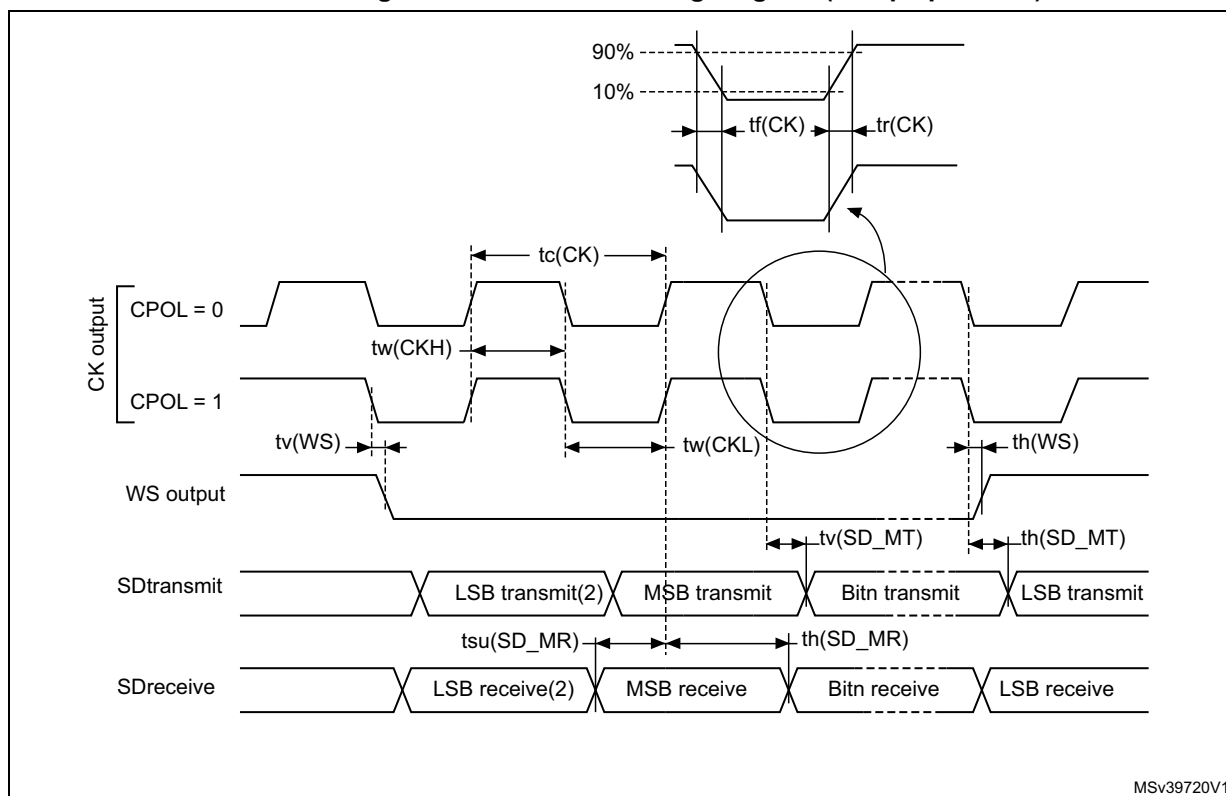
1. Based on characterization results, not tested in production.

Figure 34. I²S slave timing diagram (Philips protocol)



1. Measurement points are done at CMOS levels: $0.3 V_{DDIO1}$ and $0.7 V_{DDIO1}$.
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 35. I²S master timing diagram (Philips protocol)



MSv39720V1

1. Based on characterization results, not tested in production.
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

USART characteristics

Unless otherwise specified, the parameters given in [Table 77](#) for USART are derived from tests performed under the ambient temperature, f_{PCLKx} frequency and supply voltage conditions summarized in [Table 24: General operating conditions](#). The additional general conditions are:

- OSPEEDRy[1:0] set to 10 (output speed)
- capacitive load C = 30 pF
- measurement points at CMOS levels: $0.5 \times V_{DD}$

Refer to [Section 5.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, CK, TX, and RX for USART).

Table 77. USART characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f _{CK}	USART clock frequency	Master mode	-	-	8	MHz
		Slave mode	-	-	21	

Table 77. USART characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{su(NSS)}$	NSS setup time	Slave mode	$t_{ker} + 2$	-	-	ns
$t_{h(NSS)}$	NSS hold time	Slave mode	2	-	-	
$t_{w(CKH)}$	CK high time	Master mode	$1 / f_{CK} / 2 - 1$	$1 / f_{CK} / 2$	$1 / f_{CK} / 2 + 1$	
$t_{w(CKL)}$	CK low time					
$t_{su(RX)}$	Data input setup time	Master mode	$t_{ker} + 2$	-	-	
		Slave mode	4	-	-	
$t_{h(RX)}$	Data input hold time	Master mode	1	-	-	
		Slave mode	0.5	-	-	
$t_{v(TX)}$	Data output valid time	Master mode	-	0.5	1	
		Slave mode	-	10	19	
$t_{h(TX)}$	Data output hold time	Master mode	0	-	-	
		Slave mode	7	-	-	

USB full speed (FS) characteristics

The STM32G0B1xB/xC/xE USB interface is fully compliant with the USB specification version 2.0 and is USB-IF certified (for Full-speed device operation).

Table 78. USB DC electrical characteristics

Symbol	Parameter	Conditions	Min ⁽¹⁾	Typ	Max ⁽¹⁾	Unit
V_{DDUSB}	USB full speed transceiver operating voltage	-	3.0 ⁽²⁾	-	3.6	V
$V_{DI}^{(3)}$	Differential input sensitivity	Over VCM range	0.2	-	-	V
$V_{CM}^{(3)}$	Differential input common mode range	Includes V_{DI} range	0.8	-	2.5	
$V_{SE}^{(3)}$	Single ended receiver input threshold	-	0.8	-	2.0	
V_{OL}	Static output level low	R_L of 1.5 kΩ to 3.6 V ⁽⁴⁾	-	-	0.3	V
V_{OH}	Static output level high	R_L of 15 kΩ to $V_{SS}^{(4)}$	2.8	-	3.6	
$R_{PD}^{(3)}$	Pull down resistor on PA11, PA12 (USB_FS_DP/DM)	$V_{IN} = V_{DD}$	14.25	-	24.8	kΩ
$R_{PU}^{(3)}$	Pull Up Resistor on PA12 (USB_FS_DP)	$V_{IN} = V_{SS}$, during idle	0.9	1.25	1.575	kΩ
	Pull Up Resistor on PA12 (USB_FS_DP)	$V_{IN} = V_{SS}$ during reception	1.425	2.25	3.09	kΩ

1. All the voltages are measured from the local ground potential.
2. The USB full speed transceiver functionality is ensured down to 2.7 V but not the full USB full speed electrical characteristics which are degraded in the 2.7-to-3.0 V V_{DD} voltage range.
3. Guaranteed by design.
4. R_L is the load connected on the USB full speed drivers.

Note: When VBUS sensing feature is enabled, PA9 should be left at its default state (floating input), not as alternate function. A typical 200 μA current consumption of the sensing block (current to voltage conversion to determine the different sessions) can be observed on PA9 when the feature is enabled.

Figure 36. USB timings – definition of data signal rise and fall time

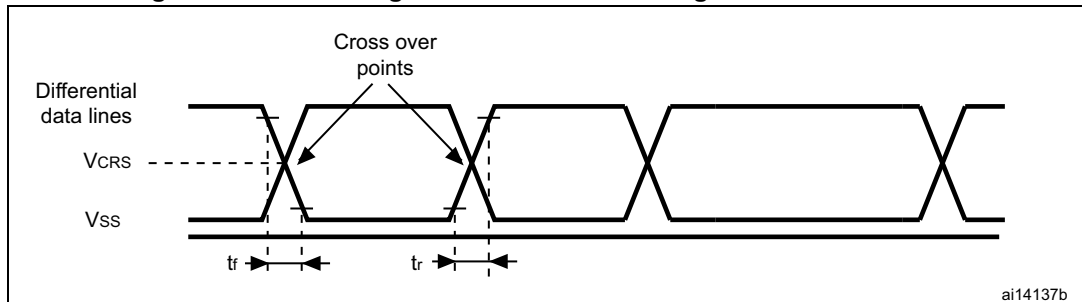


Table 79. USB electrical characteristics⁽¹⁾

Driver characteristics					
Symbol	Parameter	Conditions	Min	Max	Unit
t _{rLS}	Rise time in LS ⁽²⁾	C _L = 200 to 600 pF	75	300	ns
t _{fLS}	Fall time in LS ⁽²⁾	C _L = 200 to 600 pF	75	300	ns
t _{rfmLS}	Rise/ fall time matching in LS	t _r /t _f	80	125	%
t _{rFS}	Rise time in FS ⁽²⁾	C _L = 50 pF	4	20	ns
t _{fFS}	Fall time in FS ⁽²⁾	C _L = 50 pF	4	20	ns
t _{rfmFS}	Rise/ fall time matching in FS	t _r /t _f	90	111	%
V _{CRS}	Output signal crossover voltage (LS/FS)	-	1.3	2.0	V
Z _{DRV}	Output driver impedance ⁽³⁾	Driving high or low	28	44	Ω

1. Guaranteed by design.
2. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).
3. No external termination series resistors are required on DP (D+) and DM (D-) pins since the matching impedance is included in the embedded driver.

Table 80. USB BCD DC electrical characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I _{DD(USBBCD)}	Primary detection mode consumption	-	-	-	300	μA
	Secondary detection mode consumption	-	-	-	300	μA

Table 80. USB BCD DC electrical characteristics⁽¹⁾ (continued)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
RDAT_LKG	Data line leakage resistance	-	300	-	-	kΩ
VDAT_LKG	Data line leakage voltage	-	0.0	-	3.6	V
RDCP_DAT	Dedicated charging port resistance across D+/D-	-	-	-	200	Ω
VLGC_HI	Logic high	-	2.0	-	3.6	V
VLGC_LOW	Logic low	-	-	-	0.8	V
VLGC	Logic threshold	-	0.8	-	2.0	V
VDAT_REF	Data detect voltage	-	0.25	-	0.4	V
VDP_SRC	D+ source voltage	-	0.5	-	0.7	V
VDM_SRC	D- source voltage	-	0.5	-	0.7	V
IDP_SINK	D+ sink current	-	25	-	175	μA
IDM_SINK	D- sink current	-	25	-	175	μA

1. Guaranteed by design.

CAN (controller area network) interface

Refer to [Section 5.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (FDCANx_TX and FDCANx_RX).

5.3.25 UCPD characteristics

UCPD1 and UCPD2 controllers comply with USB Type-C Rev.1.2 and USB Power Delivery Rev. 3.0 specifications.

Table 81. UCPD operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{DD}	UCPD operating supply voltage	Sink mode only	3.0	3.3	3.6	V
		Sink and source mode	3.135	3.3	3.465	V

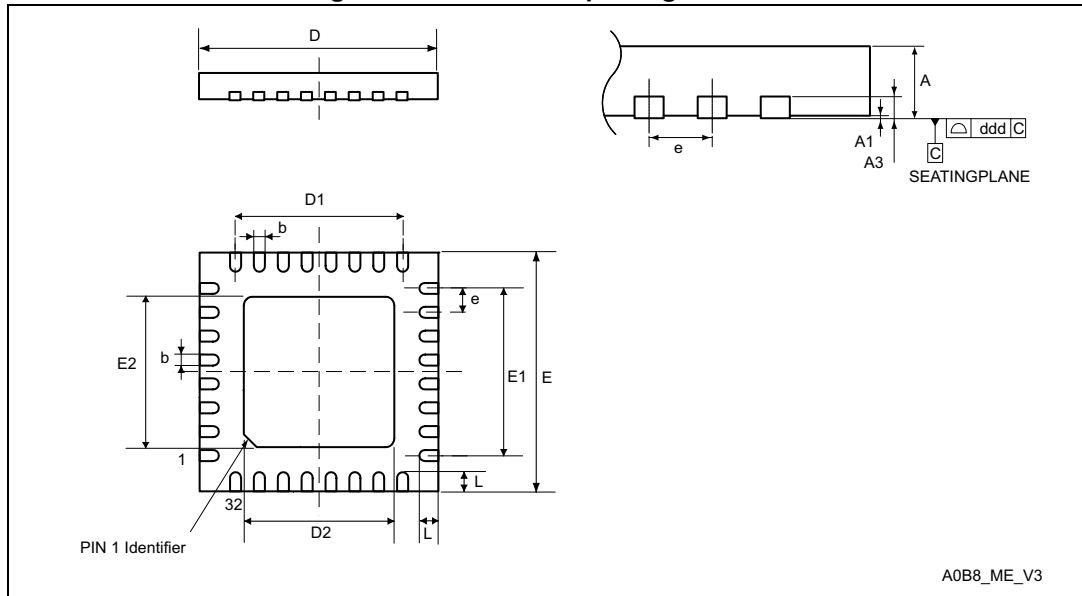
6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

6.1 UFQFPN32 package information

UFQFPN32 is a 32-pin, 5x5 mm, 0.5 mm pitch ultra-thin fine-pitch quad flat package.

Figure 37. UFQFPN32 package outline



1. Drawing is not to scale.
2. There is an exposed die pad on the underside of the UFQFPN package. It is recommended to connect and solder this backside pad to PCB ground.

Table 82. UFQFPN32 package mechanical data

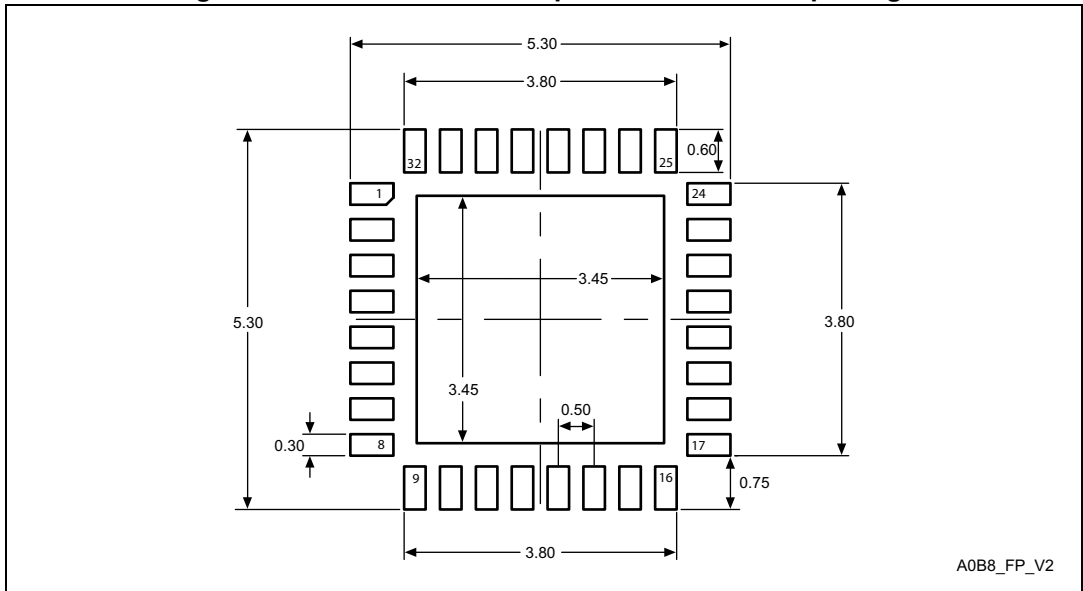
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.500	0.550	0.600	0.0197	0.0217	0.0236
A1	0.000	0.020	0.050	0.000	0.0007	0.0020
A3	-	0.152	-	-	0.0060	-
b	0.180	0.230	0.280	0.0071	0.0091	0.0110
D ⁽²⁾	4.900	5.000	5.100	0.1929	0.1969	0.2008
D1	3.400	3.500	3.600	0.1339	0.1378	0.1417
D2	3.400	3.500	3.600	0.1339	0.1378	0.1417
E ⁽²⁾	4.900	5.000	5.100	0.1929	0.1969	0.2008

Table 82. UFQFPN32 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
E1	3.400	3.500	3.600	0.1339	0.1378	0.1417
E2	3.400	3.500	3.600	0.1339	0.1378	0.1417
e	-	0.500	-	-	0.0197	-
L	0.300	0.400	0.500	0.0118	0.0157	0.0197
ddd	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Dimensions D and E do not include mold protrusion, not to exceed 0,15mm.

Figure 38. Recommended footprint for UFQFPN32 package



1. Dimensions are expressed in millimeters

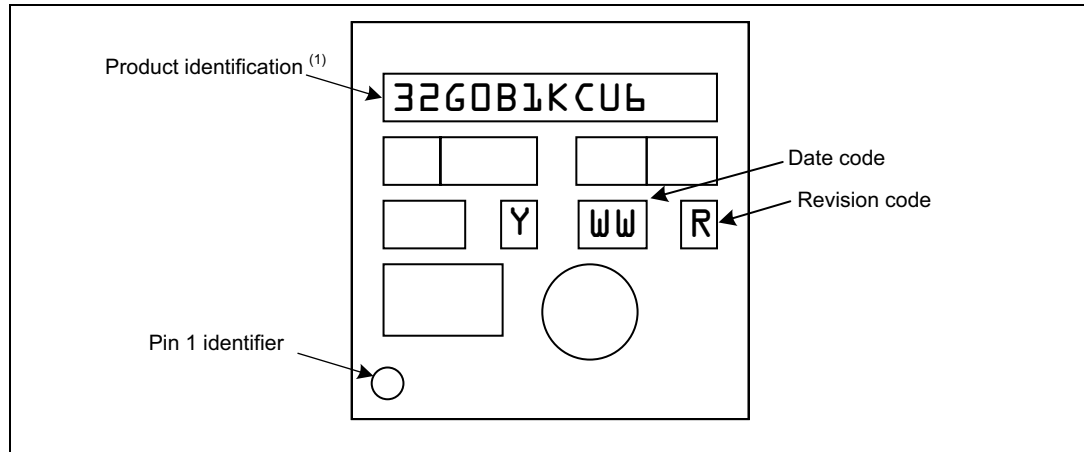
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 39. UFQFPN32 package marking example

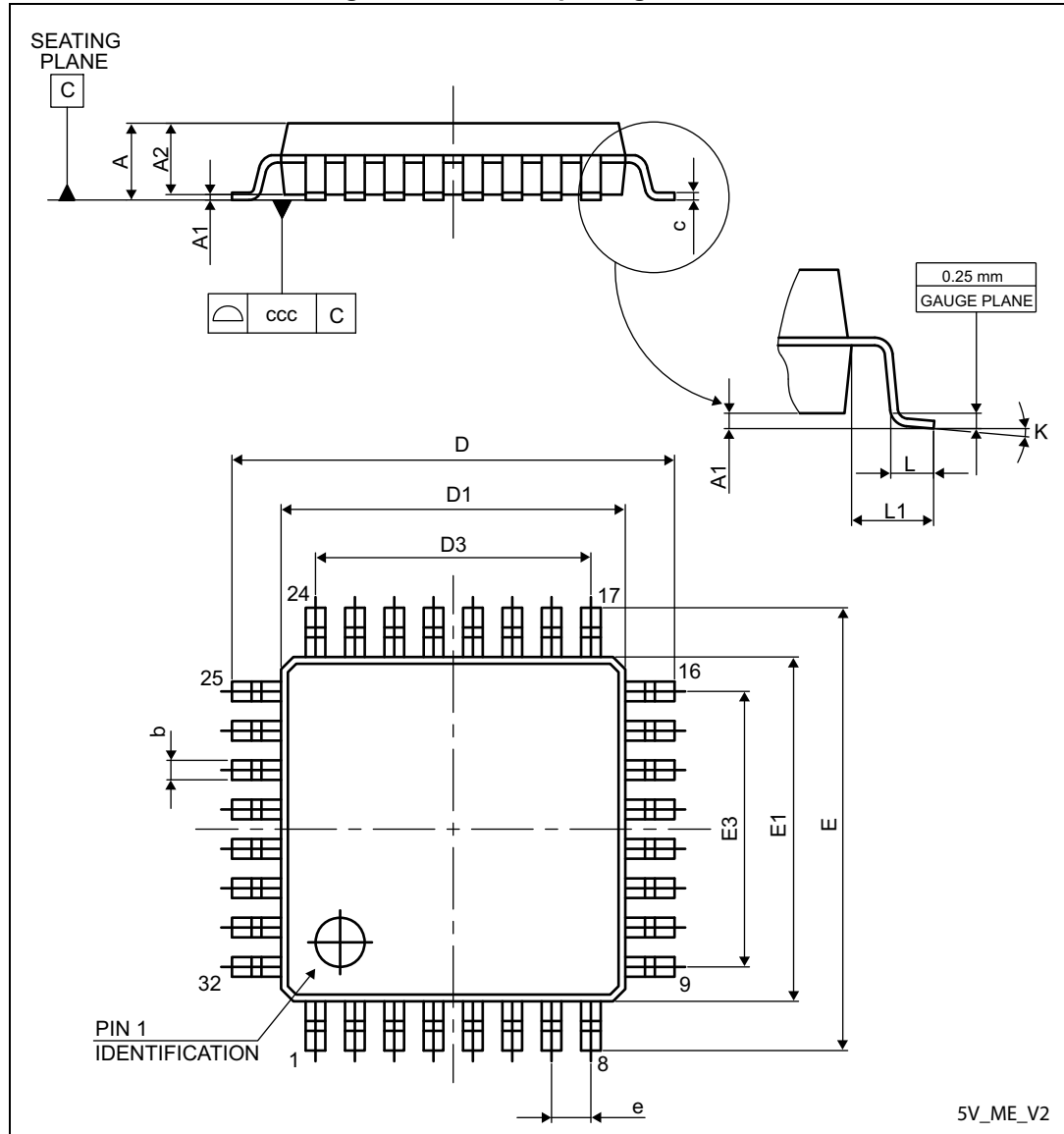


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.2 LQFP32 package information

LQFP32 is a 32-pin, 7 x 7 mm low-profile quad flat package.

Figure 40. LQFP32 package outline



1. Drawing is not to scale.

Table 83. LQFP32 mechanical data

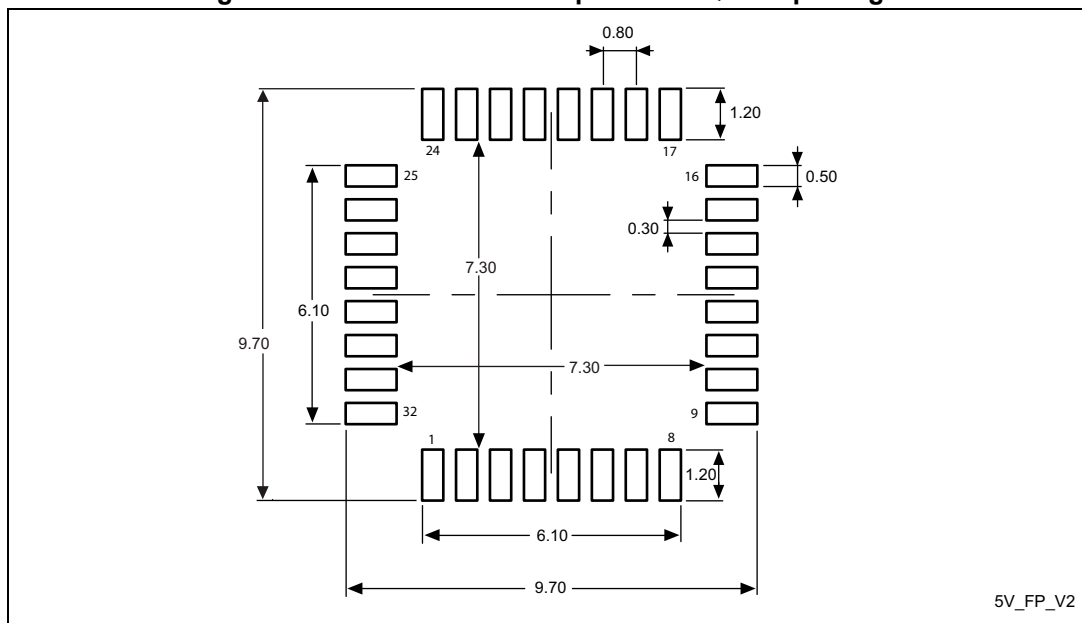
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571

Table 83. LQFP32 mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
b	0.300	0.370	0.450	0.0118	0.0146	0.0177
c	0.090	-	0.200	0.0035	-	0.0079
D	8.800	9.000	9.200	0.3465	0.3543	0.3622
D1	6.800	7.000	7.200	0.2677	0.2756	0.2835
D3	-	5.600	-	-	0.2205	-
E	8.800	9.000	9.200	0.3465	0.3543	0.3622
E1	6.800	7.000	7.200	0.2677	0.2756	0.2835
E3	-	5.600	-	-	0.2205	-
e	-	0.800	-	-	0.0315	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.100	-	-	0.0039

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 41. Recommended footprint for LQFP32 package



1. Dimensions are expressed in millimeters.

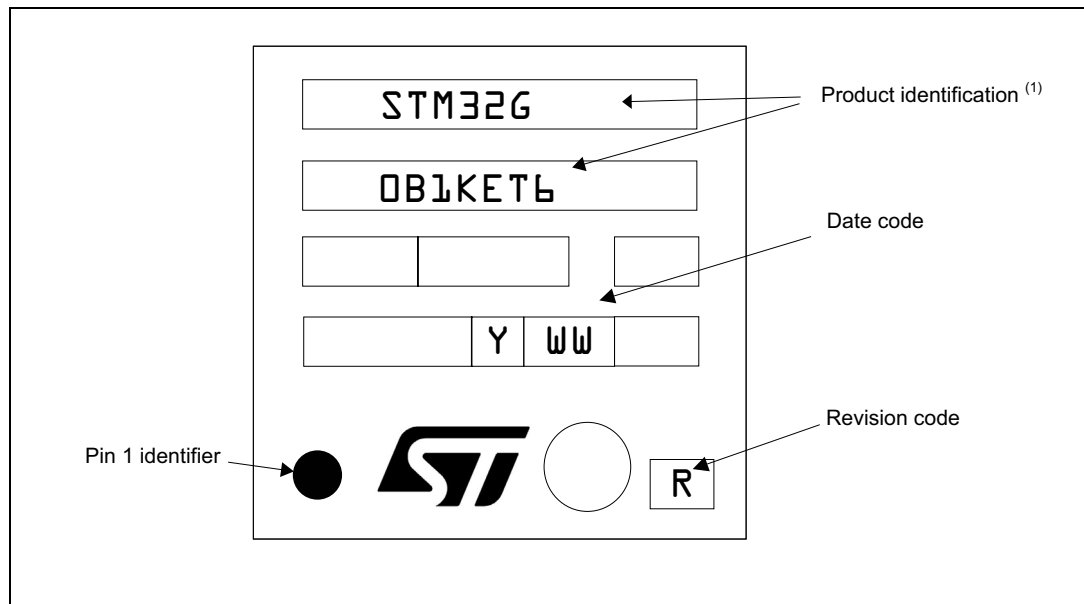
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 42. LQFP32 package marking example

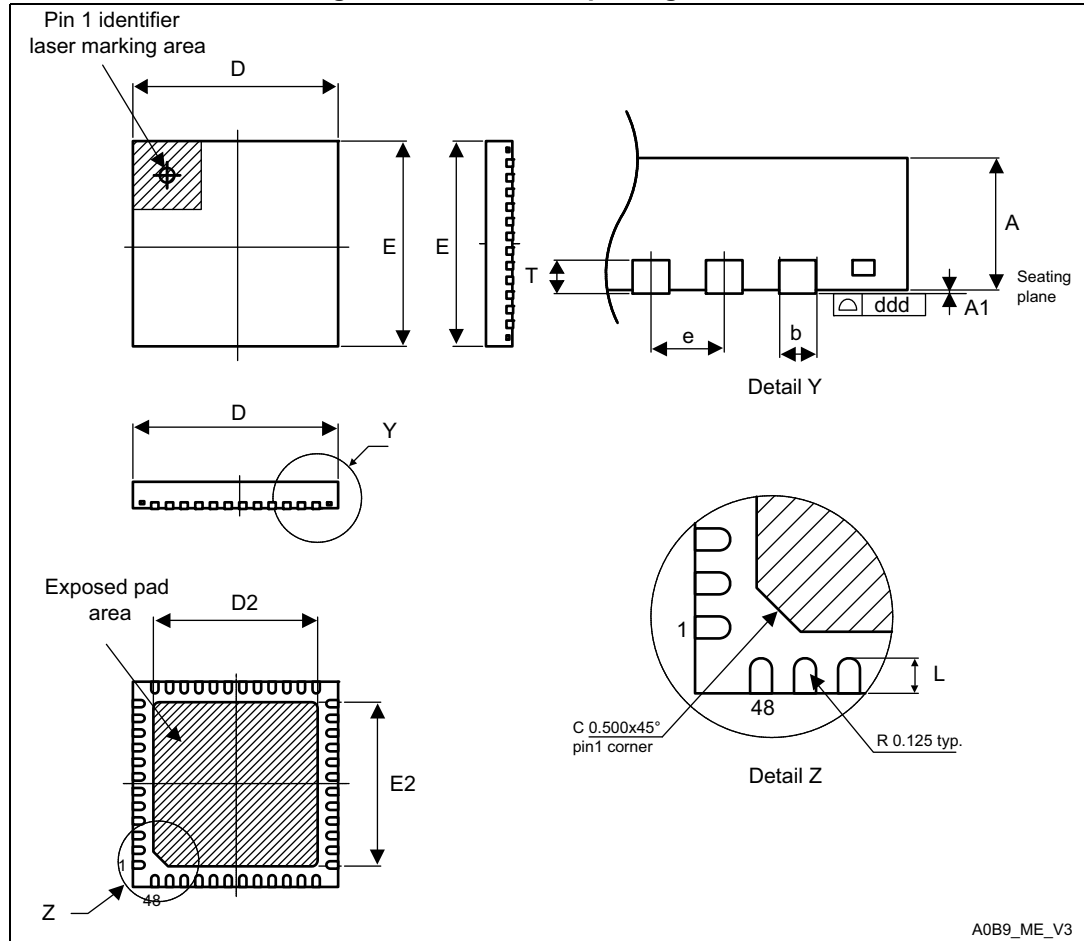


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.3 UFQFPN48 package information

UFQFPN48 is a 48-lead, 7x7 mm, 0.5 mm pitch, ultra-thin fine-pitch quad flat package

Figure 43. UFQFPN48 package outline



A0B9_ME_V3

1. Drawing is not to scale.
2. All leads/pads should also be soldered to the PCB to improve the lead/pad solder joint life.
3. There is an exposed die pad on the underside of the UFQFPN package. It is recommended to connect and solder this back-side pad to PCB ground.

Table 84. UFQFPN48 package mechanical data

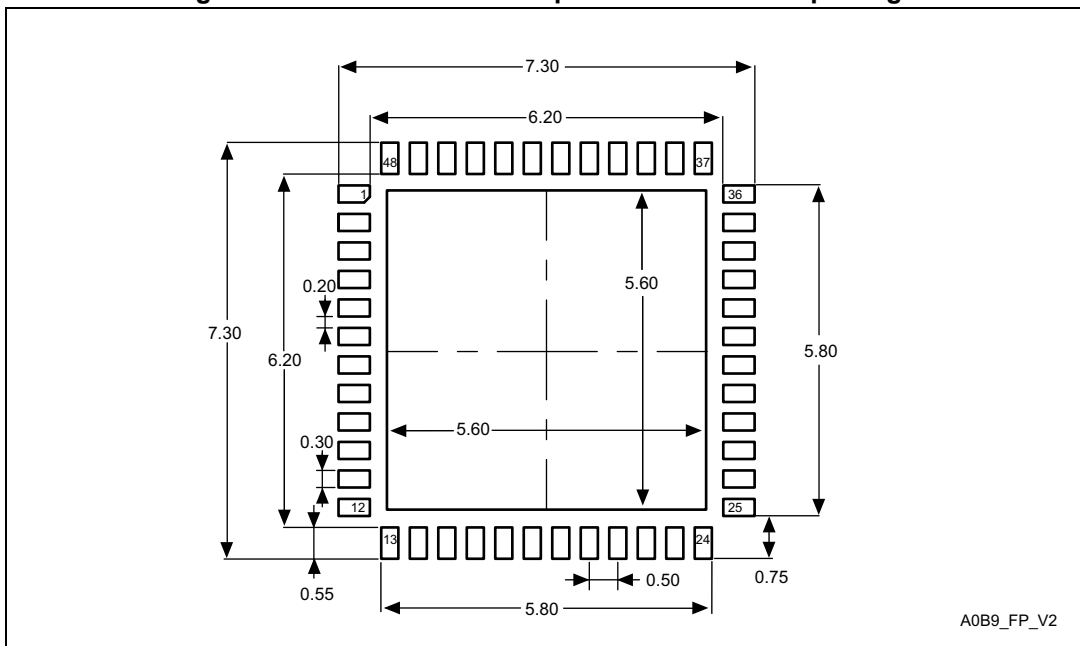
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.500	0.550	0.600	0.0197	0.0217	0.0236
A1	0.000	0.020	0.050	0.0000	0.0008	0.0020
D	6.900	7.000	7.100	0.2717	0.2756	0.2795
E	6.900	7.000	7.100	0.2717	0.2756	0.2795
D2	5.500	5.600	5.700	0.2165	0.2205	0.2244
E2	5.500	5.600	5.700	0.2165	0.2205	0.2244

Table 84. UFQFPN48 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
L	0.300	0.400	0.500	0.0118	0.0157	0.0197
T	-	0.152	-	-	0.0060	-
b	0.200	0.250	0.300	0.0079	0.0098	0.0118
e	-	0.500	-	-	0.0197	-
ddd	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 44. Recommended footprint for UFQFPN48 package



1. Dimensions are expressed in millimeters.

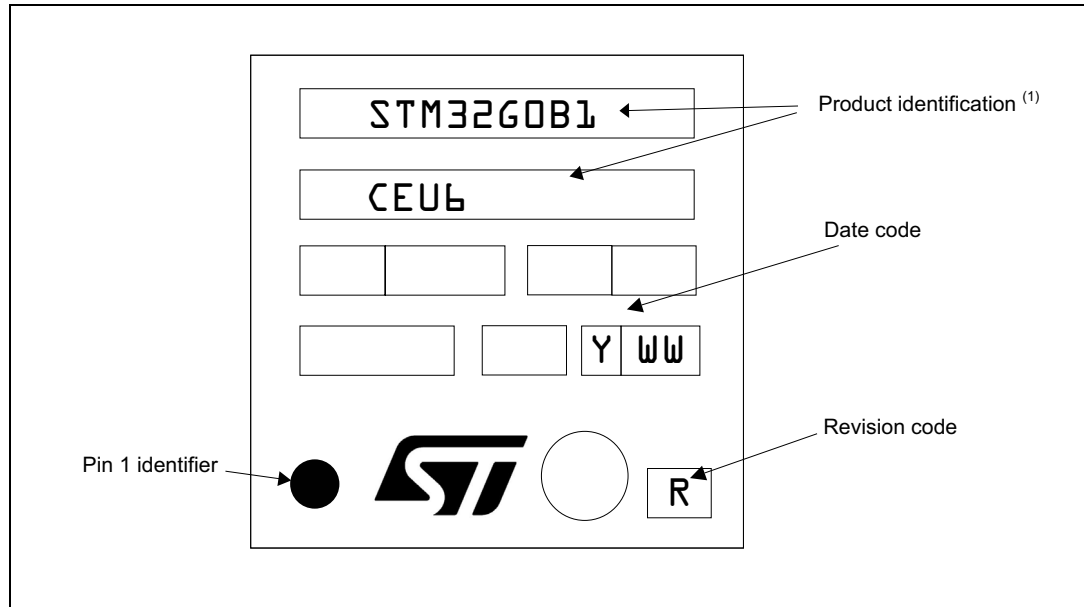
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 45. UFQFPN48 package marking example

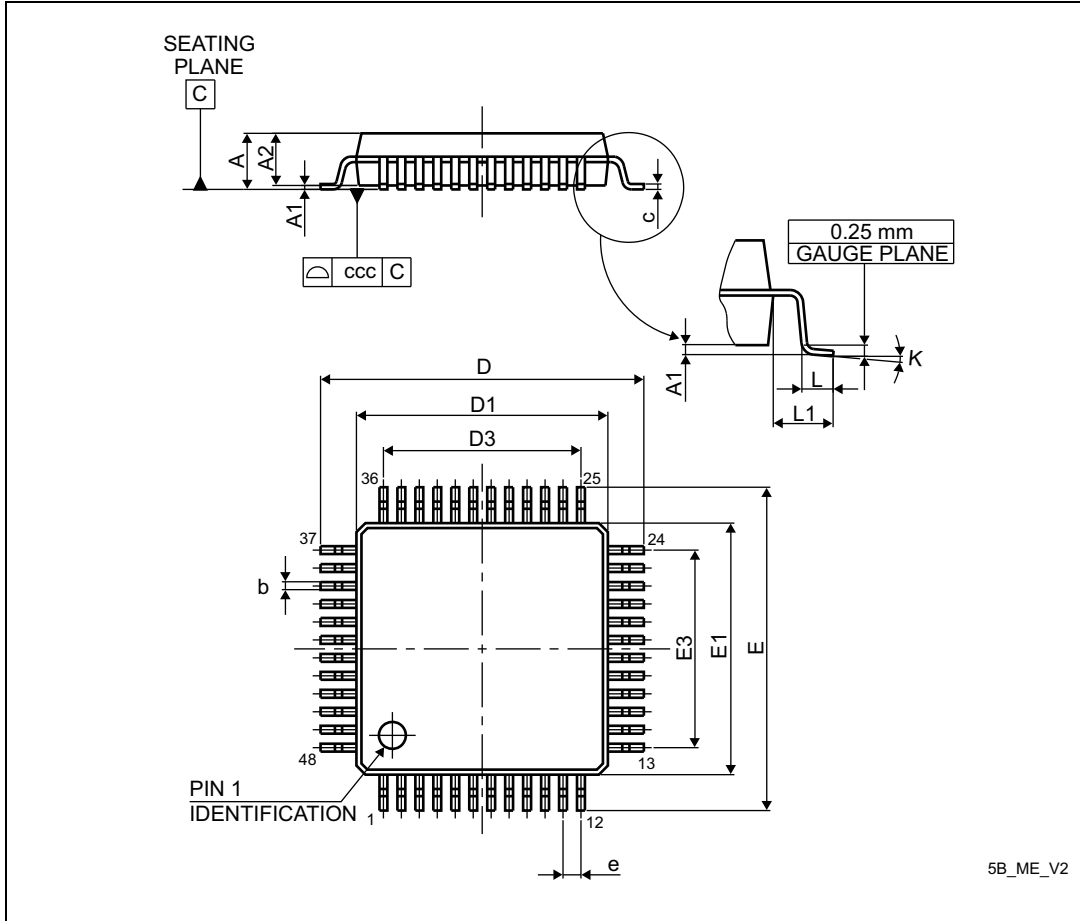


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.4 LQFP48 package information

LQFP48 is a 48-pin, 7 x 7 mm low-profile quad flat package.

Figure 46. LQFP48 package outline



1. Drawing is not to scale.

Table 85. LQFP48 mechanical data

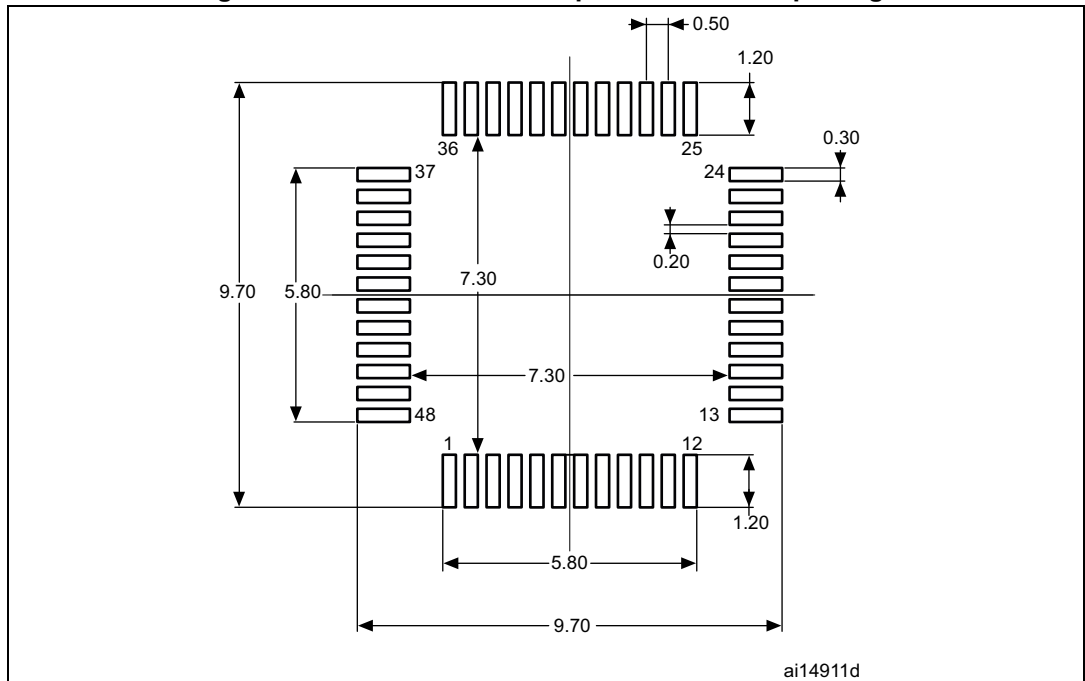
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	8.800	9.000	9.200	0.3465	0.3543	0.3622
D1	6.800	7.000	7.200	0.2677	0.2756	0.2835
D3	-	5.500	-	-	0.2165	-

Table 85. LQFP48 mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
E	8.800	9.000	9.200	0.3465	0.3543	0.3622
E1	6.800	7.000	7.200	0.2677	0.2756	0.2835
E3	-	5.500	-	-	0.2165	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 47. Recommended footprint for LQFP48 package



ai14911d

1. Dimensions are expressed in millimeters.

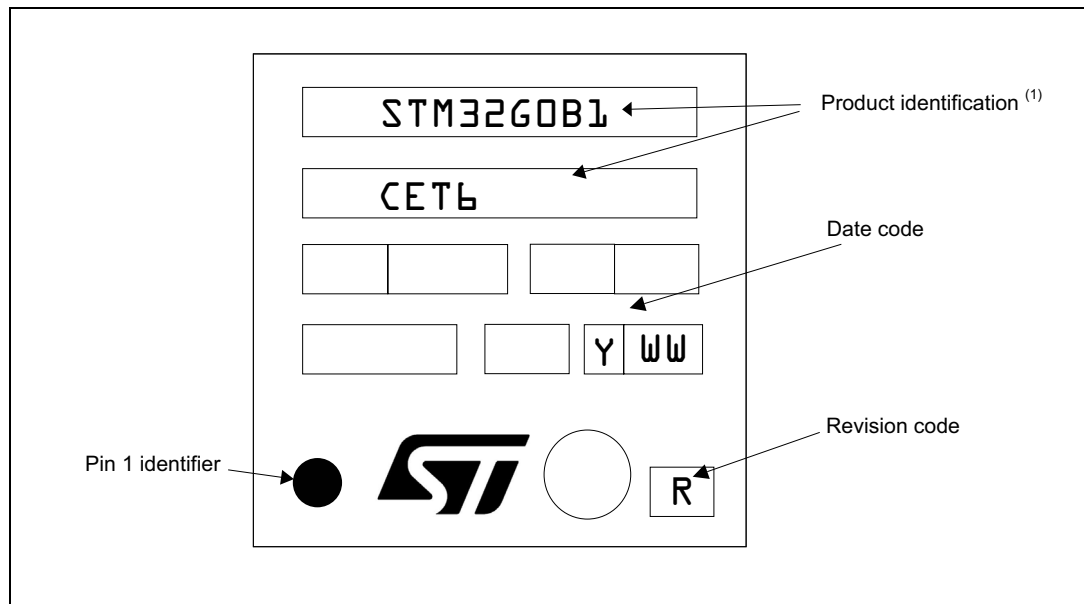
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 48. LQFP48 package marking example

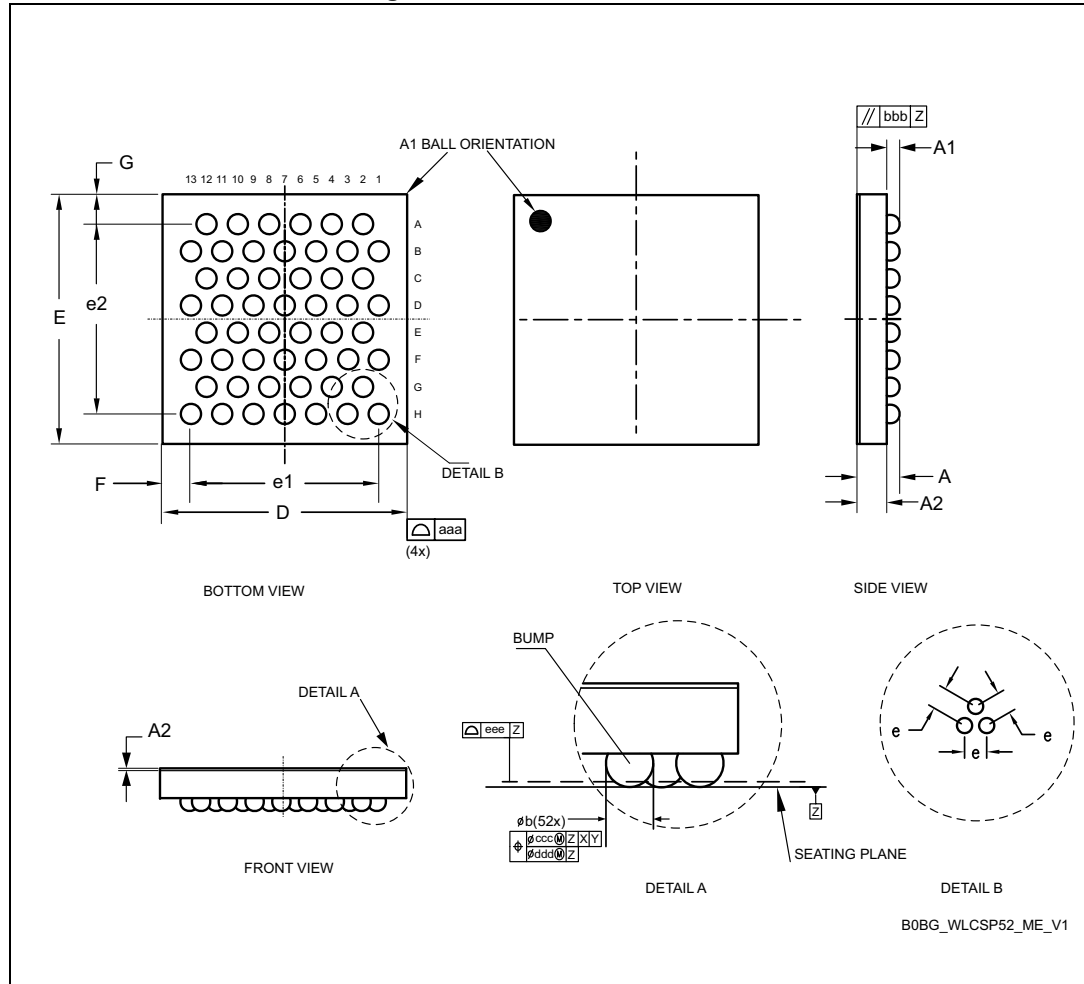


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.5 WLCSP52 package information

WLCSP52 is a 52-ball, 3.09 x 3.15 mm, 0.4 mm pitch, wafer-level chip-scale package.

Figure 49. WLCSP52 - Outline



1. Drawing is not to scale.
2. Dimension is measured at the maximum bump diameter parallel to primary datum Z.
3. Primary datum Z and seating plane are defined by the spherical crowns of the bump.
4. Bump position designation per JESD 95-1, SPP-010.

Table 86. WLCSP52 - Mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A ⁽²⁾	-	-	0.58	-	-	0.023
A1	-	0.17	-	-	0.007	-
A2	-	0.38	-	-	0.015	-
A3 ⁽³⁾	-	0.025	-	-	0.001	-

Table 86. WLCSP52 - Mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
b	0.23	0.26	0.28	0.009	0.010	0.011
D	3.06	3.09	3.12	0.120	0.122	0.123
E	3.12	3.15	3.18	0.123	0.124	0.125
e	-	0.40	-	-	0.016	-
e1	-	2.40	-	-	0.094	-
e2	-	2.42	-	-	0.095	-
F ⁽⁴⁾	-	0.35	-	-	0.014	-
G ⁽⁴⁾	-	0.36	-	-	0.014	-
N	-	-	0.10	-	-	0.004
aaa	-	-	0.10	-	-	0.004
bbb	-	-	0.10	-	-	0.004
ccc	-	-	0.05	-	-	0.002
ddd	-	-	0.05	-	-	0.002
eee	-	-	0.58	-	-	0.023

1. Values in inches are converted from mm and rounded to 3 decimal digits.
2. The maximum total package height is calculated by the RSS method (Root Sum Square) using nominal and tolerances values of A1 and A2.
3. Back side coating. Nominal dimension is rounded to the 3rd decimal place resulting from process capability.
4. Calculated dimensions are rounded to the 3rd decimal place

Figure 50. WLCSP52 - Recommended footprint

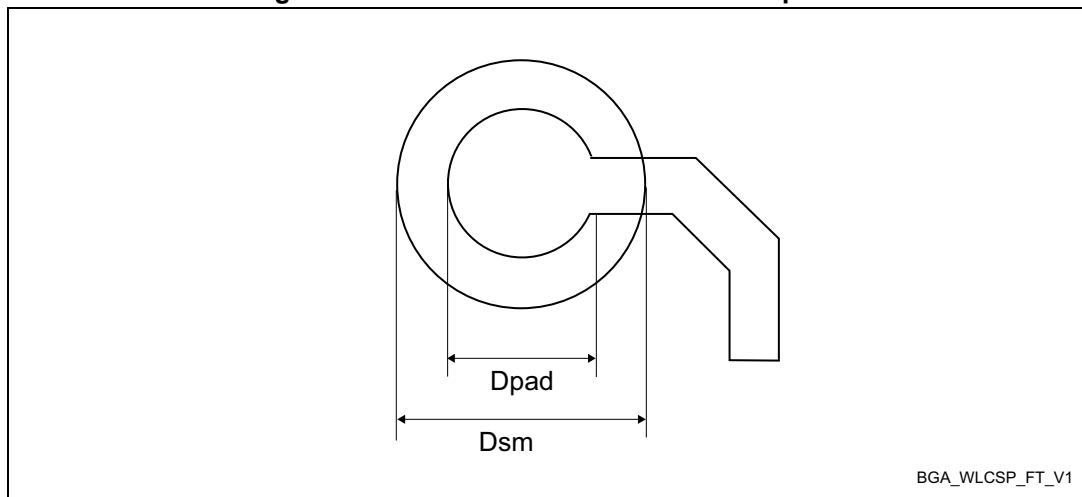


Table 87. WLCSP52 - Recommended PCB design rules

Dimension	Recommended values
Pitch	0.4 mm
Dpad	0,225 mm
Dsm	0.290 mm typ. (depends on soldermask registration tolerance)
Stencil opening	0.250 mm
Stencil thickness	0.100 mm

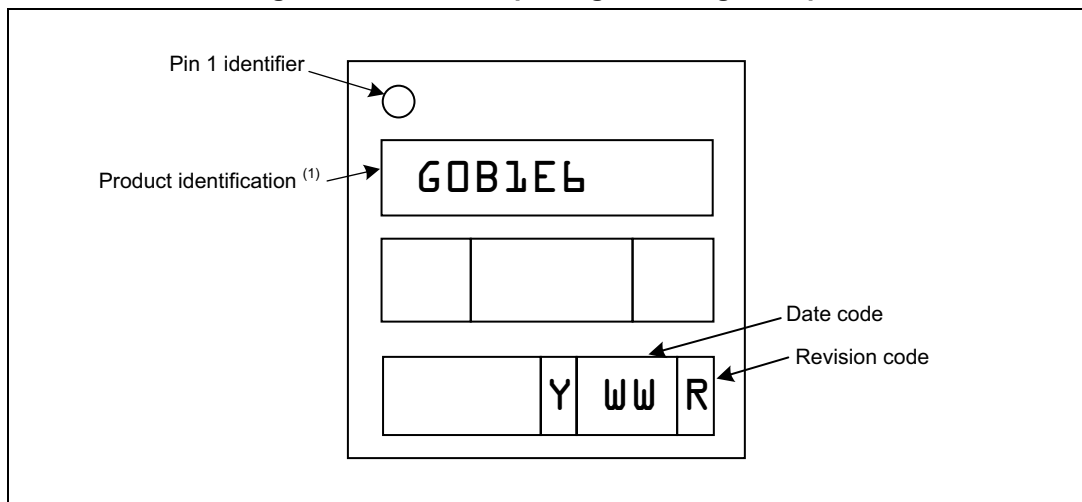
Device marking

The following figure gives an example of topside marking orientation versus ball A1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks that identify the parts throughout supply chain operations, are not indicated below.

Figure 51. WLCSP52 package marking example

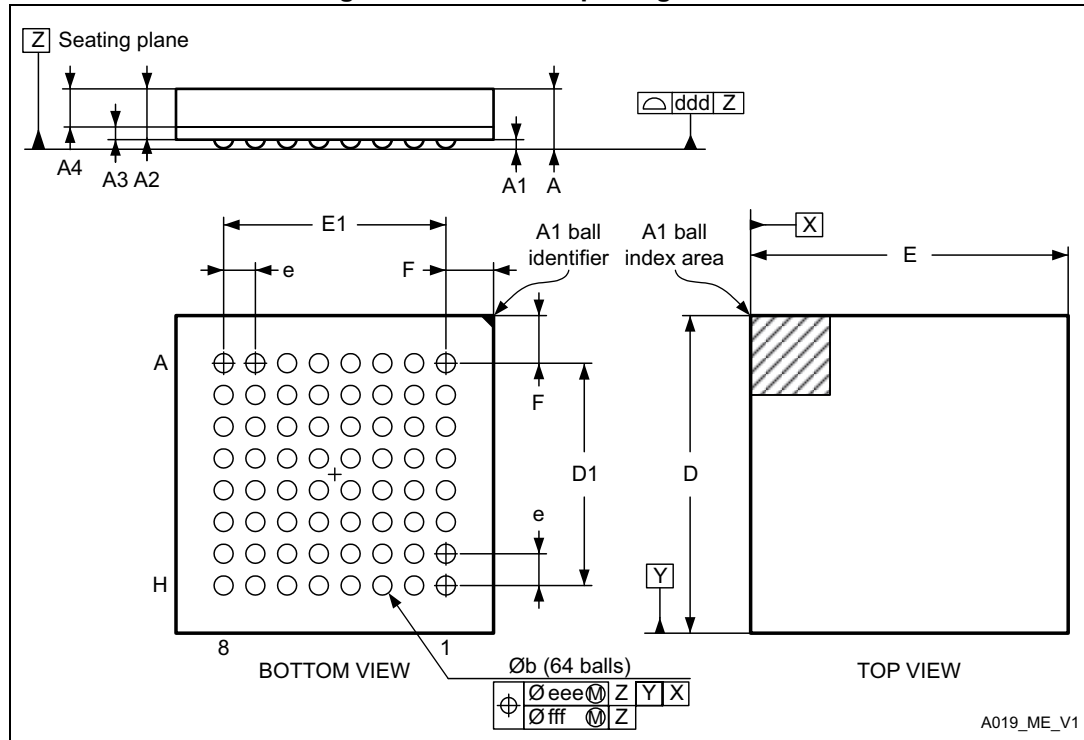


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.6 UFBGA64 package information

UFBGA64 is a 64-ball, 5 x 5 mm, 0.5 mm pitch ultra-low-profile fine-pitch ball grid array package.

Figure 52. UFBGA64 package outline



1. Drawing is not to scale.

Table 88. UFBGA64 package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.460	0.530	0.600	0.0181	0.0209	0.0236
A1	0.050	0.080	0.110	0.0020	0.0031	0.0043
A2	0.400	0.450	0.500	0.0157	0.0177	0.0197
A3	0.080	0.130	0.180	0.0031	0.0051	0.0071
A4	0.270	0.320	0.370	0.0106	0.0126	0.0146
b	0.170	0.280	0.330	0.0067	0.0110	0.0130
D	4.850	5.000	5.150	0.1909	0.1969	0.2028
D1	3.450	3.500	3.550	0.1358	0.1378	0.1398
E	4.850	5.000	5.150	0.1909	0.1969	0.2028
E1	3.450	3.500	3.550	0.1358	0.1378	0.1398
e	-	0.500	-	-	0.0197	-
F	0.700	0.750	0.800	0.0276	0.0295	0.0315

Table 88. UFBGA64 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.460	0.530	0.600	0.0181	0.0209	0.0236
ddd	-	-	0.080	-	-	0.0031
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.050	-	-	0.0020

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 53. Recommended footprint for UFBGA64 package

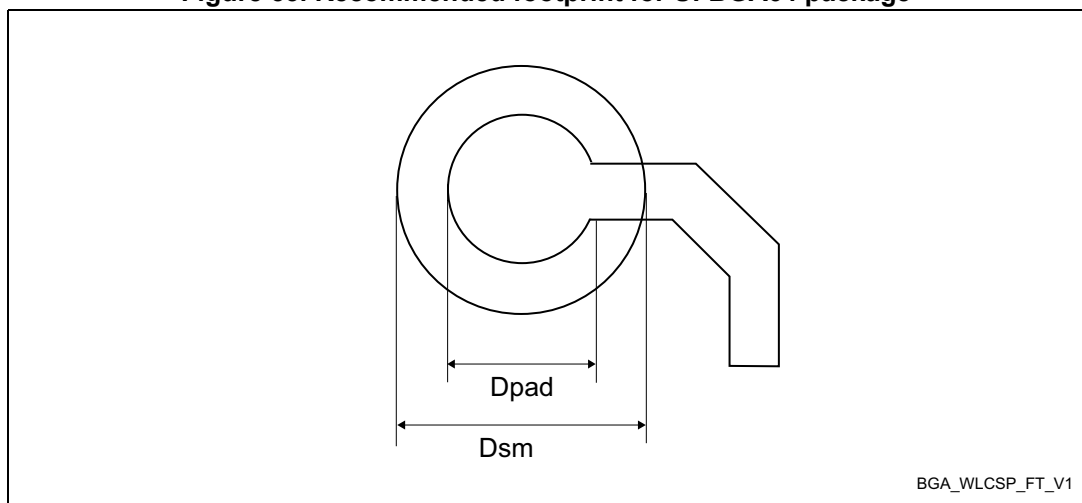


Table 89. Recommended PCB design rules for UFBGA64 package

Dimension	Recommended values
Pitch	0.5
Dpad	0.280 mm
Dsm	0.370 mm typ. (depends on the solder mask registration tolerance)
Stencil opening	0.280 mm
Stencil thickness	Between 0.100 mm and 0.125 mm
Pad trace width	0.100 mm

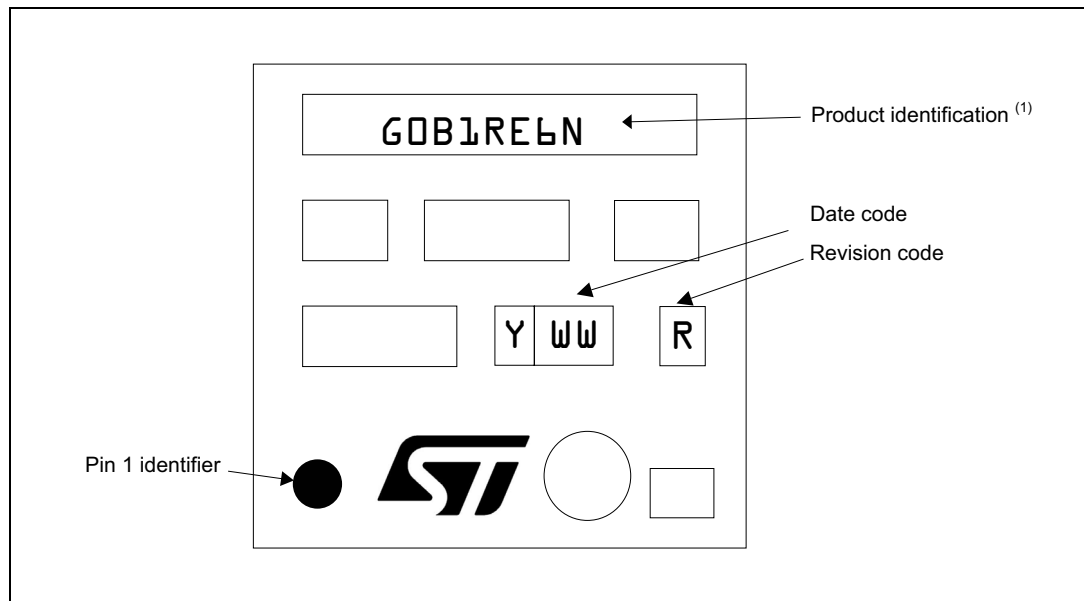
Device marking

The following figure gives an example of topside marking orientation versus ball A1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 54. UFBGA64 package marking example

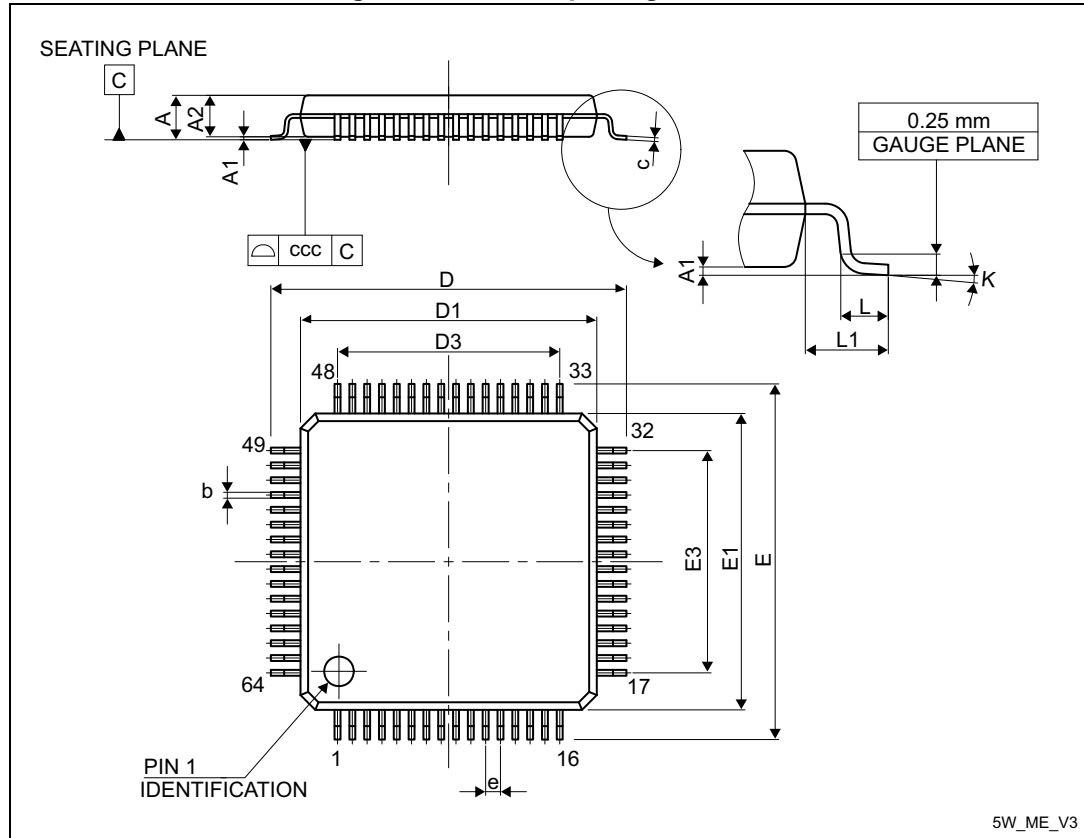


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.7 LQFP64 package information

LQFP64 is a 64-pin, 10 x 10 mm low-profile quad flat package.

Figure 55. LQFP64 package outline



1. Drawing is not to scale.

Table 90. LQFP64 package mechanical data

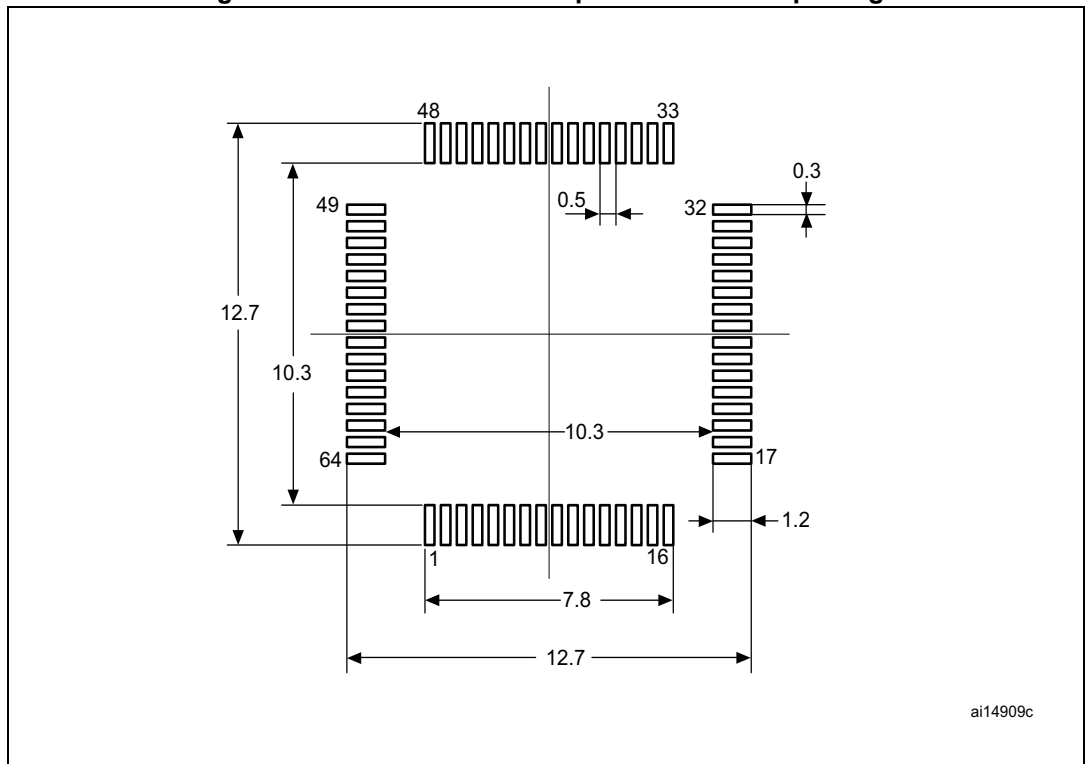
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	-	12.000	-	-	0.4724	-
D1	-	10.000	-	-	0.3937	-
D3	-	7.500	-	-	0.2953	-
E	-	12.000	-	-	0.4724	-
E1	-	10.000	-	-	0.3937	-

Table 90. LQFP64 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
E3	-	7.500	-	-	0.2953	-
e	-	0.500	-	-	0.0197	-
K	0°	3.5°	7°	0°	3.5°	7°
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 56. Recommended footprint for LQFP64 package



1. Dimensions are expressed in millimeters.

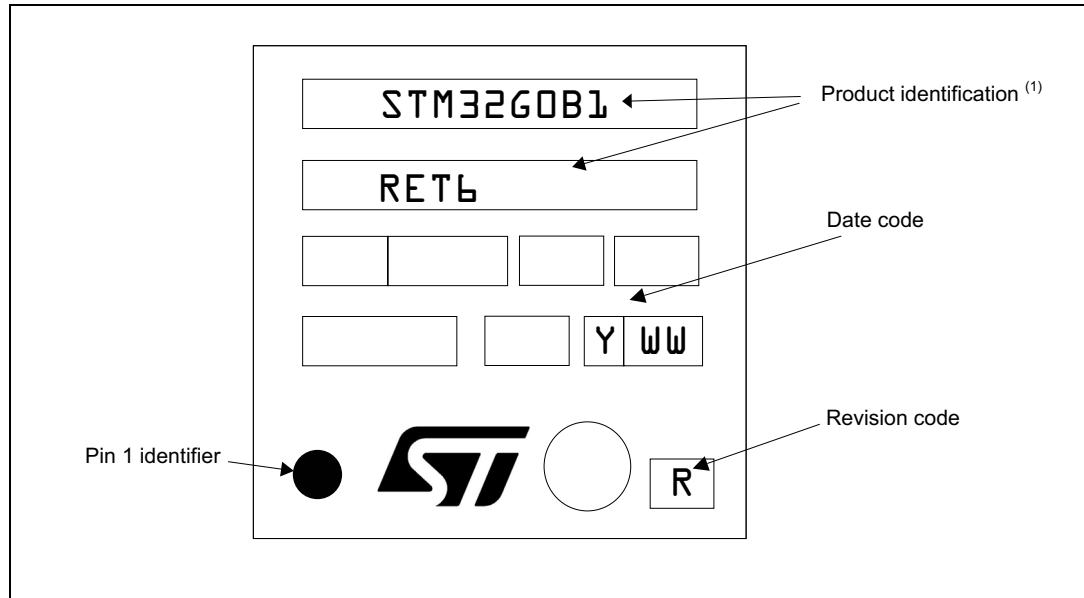
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 57. LQFP64 package marking example

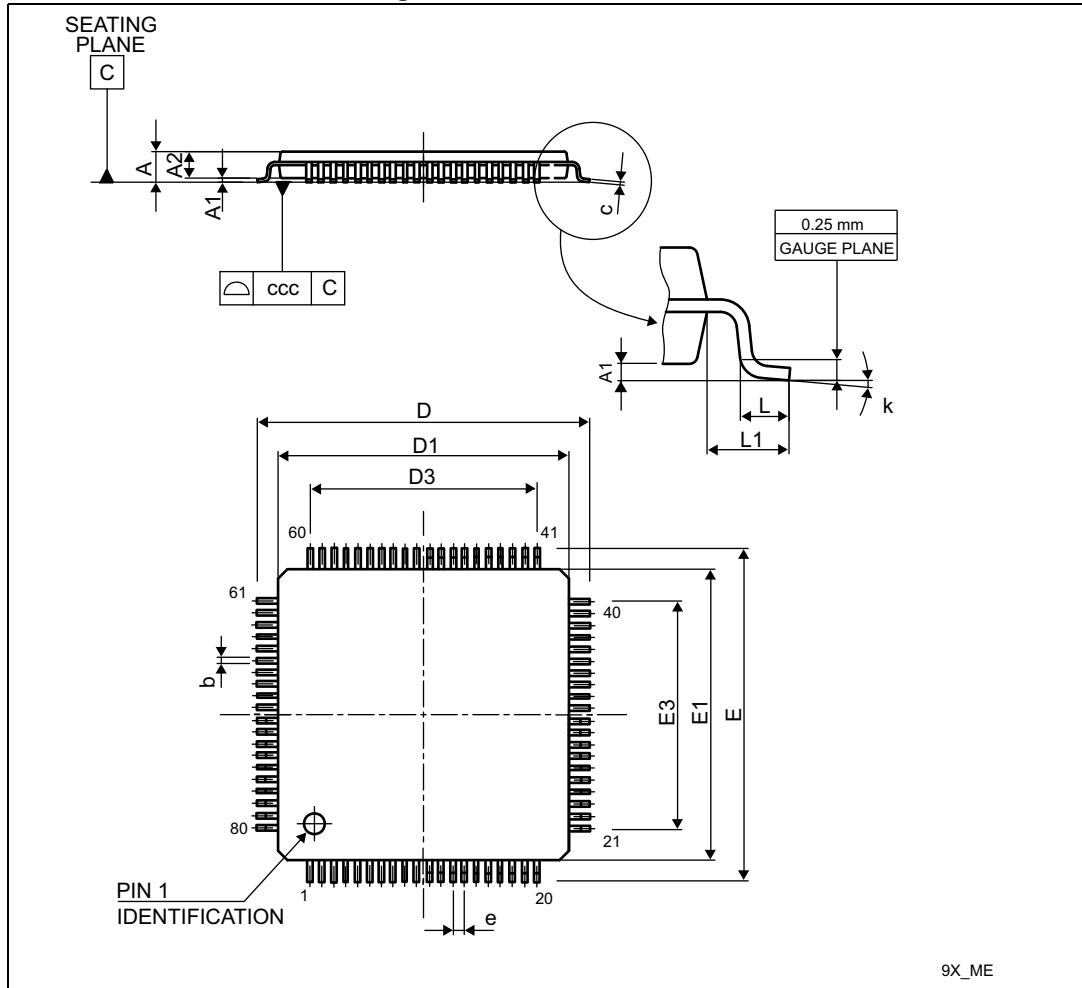


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.8 LQFP80 package information

This LQFP is a 80 pin, 12 x 12 mm low-profile quad flat package.

Figure 58. LQFP80 - Outline



1. Drawing is not to scale.

Table 91. LQFP80 - Mechanical data

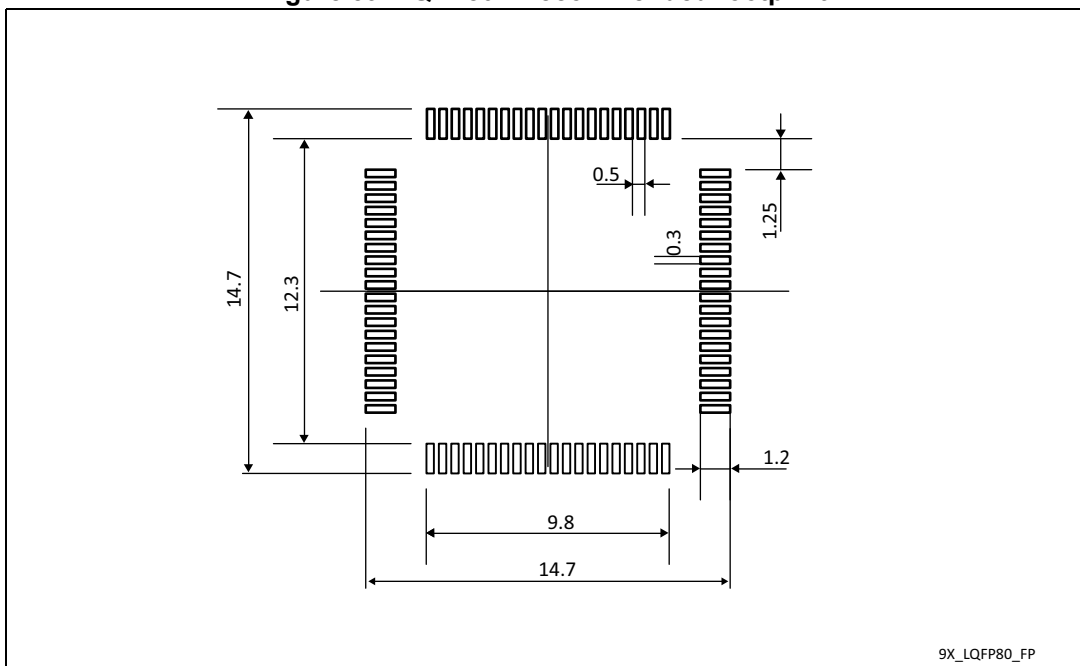
Dim.	mm			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	-	14.000	-	-	0.5512	-
D1	-	12.000	-	-	0.4724	-

Table 91. LQFP80 - Mechanical data (continued)

Dim.	mm			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
D2	-	9.500	-	-	0.3740	-
E	-	14.000	-	-	0.5512	-
E1	-	12.000	-	-	0.4724	-
E3	-	9.500	-	-	0.3740	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
ccc	-	-	0.080	-	-	0.0031
k	0.0°	-	7.0°	0.0°	-	7.0°

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 59. LQFP80 - Recommended footprint



1. Dimensions are expressed in millimeters.

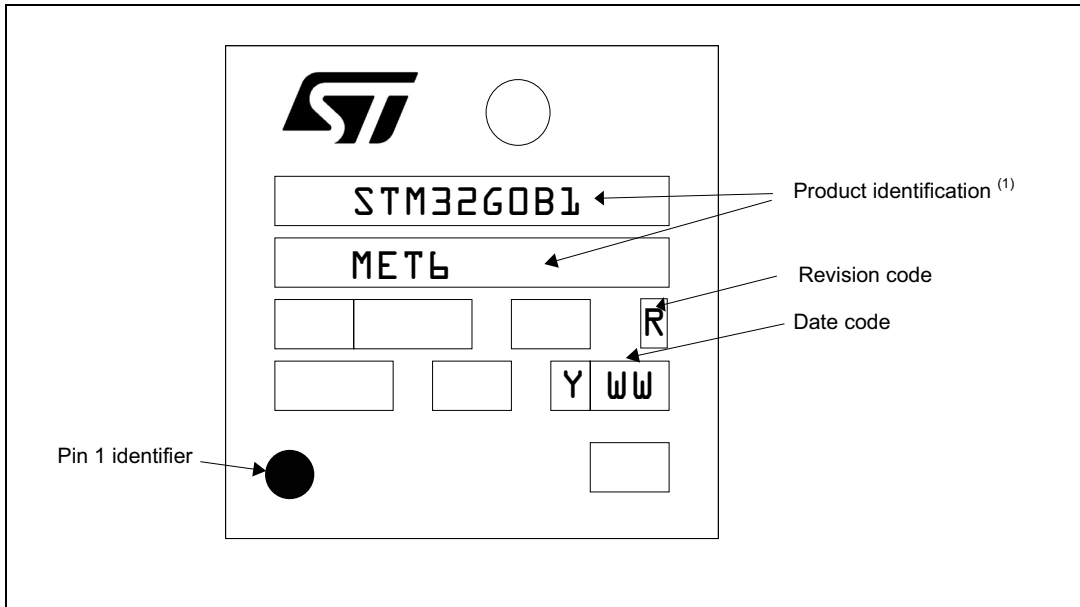
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 60. LQFP80 package marking example

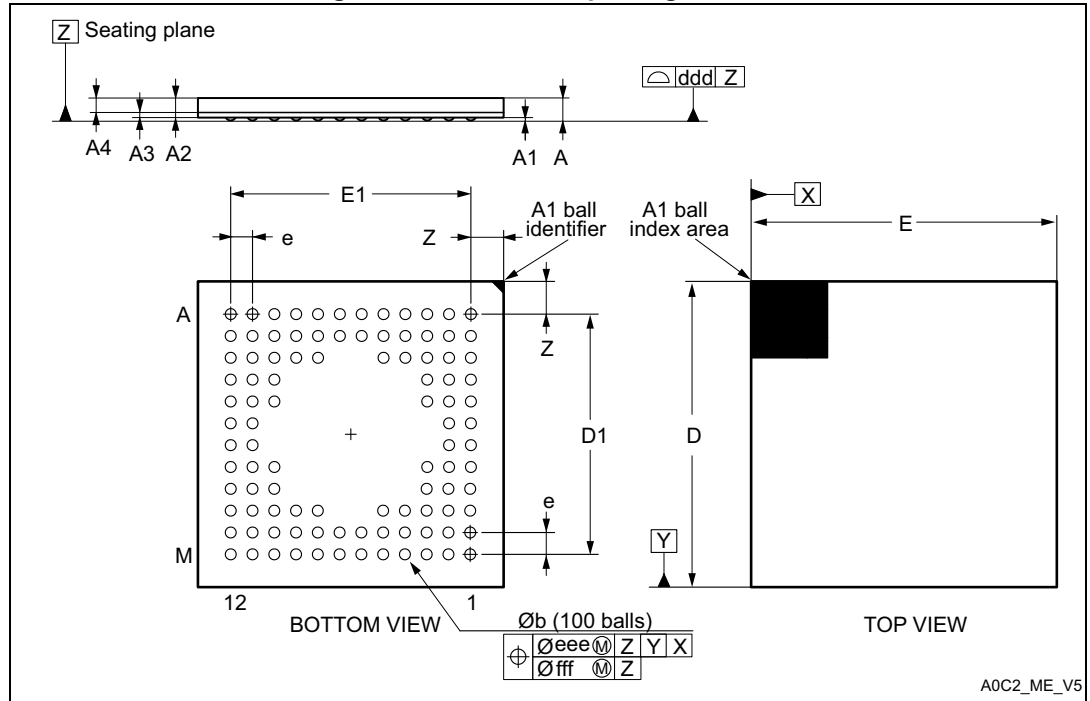


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.9 UFBGA100 package information

UFBGA100 is a 100-ball, 7 x 7 mm, 0.5 mm pitch ultra-fine-profile ball grid array package.

Figure 61. UFBGA100 package outline



1. Drawing is not to scale.

Table 92. UFBGA100 package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	-	0.600	-	-	0.0236
A1	-	-	0.110	-	-	0.0043
A2	-	0.450	-	-	0.0177	-
A3	-	0.130	-	-	0.0051	0.0094
A4	-	0.320	-	-	0.0126	-
b	0.240	0.290	0.340	0.0094	0.0114	0.0134
D	6.850	7.000	7.150	0.2697	0.2756	0.2815
D1	-	5.500	-	-	0.2165	-
E	6.850	7.000	7.150	0.2697	0.2756	0.2815
E1	-	5.500	-	-	0.2165	-
e	-	0.500	-	-	0.0197	-
Z	-	0.750	-	-	0.0295	-
ddd	-	-	0.080	-	-	0.0031

Table 92. UFBGA100 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.050	-	-	0.0020

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 62. Recommended footprint for UFBGA100 package

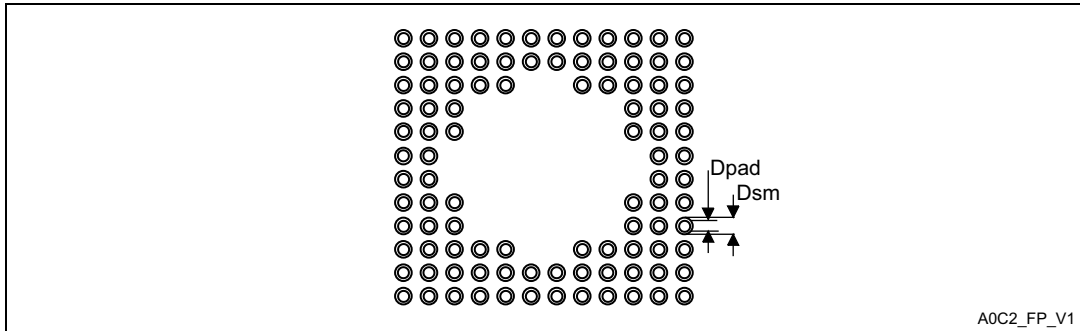


Table 93. UFBGA100 recommended PCB design rules

Dimension	Recommended values
Pitch	0.5
Dpad	0.280 mm
Dsm	0.370 mm typ. (depends on the solder mask registration tolerance)
Stencil opening	0.280 mm
Stencil thickness	Between 0.100 mm and 0.125 mm

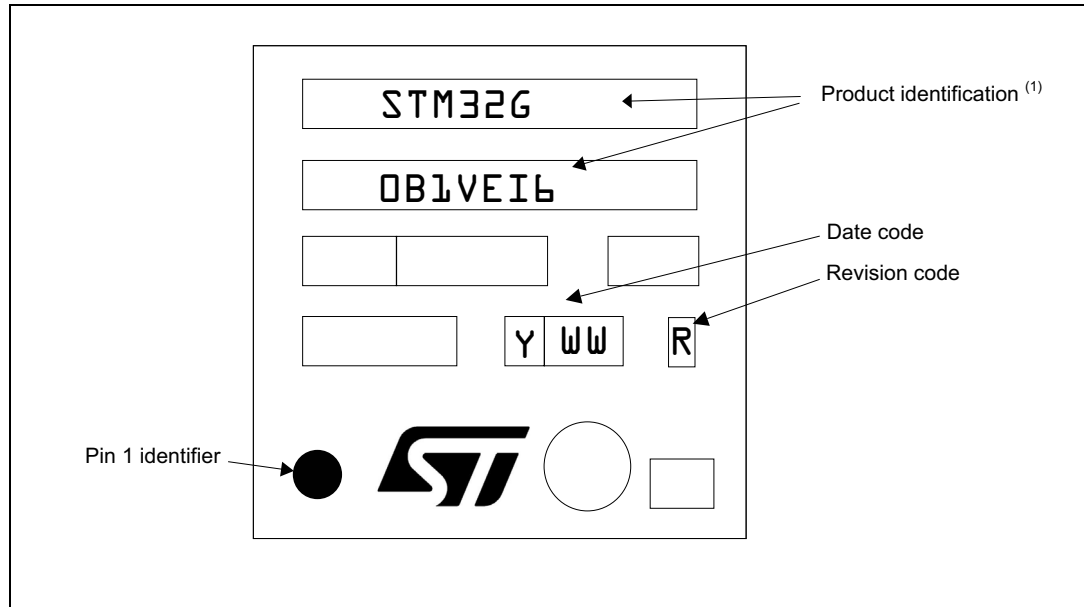
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 63. UFBGA100 package marking example

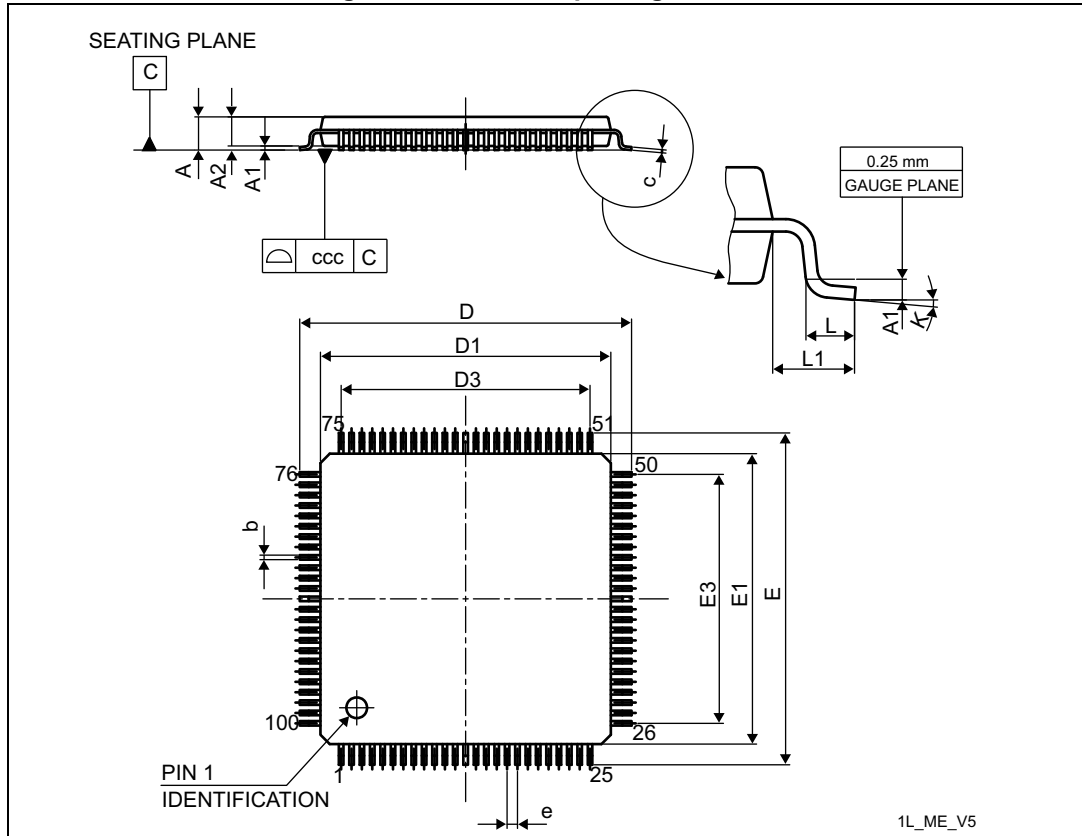


1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.10 LQFP100 package information

LQFP100 is a 100-pin, 14 x 14 mm low-profile quad flat package.

Figure 64. LQFP100 package outline



1. Drawing is not to scale.

Table 94. LQFP100 package mechanical data

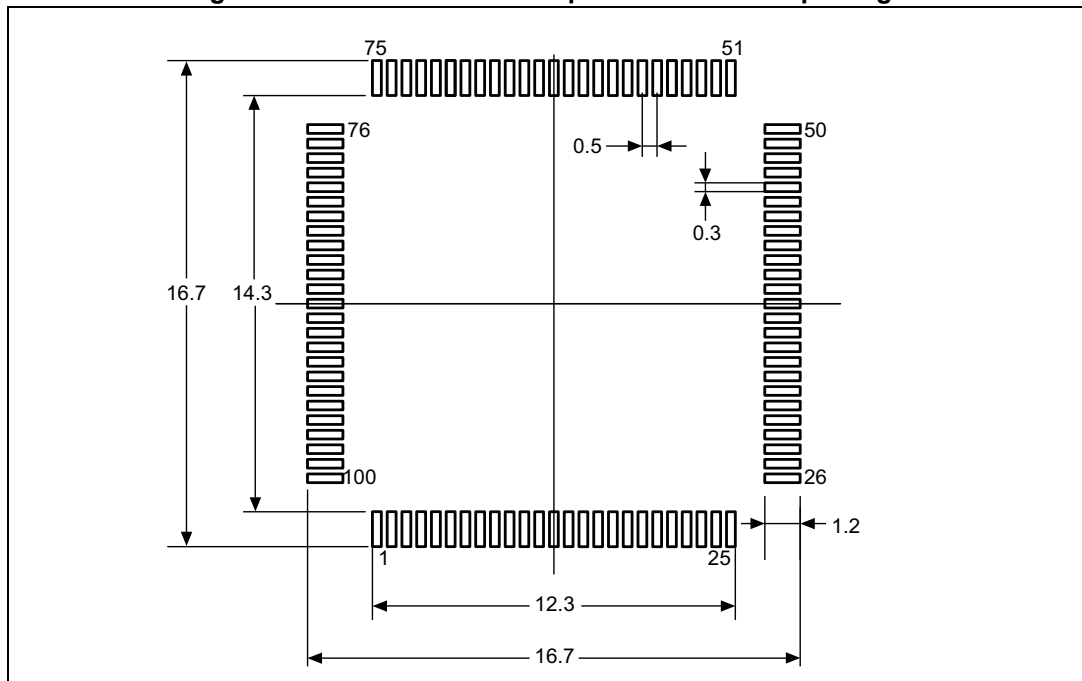
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	15.800	16.000	16.200	0.6220	0.6299	0.6378
D1	13.800	14.000	14.200	0.5433	0.5512	0.5591
D3	-	12.000	-	-	0.4724	-
E	15.800	16.000	16.200	0.6220	0.6299	0.6378
E1	13.800	14.000	14.200	0.5433	0.5512	0.5591

Table 94. LQFP100 package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
E3	-	12.000	-	-	0.4724	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0.0°	3.5°	7.0°	0.0°	3.5°	7.0°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 65. Recommended footprint for LQFP100 package



1. Dimensions are expressed in millimeters.

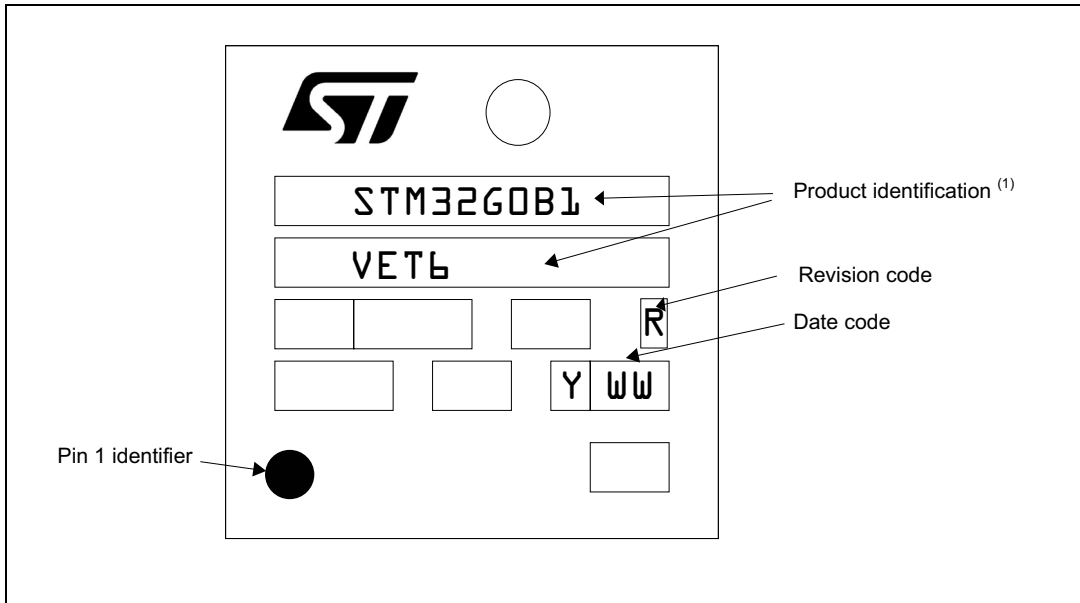
Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 66. LQFP100 package marking example



1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

6.11 Thermal characteristics

The operating junction temperature T_J must never exceed the maximum given in [Table 24: General operating conditions](#).

The maximum junction temperature in °C that the device can reach if respecting the operating conditions, is:

$$T_J(\text{max}) = T_A(\text{max}) + P_D(\text{max}) \times \Theta_{JA}$$

where:

- $T_A(\text{max})$ is the maximum operating ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W,
- $P_D = P_{INT} + P_{I/O}$.
 - P_{INT} is power dissipation contribution from product of I_{DD} and V_{DD}
 - $P_{I/O}$ is power dissipation contribution from output ports where:
 $P_{I/O} = \sum (V_{OL} \times I_{OL}) + \sum ((V_{DDIO1} - V_{OH}) \times I_{OH})$,
 taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 95. Package thermal characteristics

Symbol	Parameter	Package	Value			Unit
			Junction-to-ambient	Junction-to-board	Junction-to-case	
Θ	Thermal resistance	LQFP100 14 × 14 mm	47	23	9	°C/W
		UFBGA100 7 × 7 mm	48	30	12	
		LQFP80 12 × 12 mm	51	24	10	
		LQFP64 10 × 10 mm	53	25	11	
		UFBGA64 5 × 5 mm	51	32	32	
		WLCSP52 TBD × TBD mm	55	23	3	
		LQFP48 7 × 7 mm	59	27	13	
		UFQFPN48 7 × 7 mm	28	12	9	
		LQFP32 7 × 7 mm	59	27	13	
		UFQFPN32 5 × 5 mm	35	20	14	

6.11.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (still air). Available from www.jedec.org.

6.11.2 Selecting the product temperature range

The temperature range is specified in the ordering information scheme shown in [Section 7: Ordering information](#).

Each temperature range suffix corresponds to a specific guaranteed ambient temperature at maximum dissipation and to a specific maximum junction temperature.

As applications do not commonly use microcontrollers at their maximum power consumption, it is useful to calculate the exact power consumption and junction temperature to determine which temperature range best suits the application.

The following example shows how to calculate the temperature range needed for a given application.

Example:

Assuming the following worst application conditions:

- ambient temperature $T_A = 50\text{ °C}$ (measured according to JESD51-2)
- $I_{DD} = 50\text{ mA}$; $V_{DD} = 3.6\text{ V}$
- 20 I/Os simultaneously used as output at low level with $I_{OL} = 8\text{ mA}$ ($V_{OL} = 0.4\text{ V}$), and
- 8 I/Os simultaneously used as output at low level with $I_{OL} = 20\text{ mA}$ ($V_{OL} = 1.3\text{ V}$),

the power consumption from power supply P_{INT} is:

$$P_{INT} = 50\text{ mA} \times 3.6\text{ V} = 180\text{ mW},$$

the power loss through I/Os P_{IO} is

$$P_{IO} = 20 \times 8\text{ mA} \times 0.4\text{ V} + 8 \times 20\text{ mA} \times 1.3\text{ V} = 272\text{ mW},$$

and the total power P_D to dissipate is:

$$P_D = 180\text{ mW} + 272\text{ mW} = 452\text{ mW}$$

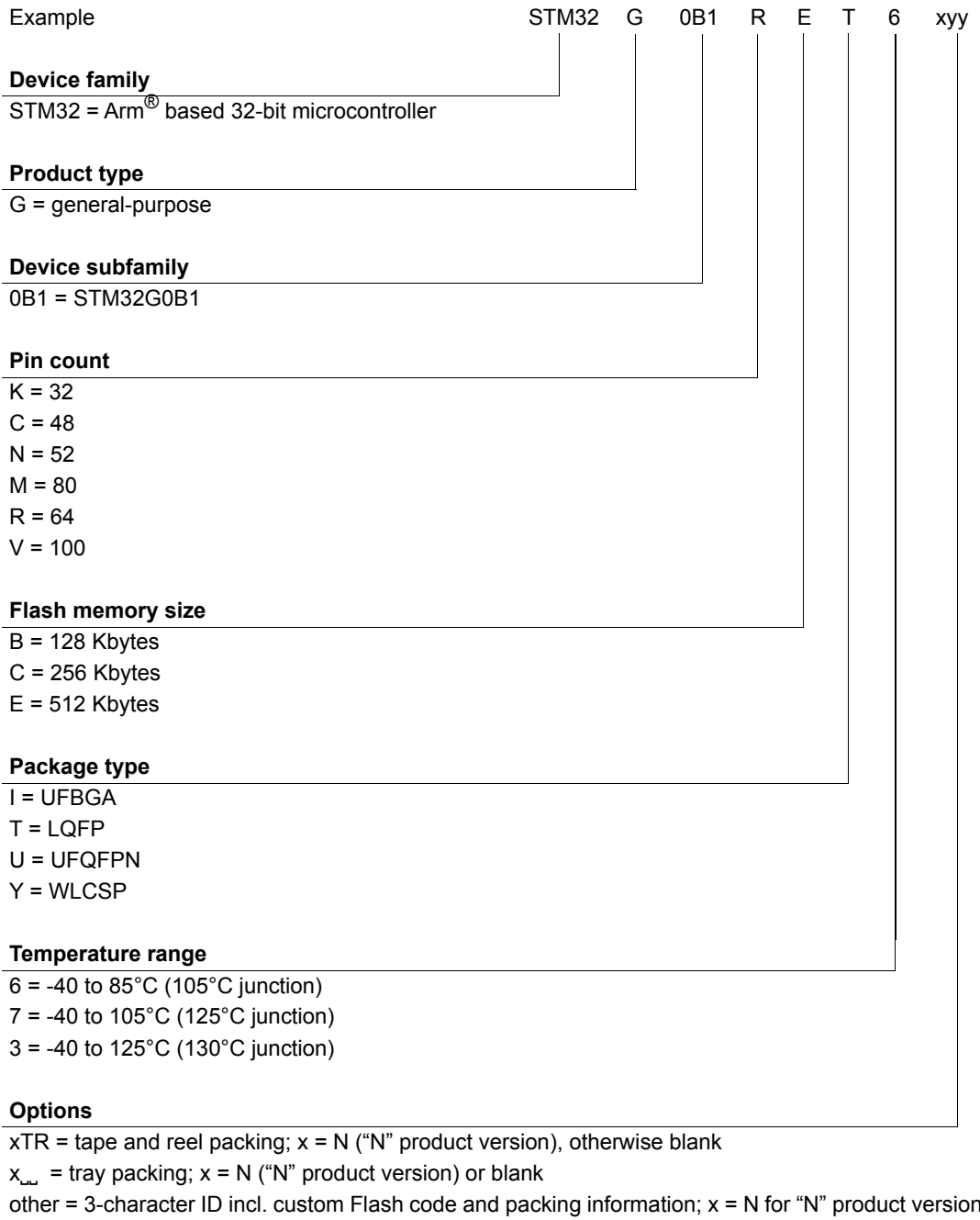
For a package with $\Theta_{JA} = 65\text{ °C/W}$, the junction temperature stabilizes at:

$$T_J = 50\text{ °C} + (65\text{ °C/W} \times 452\text{ mW}) = 50\text{ °C} + 29.4\text{ °C} = 79.4\text{ °C}$$

As a conclusion, product version with suffix 6 (maximum allowed $T_J = 105\text{ °C}$) is sufficient for this application.

If the same application was used in a hot environment with maximum T_A greater than 75.5 °C , the junction temperature would exceed 105 °C and the product version allowing higher maximum T_J would have to be ordered.

7 Ordering information



For a list of available options (memory, package, and so on) or for further information on any aspect of this device, please contact your nearest ST sales office.

8 Revision history

Table 96. Document revision history

Date	Revision	Changes
13-Nov-2020	1	Initial release.
30-Nov-2021	2	<p><i>Table 1: Device summary</i> table reordered;</p> <p>Updated last paragraph in <i>Section 2: Description</i>;</p> <p>Updated <i>Table 12: Pin assignment and description</i>;</p> <p>Updated <i>Table 66: VREFBUF characteristics</i>;</p> <p>Missing package marking examples added in <i>Section 6: Package information</i> and <i>Figure 42: LQFP32 package marking example</i> corrected;</p> <p><i>Section 6.5: WLCSP52 package information</i> updated;</p> <p>Updated example in <i>Section 6.11.2: Selecting the product temperature range</i>;</p> <p><i>Section 6.11: Thermal characteristics</i> - improved UFBGA100, UFBGA64, and LQFP80 Θ_{JA} values as a result of characterization;</p> <p>Updated <i>Section 6.8: LQFP80 package information</i>.</p>

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